MCCOVAVES & FEED ELECTRONICS GROUP

News

VISIL US dt. WW.pianetee.com

eriodicais postage raid . Osps iou approveu poiy

Design Feature

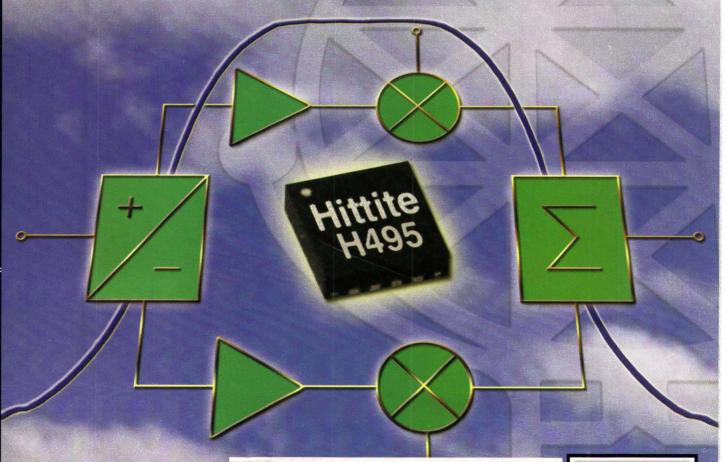
Product Technology

Surveying advanced frequency synthesizers

Smart synthesizers simplify RF integration

C/N generators cover 0.8 to 6.0 GHz

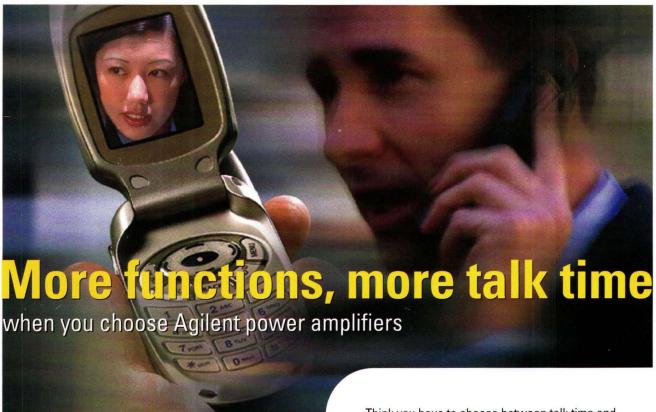
SiGe Direct Modulators Span Wide Dynamic Range



JOE LORITZ, ENGINEER GBPPR 424 WILSON AVE

WI 54303-4115

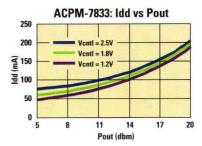
Frequency Synthesis Issue

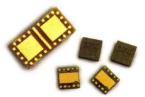


CDMA PAs: Efficiency at Low Vdd

TELLE	P	AE (%)		
Vdd1 & Vdd2 (V)	3.4	2.0	1.0	Freq (MHz)
ACPM-7833	6.2	10.2	18.2	1880
ACPM-7813	6.1	10.1	18.6	836

Test conditions: Pout = 14dBm Vbias = 3.4V





www.agilent.com/view/ephemt

Think you have to choose between talk time and new features? Think again! Agilent's new E-pHEMT power amplifiers deliver the industry's best power-added efficiency, so now you can have both.

And when you choose Agilent's CDMA or GSM PAs, you benefit from our 30 years of experience in delivering RF components. Our state-of-the-art process technology and 6-inch wafer fab expertise offer high volumes to ramp you up fast. And our legendary quality standards will keep you running strong.

So whether you're designing for CDMA or GSM standards, don't compromise.... choose Agilent.

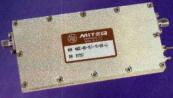
How does Agilent's E-pHEMT stack-up against HBT solutions? For the answer, visit us at www.agilent.com/view/ephemt



HAS YOUR RADAR DETECTED THESE?

AGC & AFC SUBSYSTEMS AND SUPERCOMPONENTS

HIGH PERFORMANCE LOW INTERMODULATION AGC AMPLIFIERS



MODEL NUMBER	CENTER FREQUENCY (MHz)	FREQUENCY SPAN (MHz)	DYNAMIC RANGE (dB)	The second livery with	S AGC GAIN VARIATION (dB)
HAGC-70-214-15-I/O*	21.4	15	70	0.15	0.5
HAGC-70-30-20-I/O*	30	20	70	0.25	0.5
HAGC-70-70-40-1/0*	70	40	70	0.30	0.5
HAGC-70-140-80-I/O*	140	80	70	0.60	0.6
HAGC-60-160-80-I/O*	160	80	60	0.60	0.6
*Input(I)/output(O) im	pedance can be 50 (I o	r 0 = 5) or 75 (I or 0 =	= 7) ohms independe	ent of each other	TREE STATES

- Low Power Consumption
- Models Are Available With Various Dynamic Ranges
- Very Low Intermodulation Distortion (65 dB typical across dynamic range)

HIGH PERFORMANCE PULSED IF ANALOG AGC AMPLIFIERS



 Digital/Analog Processing Feedback Circuitry

				AGC RESPONSE		ACKING ACC \triangle PIN ≤ 65 d	
MODEL Number	CENTER FREQUENCY (MHz)	FREQUENCY SPAN (MHz)	DYNAMIC RANGE (dB)	TIME (Pulse Bursts)	250 ns PULSE (dB Max.)	500 ns PULSE (dB Max.)	2μs PULSE (dB Max.)
GAGC-65-21.4-6	21.4	6	65	25	<± 2.5	<± 2	<± 2
GAGC-65-30-10	30	10	65	25	<± 2.5	<± 2	<± 2
GAGC-65-70-24	70	24	65	25	<± 2.5	<± 2	<± 2
GAGC-65-140-40	140	40	65	25	<± 2.5	<± 2	<± 2
GAGC-65-160-60	160	60	65	25	<± 2.5	<± 2	<± 2

HIGH PERFORMANCE PULSED IF ANALOG AFC AMPLIFIERS



 Stable Detected Output With Low Offset

MODEL (NUMBER	CENTER FREQUENCY (MHz)	PEAK-TO-PEAK BANDWIDTH (MHz)	TRANSFER SLOPE (V/MHz)	PULSE WIDTH (µs)	DROOP RATE µV/MS
AFCP-5-21.4-6	21.4	6	0.8	0.5	75
AFCP-8-30-10	30	10	0.5	0.4	75
AFCP-16-60-20	60	20	0.25	0.2	60
AFCP-20-70-24	70	24	0.20	0.18	60
AFCP-28-140-4	0 140	40	0.15	0.125	60
AFCP-30-160-6	0 160	60	0.125	0.100	60

HIGH PERFORMANCE DIGITALLY-LOCKED PULSED AFC SUBSYSTEMS



		AFC	DIGITAL	A	CCUMULATE	D ACCURACY	/*
MODEL NUMBER	CENTER FREQUENCY (MHz Nom.)	CAPTURE RANGE (±MHz)	CAPTURE RANGE (±MHz)	250 ns PULSE (kHz, Max.)	500 ns PULSE (kHz, Max.)	1μs PULSE (kHz, Max.)	10µs PULSE (kHz, Max.)
DAFC-21/6	21.4	3	1.5	350	150	100	15
DAFC-30/10	30	5	2	250	125	75	10
DAFC-35/14	35	7	2.5	250	125	75	10
DAFC-60/20	60	10	4	200	100	75	10
DAFC-160/40	160	20	10	175	100	75	10
*Settled response	e over multiple pul	se bursts. Minir	num operating	pulse width (F	W) is 250 ns	. Minimum P	RF is 160 Hz.

- Remote Capability
- Very Fast Capture With Integrated VCO (Optional)
- Ultra-Accurate Stability With Digital/Analog Capture Range Processing

For additional information, contact Jack Hakoopian at (631) 439-9130 or jhakoopian@miteq.com





100 Davids Drive • Hauppauge, NY 11788 TEL.: (631) 436-7400 • FAX: (631) 436-7430

AMPLIFIERS FOR EVERY APPLICATION

Low Phase Noise Design and Test Capability new!

- · Custom built to order
- Competitive pricing
- Delivery in 2 weeks ARO
- · Military reliability

Model	Freq. Range GHz	Gain dB min	N/F dB max	Flatness +/-dB	1 dB Comp. pt. dBm min	3rd Order
JCA018-3000	2.0-18.0	25	6.0	2.0	23	28
JCA218-3001	2.0-18.0	25	6.0	2.0	25	30
JCA218-3002	2.0-18.0	25	6.0	2.0	27	32
JCA218-4000	2.0-18.0	30	6.0	2.0	23	28
JCA218-4001	2.0-18.0	30	6.0	2.0	25	30
JCA218-4002	2.0-18.0	30	6.0	2.0	27	32
JCA218-5000	2.0-18.0	35	6.0	2.0	23	28
JCA218-5001	2.0-18.0	35	6.0	2.0	25	30
JCA218-5002	2.0-18.0	35	6.0	2.0	27	32

Power Amplifiers

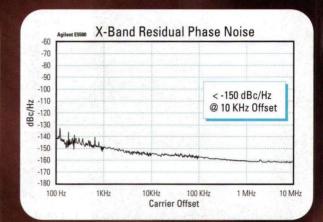
Model	Freq. Range GHz	Gain dB min	N/F dB max	Flatness +/-dB	1 dB Comp. pt. dBm min	3rd Order
JCA12-P01	1.35-1.85	35	4.0	1.0	33	41
JCA34-P02	3.1-3.5	40	4.5	1.0	37	45
JCA56-P01	5.9-6.4	30	5.0	1.0	34	42
JCA812-P03	8.0-12.0	40	5.0	1.5	33	40
ICA1218-P02	12.0-18.0	22	4.0	2.0	25	35

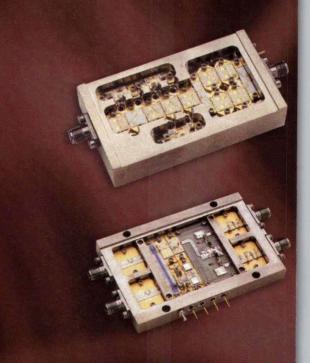
Low Noise Amplifiers

Model	Freq. Range GHz	Gain dB min	N/F dB max	Flatness +/-dB	1 dB Comp. pt. dBm min	3rd Order ICP typ
JCA12-1000	1.2-1.6	25	0.8	0.5	10	20
JCA12-3001	1.0-2.0	40	0.8	1.0	10	20
JCA23-302	2.2-2.3	30	0.8	0.5	10	20
JCA34-301	3.7-4.2	30	1.0	0.5	10	20
JCA78-300	7.25-7.75	27	1.2	0.5	13	23
JCA910-3000	9.0-9.5	25	1.3	0.5	13	23
JCA1112-3000	11.7-12.2	27	1.4	0.5	13	23
JCA1415-3001	14.4-15.4	35	1.6	1.0	14	24
JCA1819-3001	18.1-18.6	25	2.0	0.5	10	20
JCA2021-3001	20.2-21.2	25	2.5	0.5	10	20

Millimeter Wave Amplifiers

Model	Freq. Range GHz	Gain dB min	N/F dB max	Flatness +/-dB	1 dB Comp. pt. dBm min	3rd Order
JCA2629-201	26.0-29.0	19	5.0	1.5	5	15
JCA2629-401	26.0-29.0	35	5.0	1.5	5	15
JCA2730-205	27.5-30.0	15	5.0	1.0	15	25
JCA2730-302	27.5-30.0	26	5.0	1.0	8	18
JCA2730-502	27.5-30.0	43	5.0	1.0	8	18
JCA3031-102	30.0-31.0	18	5.0	1.5	8	18
JCA3031-302	30.0-31.0	34	5.0	1.5	8	18
JCA3031-405	30.0-31.0	40	5.0	1.5	15	25
JCA2640-301	26.5-40.0	30	5.0	2.5	0	10





Integrated Functions/Options

- · Variable Gain Control
- TTL Switching
- Temperature Compensation
- Input/Output Isolators
- · Wayequide Interface
- Detector Output
- Input Limiters
- · Phase Matching
- · Gain Matchine
- · Limiting Amplifier
- Hermetic Packages
- · Bias-T Outpu

Request for quote! Call, fax, or e-mail.

Free catalog! Call or download.



2584 Junction Avenue, San Jose, CA 95134-1902 p: 408 = 919-5300 f: 408 = 919-1505 www.jcatech.com = e-mail: jca@jcatech.com

Everything You Need

ALL FROM ONE SOURCE

No.1 Web Site!

Digi-Key provides easy online access and order entry with real-time inventory and lead-time information.

No.1 On-Time Delivery

Digi-Key ships product from its 600,000 sq. foot facility the same day your order is received.



No.1 Availability of Product

Digi-Key stocks over 275,000 different electronic components from more than 220 leading manufacturers.



No.1 Overall Performance

Digi-Key is committed to giving you the best service possible. Engineers have ranked Digi-Key No. 1 for overall performance for 11 consecutive years.



Fax: 218-681-3380 www.digikey.com Toll-Free: 1-800-344-4539

New NEC Bipolar Transistors Higher f_Ts, Lower 1/f New, Smaller Packages

Oscillators & Buffer Amps

With the best 1/f performance available, these devices help you achieve the phase noise your design demands. They're also available in Twin Transistors.

Part Number	Corner Freq*	V _{CE}	Ic	Package
NE851M13	1 KHz	1 V	5 mA	M13
NE894M13	3 KHz	1 V	5 mA	M13
NE685M13	5 KHz	3V	5 mA	M13

*Review Application Note AN1026 on our website for more information on 1/f noise characteristics and corner frequency calculation.

NEW Packages 0.5 mm

- Flat Lead design reduces parasitics and improves electrical performance
- Low Profile is ideal for VCO modules and other space-constrained designs



M13 One sixth the footprint a SOT-323

LNAs

Need low noise and high gain in an ultraminiature package for your handheld wireless products? These new high frequency NPN transistors deliver!

Part Number	Description	NF	Gain	Freq	Package
NESG2021M05	35 GHz f _T LNA	1.3 dB	11 dB	5.2 GHz	M05
NE662M04	23 GHz f _T LNA	1.1 dB	16 dB	2 GHz	M04
NE687M13	14 GHz f _T LNA	1.4 dB	14 dB	1 GHz	M13
The second secon	The second second second second				

HALF SOLIDS INCH

M04/M05 Half the footprint of a SOT-143

Twin Transistor Devices

Cascode LNAs, cascade LNAs and oscillator/buffer combinations are just three possible uses of these versatile devices. *Matched Die* versions pair two adjacent die from the wafer to help simplify your design, while *Mixed Die* versions — an NEC exclusive — let you optimize oscillator performance while achieving the buffer amp output power you need. Many combinations are available.



One of three pin-outs available

Part Number	Description	Q1 Spec	Q2 Spec
UPA802TC	Matched Die/Cascade LNA	NE681	NE681
UPA895TD	Matched Die/Dual Oscillator	NE851	NE851
UPA861TD	Mixed Die/Osc-Buffer Amp	NE687	NE894
UPA862TD	Mixed Die/Osc-Buffer Amp	NE685	NE851



TD Twin Transistors

Less than one third the footprint of a SOT-363.

CEL California Eastern Laboratories

Santa Clara, California = 408 988-3500 = www.cel.com

DISTRIBUTORS: Arrow (800) 525-6666 **Nu Horizons** (888) 747-6846

Mouser Electronics (800) 346-6873

OCTOBER 2003 • VOL. 42 • NO. 10

Visit us at www.planetee.com

Departments

Feedback

17 **Editorial**

23 The Front End

42 **Editor's Choice**

44 **Financial News**

Company News

48 People

50 Educational Meetings

52 **R&D Roundup**

Application Notes

106 **New Products**

111 Infocenter

112 **Looking Back**

112 **Next Month**



OO SiGe Direct Modulators Ease

These direct quadrature modulators support digital modulation formats with I and Q bandwidths as wide as 250 MHz for carrier frequencies from 250 to 7000 MHz.

Product Technology **News** ^o Design

33 Frequency Synthesizers **Yield Stable Signals**

55 **Smart Synthesizers** Simplify RF Integration

66 **Active Mixers Deliver** High IP3

Carrier-To-Noise **Generators Enhance BER Testing**

92 Circulators/Isolators Serve UMTS Applicaions

96 Third-Generation ICs Speed Bluetooth Integration

98 **Engineered Substrates Yield High Stability**

100 **New Supplier Debuts Innovative WLAN Chips**





SUBSCRIPTION ASSISTANCE AND INFORMATION:

Microwaves & RF (ISSN 0745-2993) is published monthly, except semi-monthly in December. Subscription rates for US are \$80 for 1 year (\$105 in Canada, \$140 for International). Published by Penton Media, Inc., The Penton Building, 1300 E. 9th St., Cleveland, OH 44114-1503. Periodicals Postage Paid at Cleveland, OH and at additional mailing offices.

Canada Post International Publications Mail (Canadian Distribution Sales Agreement #400268800). Canadian GST #R126431964. For paid subscription requests, please contact: Penton Media Inc., P.O. Box 2135, Skokie, IL 60076-7835. For all other Customer Service inquiries, contact: Penton Media Inc., P.O. Box 2095, Skokie, IL

got interference?

Chances are, in your most competitive markets,

cellular interference

is a problem that is

not only *causing*

you problems, but sending

your customers to other, uh...forms of communication.



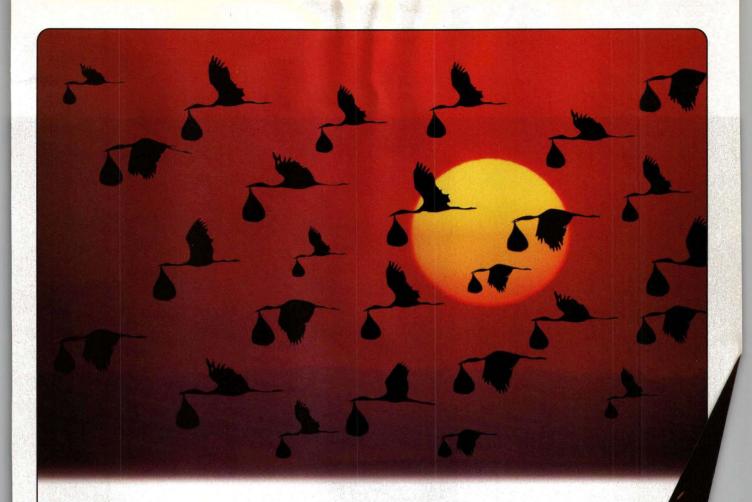
Bottom line, cellular interference is costing you money and customers. In an age where local governments and environmental policy dictate fewer opportunities for cellular site locations, the problem is going to get worse before it gets better. That's why K&L Microwave developed the new Notch Filter Solution.

Developed to isolate and reject a specific band of interference and be placed in line with your existing BTS equipment, the new Notch Filter Solution allows optimum performance of your customers' calls without interference, while providing extremely low loss of both receive and transmit passbands.

The New Notch Filter Solution from K&L Microwave. Some things you just can't do without.



Filtering Solutions for Your Global Market www.klmicrowave.com



Last year, Atmel delivered over 100 million wireless I



We know you're doing your part to eliminate those pesky wires from every electronic application on the planet.

We just want you to know that we're with you all the way. You see, in just the past few years we've quietly become one of the world's largest suppliers of ICs for wireless applications. Every day, we crank out nearly 300,000 devices in over a dozen different product categories. We have everything you need to design almost any application—from antenna-support and RF products to complex processors (including MACs) and other

controllers. Plus a whole lot in between. All conlatest standards, including 802.11, Bluetooth™, Wi-Fi® and Zigbee™.

And when it comes to technology, we've You might like to know that we're the silicon-germanium foundry. And that of special processes that are perfectly a special processes that are perfectly as the silicon of the si

So if you're looking for ways to designs, cut costs and generally Atmel's wireless IC portfolio at

Check out Atmel's wireless IC portfolio today at www.atmel.cg

GPS Automotive Cordless Phones Wireless LAN Mobile Phones P

Bluetooth Foundry Home Applications Smart RF Standard RF Infras'

© 2003 Atmel Corporation. Atmel and the Atmel logo are registered trademarks of Atmel Corporation. Wi-Fi is a registered trademark of Philips Electronics North America Corporation. Bluetooth is a trademark of Bluetooth SIG, Inc.

devices—faster the your designs. Down

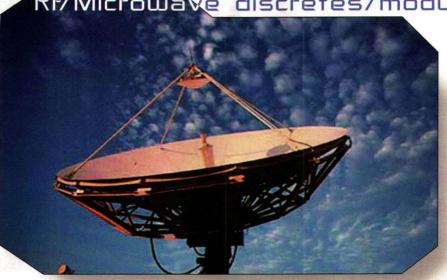


Office 2003



ne capabilities, and an optional link to T&M equipment. Feel what it's like to fly through

load a 30-day eval from www.mwoffice.com or call us at 310-726-3000 for more details.



Microsemi RF and microwave devices support your high-rel designs with PIN and limiter diodes, tuning and multiplier varactors, noise diodes, Schottky-barrier diodes, MNS chip capacitors, spiral inductors and solid state control modules.



for frequencies
from 100 Hz
through millimeter
wave in standard,
custom, and patented

MMSM[™] or Powermite® packages.

Integrated Packages

All our PIN diode switches, limiters, comb generators and detectors can be combined into standard or custom integrated multifunction packages such as switch/limiters, switch matrices and limiter/detectors, for higher performance at a cost lower than with individual components.

Consistent Performance

To assure consistent performance over the full life of your system, we even maintain c closely controlled inventory of matchir RF/microwave diode chips, to fulfill y future needs. Exactly.

Hard-to-Find Discrete

Plus, we deliver those hard-to-g discretes you no longer find sources. *Microsemi*'s probable so whatever your design needs, make us your first call:

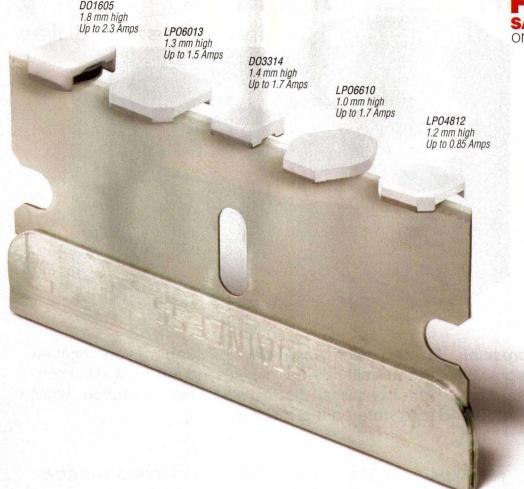
978-442-5600.

Coilcraft P Now You ha They off









have your board height with our ltrathin Power Wafer inductors

ing five new power inductor all less than 2 mm thick

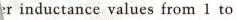
ioneered low profile power ncluding the first 1 mm part. ve even more options with wer Wafer families.



1000 µH and current ratings up to 2.3 Amps. Footprints as small as 3.5 mm square make it easy to cut your design down to size.

For complete specifications, SPICE models and free evaluation samples of all our Power Wafer inductors, visit us

at www.coilcraft.com/powerwafers.







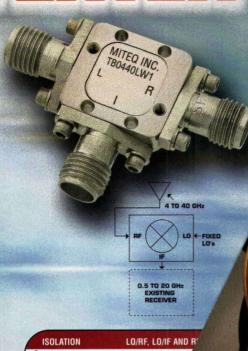
4 - 40 GHz BLOCK DOVNCONJERTER

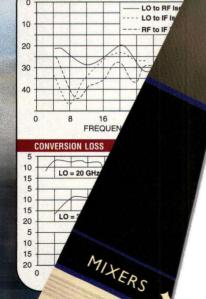
MITEQ's Model TBO440LW1 allows the use of existing wide bandwidth receivers over millimeter frequency bands!

FEATURES:

- RF/LO Coverage 4 to 40/4 to 42 GHz
- IF Operation 0.5 to 20 GHz
- LO Power Range +10 to +15 dBm (usable at +7 dBm)
- RF to IF Isolation.... 25 dB
- Removable K Connectors
- From Stock

INPUT PARAMETERS	MIN.	TYP.	MAX.
RF frequency range (GHz)	4		40
RF VSWR (RF = -10 dBm, LO = +13 dBm)	100	2.5:1	
LO frequency range (GHz)	4		42
LO power range (dBm)	+10	+13	+15
LO VSWR (RF = -10 dBm, LO = +13 dBm)		2.0:1	
TRANSFER CHARACTERISTICS	MIN.	TYP.	MAX.
Conversion loss (dB)		10	12
Single sideband noise figure (dB, at +25° C)		10.5	
Isolation - LO to RF (dB)	18	20	170 57
Isolation - LO to IF (dB)	20	25	
Isolation - RF to IF (dB)	20	30	
Input power at 1 dB compression (dBm)		+5	
Input two-tone 3rd order intercept point (dBm)		+15	A THE O
OUTPUT PARAMETERS	MIN.	TYP.	MAX.
IF frequency range (GHz)	0.5		20
IF VSWR (RF = -10 dBm, LO = +13 dBm)		2.5:1	arek I





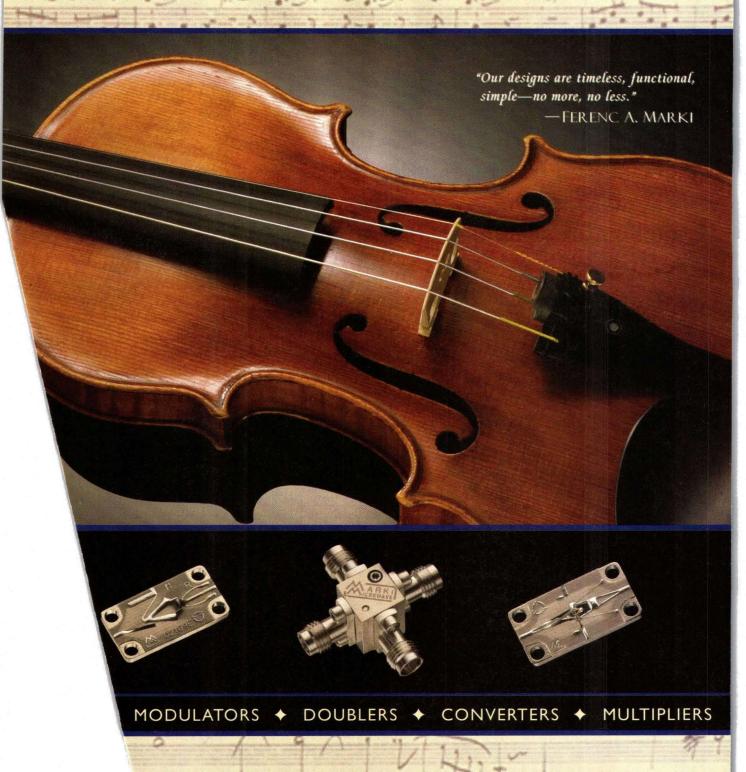
For additional information, please contact Mary Become or e-mail mbecker@miteq.com



100 Day TEL.: (631)



CLASSICAL DETAIL





FOR DETAILED SPECS, VISIT OUR WEBSITE: www.MarkiMicrowave.com

phone 408.778.4200 fax 408.778.4300 e-mail Mixers@MarkiMicrowave.com

((feedback))

Contents Correction

▶IN THE TABLE OF CONTENTS of *Microwaves & RF's* September 2003 issue, the Product Technology article on p. 108 was listed as "Testers Mimic Propagation Losses To 13.25 GHz." That article ran in the August 2003 issue and was repeated in the September 2003 table of contents due to an editorial error. The correct title of the article on p. 108 should have been "Low-Cost Transceiver Drives Wireless USB." We apologize to the readers for any confusion that this error may have caused.

The Editors of Microwaves & RF

MES 2003

►► BARRY INDUSTRIES attended the recent MES show at the Baltimore Convention Center in Baltimore, MD with the expectation that its location and target audience would pay dividends as far as generating leads and interest in our company. We were exhibiting our state-of-the-industry Low Temperature Cofired Circuit (LTCC) capability. This LTCC capability enables a full front end microwave system to be assembled on a multilayer circuit in a fraction of the space of a soft substrate solution. LTCC allows for the configuration of passive and active components in the same circuit.

We were targeting Prime Contractors in the aerospace and defense industry, and we had great contact with end users from Army and Navy research establishments as well as the likes of BAE Northrop Grumman, Raytheon, and Thales. We will definitely be exhibiting in the future.

Barry Industries is an ISO 9001:2000 approved company. If you are interested in learning more about Barry Industries, please visit our website at

www.barryind.com.

Rob Sinclair Barry Industries

Editor's Note: Rob, thanks very much for your comments about MES 2003. We appreciate all who exhibited at the show as well as those who attended. We hope to see everybody at next year's shows in San Diego and Baltimore.

PLEASE COMMENT

Microwaves & RF welcomes mail from its readers. Letters must include the writer's name and address. The magazine reserves the right to edit letters appearing in "Feedback." Address letters to:

Jack Browne
Publisher/Editor
Microwaves & RF
Penton Media, Inc.
45 Eisenhower Dr., 5th Floor

Paramus, NJ 07652 e-mail: jbrowne@penton.com

1,239,580 Filters America's Filter Specialist since 1956 LC Filters to Combline & Interdigital Diplexers and Filters to 18 GHz Multiplexers to 18 GHz Surface Mount Micro-strip Micro-strip Filters to 3 GHz High Pass Low Pass Filters to 18 GHz Filters to 18 GHz Western Regional Sales Office: 11652 W. Olympic Blvd. **Eastern Regional Sales Office:** St. Pete Beach, FL Los Angeles, CA 90064 Toll Free: 866.363.0849 Ph: 800.776.7614 310.478.8224 Ph: 727.363.0849 Fax: 800.473.2791 310.445.2791 www.tte.com Fax: 727.363.7639 E-mail: sls@tte.com E-mail: sls@tte.com



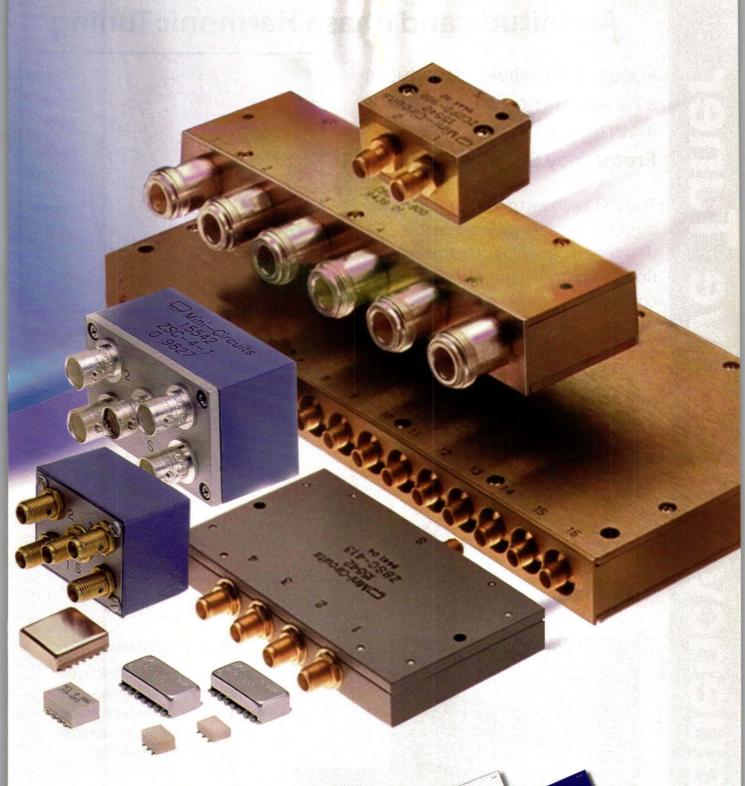
FOLIA SPACES COLONIALES



2kHz to 12.6GHz from 794

Need just the right surface mount, coaxial, thru mount, or flat pack power splitter or combiner for your project? Mini-Circuits is on the case offering you thousands of high performance, cost-effective models off-the-shelf and immediately available for your military and commercial applications. Choose from 2 and 3way to 48way; 0°, 90°, 180°; 50&75 ohms covering 2kHz to 12.6GHz and beyond, all characterized with detailed data and performance curves available to you in a flash 24/7 on "The Yoni Search Engine" at the Mini-Circuits web site. Surface mount products include highly reliable LTCC designs giving you extremely small size, ultra-low profile, excellent stability over temperature, and high performance repeatability. Tough built coaxial models are available with SMA, BNC, TNC, and Type-N connectors and include broadband ZX10 units standing less than $^{3}/_{4}$ " in size. And when it comes to your custom needs...just let us know what you're looking for and our development team will go to work! Add our 1 year guarantee, knowledgeable applications support, and value pricing, and the decision is easy. Contact Mini-Circuits today!

Mini-Circuits...we're redefining what VALUE is all about!





New Blue Cell™ LTCC 164 Page Handbook...FREE! For Complete Product Line...See Our Designer's Guide On The Web Site.



P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 For quick access to product information see MINI-CIRCUITS CATALOG & WEB

The Design Engineers Search Engine Provides ACTUAL Data Instantly From MINI-CIRCUITS At: www.minicircuits.com

ISO 9001 ISO 14001 CERTIFIED

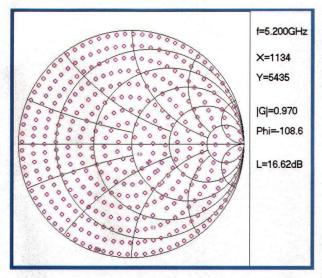
194 Rev E

Amplitude and Phase Harmonic Tuning

Focus Microwaves introduces a novel harmonic Load Pull instrument:

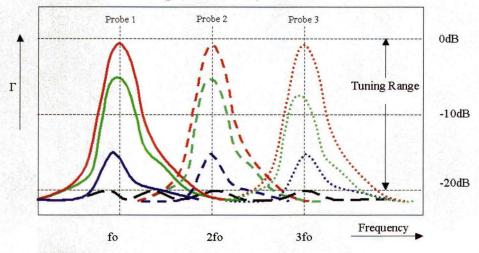
Frequency Selective Tuner FST

The FST* allows to independently adjust impedances at three different frequencies (harmonics). Both amplitude and phase are controllable.



Fo, 2Fo, 3Fo Independently tunable in Γ and ϕ

INDEPENDENT TUNING using resonant probes





Main Features

- Dynamic range: 20dB/360° at all three frequencies
- Contactless resonant probes
- No lossy Triplexers required
- High power capability
- Highest Γat Fo
- Compact design with built-in micro-controller
- TCP/IP interface (iTuner)
- On-wafer operation

The PERFECT Harmonic Load Pull Instrument



16)3 St. Regis Dcllard-des-Ormeaux, Quebec Canada, H9B 3H7 Tel: 514-684-4554 Fax: 514-684-8581

Email: info@focus-microwaves.com

from the editor

DDS Gains Wider Application

FREQUENCY SYNTHESIZERS HAVE IMPROVED dramatically in recent years. Ten years ago, direct digital synthesis (DDS) was in its infancy; now it is widespread as a primary or secondary technology in many signal sources. Over that time, designers have learned more than a few ways to curb the spurious levels that once plagued the technology. Current DDS designs can routinely achieve spurious levels as good as –60 and –70 dBc without sacrificing the frequency agility that makes DDS technology so attractive.

The technology was often considered frivolous by "serious" synthesizer designs, since the bit resolution of early digital-to-analog converters (DACs) essentially dictated the spurious performance of the end product. A decade earlier, 8-b DACs were the standard at higher clock speeds, essentially limiting high-speed DDS sources to a spurious floor of about 6 dB per bit, or about –48 dBc.

Compare that to what is being done with modern DDS designs. As a recent example (see *Microwaves & RF*, April 2003, p. 94), the ADV-3000S DDS from Advanced Radio Corp. (Reston, VA) tunes from 20 MHz to 3 GHz with 1-Hz resolution. Although somewhat slower than some DDS sources, with better than 5-µs frequency switching speed, the VME module achieves worst-case spurious performance of –60 dBc.

Many other synthesizer suppliers, including Elcom Technologies (Rockleigh, NJ) and Synergy Microwave (Paterson, NJ), have succeeded in blending DDS technology with clever circuit design to overcome traditional spurious limitations. One of the more innovative recent applications of DDS technology was by FEI Communications (Mitchel Field, NY) as a "correction circuit" for oven-controlled crystal oscillators (OCXOs). By employing DDS technology, the company's FE205A, FE-405A, and FE-505A OCXOs can approach the frequency stability of more expensive rubidium atomic clocks.

Of course, any discussion on DDS technology would be incomplete without mention of Sciteq Electronics. The company's synthesizer product lines, which were acquired by Osicom (itself renamed to Sorrento Networks), now can be found as part of the RF production lines of optical-communications-equipment supplier Meret Optical Communications (San Diego, CA). Although small, Sciteq achieved a great many landmarks in DDS development, constantly pushing clock frequencies and introducing the first GaAs-based DDS source.

DDS technology appears to have a promising future in this industry, although advances in more traditional synthesizer technologies, including PLL, fractional-N, and direct-analog technologies, are far from exhausted. In the end, synthesizer specifiers reap the benefits of this push for the ultimate RF synthesizer.

Jack Browne

Publisher/Editor



Frequency
agility makes
DDS technology
attractive
to both
commercial and
military systems
integrators.



- FILTERS & MULTIPLEXERS
- -Bandpass & Band Reject -Hi & Low Pass
- -Notch
- HYBRIDS / CROSS GUIDE COUPLERS
- COAXIAL COUPLERS
- ISO-FILTERS
- OMT/POLARIZERS
- INTEGRATED ASSEMBLIES
- SWITCH MATRICES & SWITCH FILTERS
- BUILD-TO-PRINT & REPAIR SERVICES



- SPACE & HI-REL QUALIFICATION SERVICES
 - -Thermal Vacuum
 - -High Power Corona & Multipaction Testing
 - -Vibration/Shock & Temperature Testing

FEATURES:

- Extremely Low Loss
- High Selectivity & Rejection
- · Wide Dynamic Range
- · High Power Capability
- · Space Flight & Hi-Rel Heritage
- Coverage up to 65 GHz
- Short design & prototype cycles

Other Products:

Radial Power Combiners & Dividers



Model 9640 Dual HF Receiver

Frequency Range — 0.56 to 32 MHz

Instantaneous Bandwidth - 10 MHz

Noise Figure - 10 dB Maximum

Gain - 48 dB ±2 dB

Synthesizer Control - RS-232C Interface

Synthesizer Tuning Speed — 100 µs Maximum

Frequency Synchronous or Independent Operation



Interad Ltd.

18321 Parkway • Melfa, VA 23410

Phone: 757-787-7610 • Fax: 757-787-7740 www.interadlimited.com

e-mail: sales@interadlimited.com



SUBMINIATURE TEMPERATURE
CONTROLLED HEATERS
FOR SOLUTIONS TO
TEMPERATURE
STABILITY PROBLEMS

CUSTOM DESIGNS ARE OUR SPECIALTY!











Features

- · Beryllia Base and Aluminum Nitride for excellent thermal conduction
- · Temperature is set with a single resistor
- · Set Temperature from Ambient to 150°C
- No External Temperature Controller Needed
 Heaters that Operate from 5 to 50 Volts DC
- Heaters that Operate from 5 to 50 Volts DC
 Heaters that Operate on 115 and 240VAC
- Heater Power from 5 to 80 Watts
- Simple to use

Control the Temperature of:

- Microwave Components
- Crystal Oscillators
- Sensors
- Lasers Diodes
- · Fiber Optic AWGs
- Biological Reactions
- Electro Mechanical Assemblies
- Chemical Reactions
- · Thermal Cure of Epoxies

www.thermoptics.com

1004 Mallory Way, Carson City, NV 89701 Phone: 775-882-7721 • Fax: 775-882-7675

Microwaves&RF

A Penton Publication

HIGH-SPEED ELECTRONICS GROUP

Group Publisher Craig Roth, (201) 845-2448 • croth@penton.com
Publisher/Editor Jack Browne, (201) 845-2405 • jbrowne@penton.com
Technology Editor Nancy Friedrich, (201) 845-2428 • nfriedrich@penton.com
Managing Editor John Curley, (201) 845-2415 • jcurley@penton.com
Special Projects Editor Alan ("Pete") Conrad

Editorial Assistant Dawn Prior • dprior@penton.com
Contributing Editors Andrew Laundrie, Allen Podell

MANUFACTURING GROUP

Director Of Manufacturing Ilene Weiner Group Production Director Mike McCabe

Customer Service Representative

Dorothy Sowa, (201) 845-2453, fax: (201) 845-2494

Production Coordinator Judy Osborn, (201) 845-2445

Digital Production Staff Louis Vacca, Pat Boselli

Color Manager Leilani Lockett

ART DEPARTMENT

Art Director Patrick Prince • pprince@penton.com
Group Design Manager Anthony Vitolo • tvitolo@penton.com
Senior Artist James M. Miller
Staff Artists Linda Gravell, Michael Descul

CIRCULATION CUSTOMER SERVICE (LIVE)

Phone: (847) 763-9670 • fax: (847) 763-9673 microwaves&rf@halldata.com

REPRINTS & PDFS

PentonReprints (888) 858-8851 • www.pentonreprints.com

EDITORIAL OFFICE

Penton Media, Inc., 45 Eisenhower Dr., Fifth floor, Paramus, NJ 07652 Phone: (201) 845-2446, fax: (201) 845-2493

PENTON TECHNOLOGY MEDIA

President David B. Nussbaum

VP, HR and Organizational Effectiveness Colleen Zelina



Chairman & Chief Executive Officer Thomas L. Kemp President & Chief Operating Officer Daniel J. Ramella Chief Financial Officer Preston L. Vice Chief Technology Officer &

VP, Database Marketing Services R. Thomas Jensen Exec. VP & President,

Penton Technology & Lifestyle Media David B. Nussbaum

Exec. VP & President, Penton Industry Media William C. Donohue

President, Penton Retail Media John J. Meehan

President, Penton Lifestyle Media and Penton IT Media Groups Darrell C. Denny Senior VP, Human Resources Katherine P. Torgerson VP & Controller Jocelyn A. Bradford VP, Investor Relations Mary E. Abood

International editions are shipped via several entry points, including: Editeur Responsable (Belgique), Vuurgatstraat 92, 3090 Overijse, Belgique.

Requer, voulgastad 22, 300 Overlage, Desiguer.

Microwaves & RF is sent free to individuals actively engaged in high-frequency electronics engineering. In addition, paid subscriptions are available. For paid subscription please contact: Penton Media Inc., P.O. Box 2135, Skokle, IL 60076-7835. For all of the Customer Service inquiries, contact: Penton Media Inc., P.O. Box 2095, Skokle, IL 60076-7995.

Prices for non-qualified subscribers are:

Single Copies

	1 Yr.	Regular Issues	PDD	
U.S.	\$ 85.00	\$10.00	\$100.00	
Canada	\$110.00	\$12.00	\$125.00	
Mexico	\$145.00	\$14.00	\$125.00	
All other countries	\$145.00	\$16.00	\$125.00	

Back issues of MicroWaves and MicroWaves & RF are available on microfilm, microfiche, 16-mm, or 35-mm roll film. They can be ordered from Xerox University Microfilms, 300 North Zeeb Rd., Ann Arbor, MI 48106. For immediate information, call (313) 761–4700. Copying: Permission is granted to users registered with the Copyright Clearance Center, Inc. (CCC) to photocopy any article, with the exception of those for which separate copyright ownership is indicated on the first page of the article, provided that a base fee of \$1.25 per copy of the article pus 60 cents per page is paid directly to the CCC, 222 Rosewood Dr., Danvers, MA 01923. (Code 0745–2993/02 \$1.25+.60) Copying done for other than personal or internal reference use without the expressed permission of Penton Media, Inc., is prohibited. Requests for special permission or bulk orders should be addressed in writing to the publisher.

Copyright © 2003 by Penton Media, Inc. All rights reserved. Printed in the U.S.



The system designer's choice for nearly thirty years

PTS Synthesizers are found in more test systems than any other synthesizer on the market.

What engineers like most about PTS is our ability to provide the right performance at the

right price. At PTS, we believe there is no such thing as a "one size fits all" solution. As a result, we've built a loyal following, and have the largest installed base in the industry today. For instance, maybe you need coverage to 3200 MHz, but don't need manual control. Or maybe 1 GHz will do, but you'd like to add a programmable step attenuator. No problem. Operating to 6 GHz these days? We have you covered. Our PTS 6400 blends direct analog and digital frequency synthesis techniques to offer high spectral purity and fast frequency switching speed from 1 to 6400 MHz.

Our list of standard features and options includes: BCD or GPIB control; DDS with phase continuous switching; digital phase rotation; output power up to +13 dBm; phase noise characteristics as good as -132 dBc/Hz (100 MHz, 20 KHz offset); and switching as fast as 1 µs.



We back every synthesizer with an industry leading 3-year warranty.

At PTS, we adhere to conservative de-rating practices, keep power consumption and internal heat build-up to an absolute minimum, and subject finished systems to rigorous temperature cycling and electrical testing. The result? Proven 25,000 hour MTBF figures, and the confidence to offer you the best warranty in the business.



Choose from a vast selection of reasonably priced synthesizers to find the one that's right for you.

Our synthesizer line spans 16 models starting with the PTS x10 priced at \$2,250. It features 1 Hz resolution and DDS phase continuous switching. Even our top-of-the-line PTS 6400 is just \$15,000. It features 3-20 µs switching and phase noise of -122 dBc/Hz (1 GHz, 20 KHz offset).

Imagine, outstanding performance and the best warranty—all at a great price. PTS. The system designer's choice.



978.486.3400 www.programmedtest.com



HFSS v9 is sparking a revolution in microwave design—a revolution that brings electromagnetic precision into the design flow, cuts costs, improves manufacturability, and tackles more advanced designs than ever before.

With unprecedented accuracy and insight into electrical performance, HFSS v9's new architecture is reducing engineering time through parametric design entry, advancements in data management and design automation, and state-of-the-art algorithms. Developing on-time and on-the-mark products has never been easier.

HFSS v9—Put the power of next-generation design in your hands.

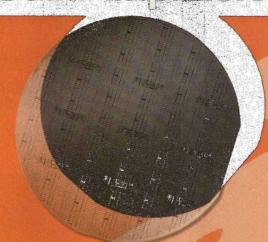


www.hfss.com



High 1P3/Variable Gain Amplifiers

- Low-Cost, High Performance
- Constant Linearity:
 +37dBm OIP3
- Broad Dynamic Range
- Low Noise-Figure: 4.5dB





LOW COST + HIGH PERFORMANCE = WJ

W) Communications Inc. is a leading RF semiconductor company focusing on the design and manufacture of high-quality devices and multi-chip modules (MCMs) for telecommunications systems worldwide. W)'s highly reliable amplifier, mixer, RF IC and MCM products are used to transmit and receive signals that enable current and next generation wireless and wireline services. For more information visit www.wj.com or call (408) 577-6200.

Nodel Number	Frequency [HHz]	Aftenuation Range (d8)	77.0 110.	5 - F 1 20	The second			Control Voltage (V)		Padkage Styles
The state of the s	50-2200 750-1000 800-2200	-28	16.5 14.0 14.0	. 37	21 21 31	- 5,5 4,2 4,3	150 150 150	0-4.5.	5	501C-8 28-PIN OFN 28-PIN OFN



THE COMMUNICATIONS EDGE™

WJ Communications Inc. 800-WJ1-4401 • fax: 408-577-6621 • sales@wj.com

the front end

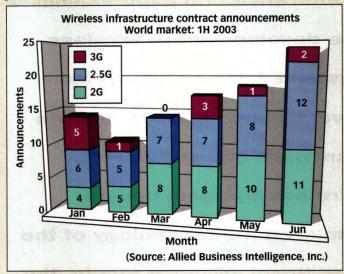
News items from the communications arena.

Wireless Infrastructure Contract Announcements Are Increasing

OYSTER BAY, NY—To satisfy consumer and enterprise demand for data, carriers will continue to deploy traditional cellular networks in the form of GPRS/WCDMA- and CDMA2000-based networks. Other carriers will deploy emerging technologies based on the IEEE 802.16 and

802.20 standards. According to technology research firm Allied Business Intelligence (ABI), infrastructure spending on these technologies will reach \$16 billion by 2007. However, the vast majority of this will be spent on traditional cellular technologies, rather than WiMAX/802.16 or 802.20 equipment.

"Though WiMAX will play a significant role in the industry, the markets for traditional cellular networks will continue to dominate due to their ubiquitous nature," claims Edward Rerisi, ABI's director of research. "Until consumers and businesses demand ever-present fixed/portable broadband wireless coverage, 802.16/20 deployments will not be as extensive. This leaves the door open in the foreseeable future to traditional cellular networks."



ABI projects that the market for WCDMA and CDMA 2000 1X EV-DO deployments will expand over 40 percent on a CAGR-basis over the next four years, eventually representing nearly 70 percent of the overall infrastructure market in 2007. For the first half of 2003, contract announcements have been on the rise (see figure), indicating momentum for the equipment providers.

QUALCOMM Celebrates The 15th Anniversary Of OmniTRACS

SAN DIEGO, CA-QUALCOMM, Inc. has announced that it is celebrating the 15th anniversary of its OmniTRACS® satellite mobile communications system, a solution for real-time data communications, automatic vehicle tracking, and satellite positioning for the transportation industry. In the 15 years since OmniTRACS was introduced, QUALCOMM has shipped nearly 480,000 commercial units to businesses in 39 countries on four continents.

"It has been very exciting to witness Omni-TRACS' contribution to the increased performance and improved efficiency of the transportation industry," comments Dr. Irwin M. Jacobs, QUALCOMM's chairman and CEO. "The success of the OmniTRACS mobile communications system, which makes use of both direct-sequence and frequency-hopped spread-spectrum technology, provided a foundation for the Company's development and commercialization of CDMA wireless technology. QUALCOMM remains focused on continuing the OmniTRACS model of stressing innovations in wireless digital communications that can have major impact on living standards and quality of life worldwide."

More than 1600 US truckload fleets and 2000 NAFTA truckload fleets depend on Omni-TRACS and QUALCOMM's Network Management Center (NMC) to communicate with drivers, monitor vehicle location, and provide superior customer service. Fleet messages are sent via satellite through the NMC to dispatch centers throughout the US. The NMC processes more than seven million data transactions daily.



WWW.WSDEXPO.COM

WIRELESS SYSTEMS DESIGN CONFERENCE AND EXPO 2004

MARCH 8 - 10, 2004 SAN DIEGO CONVENTION CENTER, SAN DIEGO, CALIFORNIA

The Wireless Systems Design **Conference and Expo examines** the development of wireless systems from a true systemlevel through a focus on both hardware and software. **Wireless Systems Design** explores the technology of the traditional wireless staple, the cell phone, but also examines base stations, software defined radios, antennas, digital signal processors and the wireless Internet as they pertain to such applications as medical, automotive and security.

Come and see the top engineering firms that have these products you need for success:

- ▶ Amplifiers/Oscillators
- ▶ Active Components/Semiconductors
- ▶ Basic Materials & Packaging
- Cables & Connectors
- ▶ Computer Aided Design
- ▶ Electronic Design Automation Tools
- ▶ Embedded Systems
- ▶ Fiber Optics
- ▶ Passive Components
- ▶ Services, Publications
- ▶ Software
- ▶ Systems & Subsystems
- ▶ Test Equipment & Instrumentation

The Wireless Systems Design Conference

At the Wireless Systems Design Conference, delve into the technical details of what today's wireless engineer needs to know to be successful.

FOR MORE INFORMATION

Exhibiting

Sharon Pierce, Director of Sales, 203/559-2968, spierce@penton.com Dave Rodriguez, Global Account Manager, 203/559-2805, drodriguez@penton.com

Speaking Opportunities

Stacey Orlick, Associate Director of Programming, 203/559-2948, sorlick@penton.com

Attending

Log onto http://www.wsdexpo.com

Sponsored





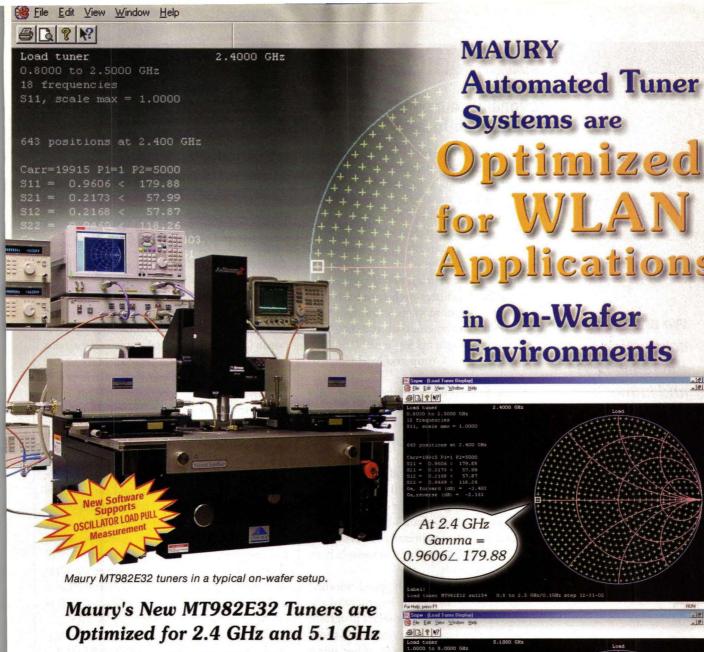












- Ideal for WLAN, Wi-Fi, Bluetooth and WCDMA
- Precision Positioners Eliminate Vibration
- Tuner Integration Adapter for On-Wafer Applications
- Common C++ Software Platform
- ADS/Microwave Office Data Format
- Application Specific Modules
- · Fixture and Pad De-Embedding

0.9606∠ 179.88

Lishel:
Lishe

There has never been a better time to call MAURY for a complete measurement solution; mechanical, solid state, or multi-mode.



MAURY MICROWAVE

CORPORATION

www.maurymw.com



the front end

McDonald's Announces Largest Wi-Fi Launch To Date

CHICAGO, IL—McDonald's has announced the launch of high-speed wireless Internet access for customers in an anticipated 100 restaurants throughout the Chicagoland and Milwaukee areas, with more than 60 of those restaurants offering wireless services immediately. Additional locations will be completed by the end of September.

McDonald's is the first quick-service restaurant to offer customers high-speed wireless access in three major markets—Chicago, New York, and the San Francisco Bay area. In Chicago, McDonald's is working with Toshiba's Computer Systems Group and Intel Corp. to provide the service.

The restaurants chosen for the Chicago pilot program are in a variety of different communities, including 12 locations in Chicago, 44 locations in the Chicago suburbs, as well as five Milwaukee-area locations.

"This is a high-tech blend of innovation and convenience that will tell our customers McDonald's is going to be part of their world," states Phil Gray, McDonald's central division vice president. "We are literally connecting to the relevancy and immediacy of today's busy American way of life."

Toshiba's SurfHere high-speed wireless Internet access service is the key piece of the Chicago area McDonald's wireless program. The SurfHere by Toshiba service allows those with notebook computers and other wireless-enabled devices to connect to the Internet without cables or wires at participating McDonald's. With this wireless technology, business professionals, road warriors, students, tourists, and busy parents can stay in contact and handle business and other communication needs during breakfast, lunch, or throughout the day.

"As the nation continues to go mobile, public demand for wireless access points is experiencing phenomenal growth. Our agreement with McDonald's represents an essential element in building the Toshiba SurfHere foundation and in planning Toshiba's top-quality wireless Internet access for future success and industry leadership," says John Marston, director of business development at Toshiba CSG. "We are extremely excited with this opportunity to demonstrate Toshiba's SurfHere service now benefitting McDonald's customers who

find it necessary to stay connected and productive while out of their home or office."

Intel Corp. and McDonald's have partnered throughout the entire Wi-Fi launch in New York, San Francisco, and Chicago.

Worldwide WLAN Hardware Revenue Tops \$608M In 2Q03

LONDON, ENGLAND—Worldwide wireless localarea-network (WLAN) hardware revenue topped \$608 million in the second quarter of 2003, and is projected to grow to \$3.2 billion in CY06, up about 100 percent from \$1.6 billion in CY02, according to Infonetics Research's quarterly worldwide market-share and forecast service, Wireless LAN Hardware. Growth will be slow and steady over the next four quarters, mostly in the single digits, reaching \$661 million in 2Q04.

"Wireless LANs will continue to show solid growth in all enterprise markets, and access point product vendors are beginning to differentiate between enterprise products and carrier-class access points for hotspots," comments Infonetics Research's Richard Webb, lead analyst of the report. "Wireless broadband gateways, which wirelessly enable cable/DSL connections, will also continue healthy growth, driven simultaneously by telecommuting for enterprises and multimedia entertainment applications, such as online gaming, for consumers."

"The service-provider public-access hotspot market will accelerate slowly through CY03," continues Webb. "It's a small market now, but hotspots are gaining rapid acceptance as an inexpensive way for service providers to drive service subscriptions for an increasingly mobile yet data-reliant workforce. Numerous service providers have indicated their intent to roll out hotspots, spurred on by advances in subscriber and network-management systems."

Wireless LAN Hardware tracks WLAN access points in three function-based categories (standalone, wireless broadband gateways, bridges), and network-integration cards (NICs) in three categories (USB, PCI, and PCMCIA cards). Access points and NICs are broken out by 802.11a vs. 802.11b vs. 802.11g, and the WLAN hardware revenue total is broken out by enterprise vs. consumers vs. service providers. Standalone access points are broken out by SOHO/consumer vs. service provider/enterprise.

We are literally connecting to the relevancy and immediacy of today's busy American way of life."



ATTENUATORS

FEATURES

- * Optimized Bandwidth
- * Flat Phase Response
- * Low Distortion
- * Small Packaging
- * Low Cost

A CORR

APPLICATIONS

- * 3G Amplifiers
- * Cellular
- * PCS
- * WLAN
- * SATCOM/VSAT

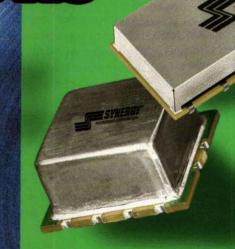


201 McLean Boulevard, Paterson, NJ 07504

Phone: (973) 881-8800 Fax: (973) 881-8361

E-mail: sales@synergymwave.com

World Wide Web: www.synergymwave.com





the front end

Andrew Corp. Completes Communication System For Hong Kong Rail Line

ORLAND PARK, IL—Andrew Corp. has completed the design and installation of a commercial communications system for Hong Kong's Kowloon-Canton Railway Corp.'s (KCRC's) new West Rail line. The Andrew-supplied distributed communications equipment carries the RF signal along the entire line, including tunnels and stations. As a result, commuters traveling on the new 30.5-km (19-mile) Nam Cheong to Tuen Mun line experience uninterrupted calls on their mobile phones.

Andrew supplied and installed EOCellTM fiber-optic distribution equipment, RADIAX[®] radiating cables, and HELIAX[®] coaxial cables and connectors to boost coverage in the West Rail line's nine stations and along part of the track. Amplifiers, installed in the tunnels, provide total coverage for mobile phones and other devices.

"This contract completion is a great endorsement of the quality of our products and service," states Vick Mamlouk, Andrew Corp.'s director of business development for distributed communications systems. "It also emphasizes our excellent relationship with Hong Kong's world-class rail service providers."

With cellular market penetration of 93 percent, Hong Kong has more than six million mobile-phone users—many are regular railway commuters. As a daily average, 817,790 passenger trips are made on the KCRC's East Rail service, and approximately 313,600 passengers use its Light Rail service.

"We are proud that the KCRC has chosen Andrew to provide a high-quality, cost-effective wireless infrastructure," says Simon Leung, Andrew Corp.'s project director for the KCRC project. "Our systems will enhance Hong Kong's commuters' lifestyle, enabling them to stay in touch while they are on the move."

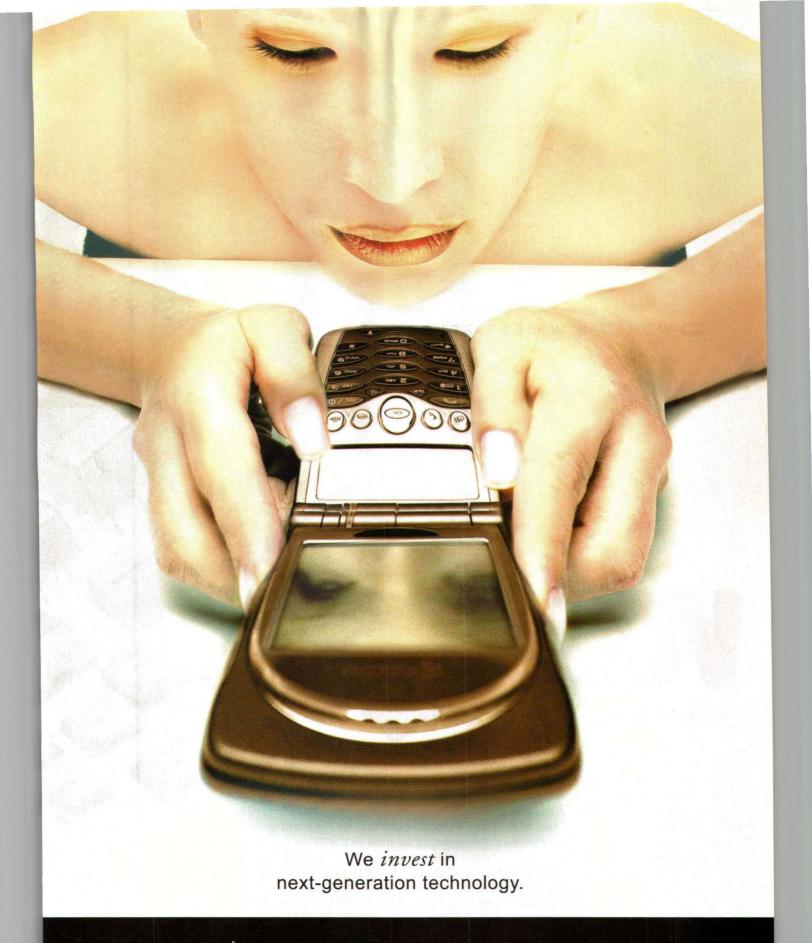
Kudos

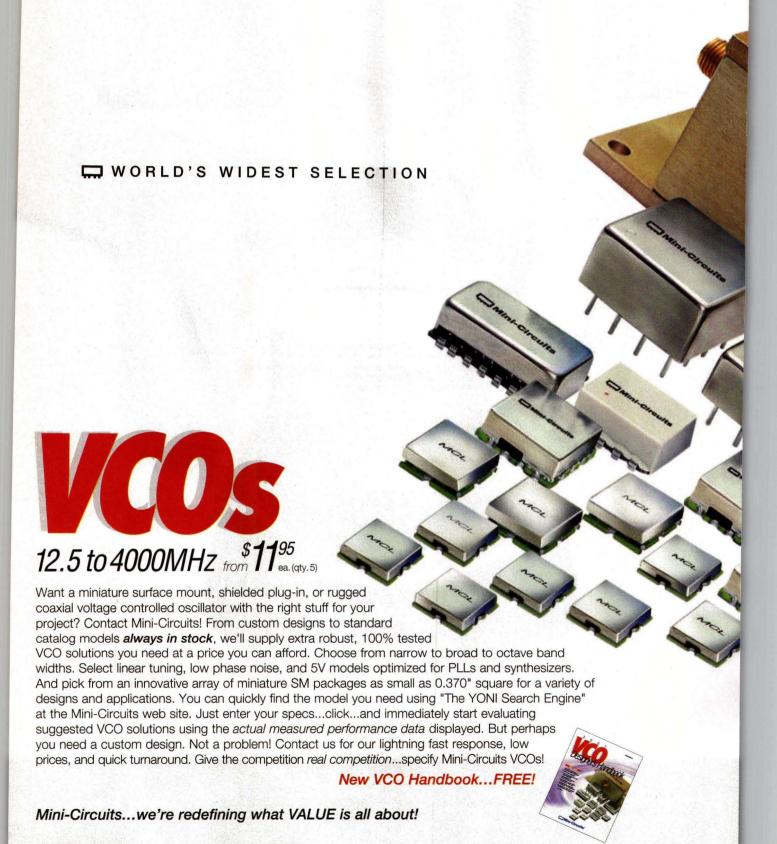
AUSTIN, TX—Wireless Valley Communications, Inc., a developer of products and technical training services for the design, measurement, and management of in-building and campus networks, announced that it has been awarded a US Patent for its wireless site-survey and mea-

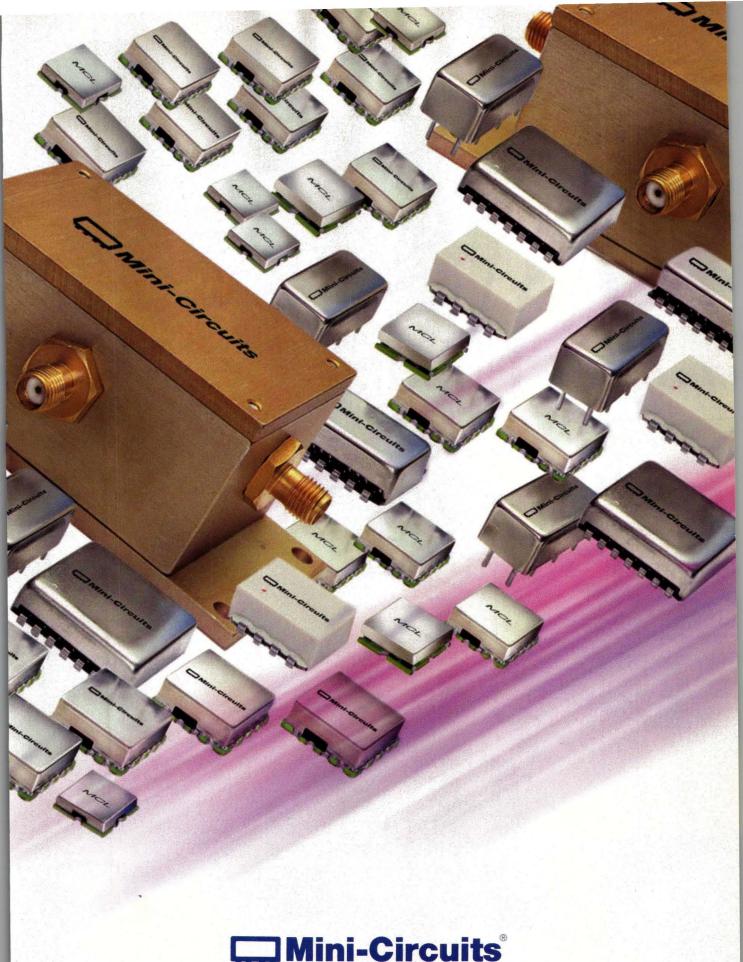
surement acquisition products. US patent 6,422,507, a patent in the field of in-building communication systems and network measurements, teaches fundamental site-survey and site-specific measurement acquisition techniques developed by Wireless Valley. The patent covers inventions used in the InFielder®, InFielder® PDA, and LANFielder® measurement products that work within or remotely with Wireless Valley's SitePlanner® in-building design product. IRVING, TX-Elcoteq Network Corp., global provider of electronics manufacturing services (EMS) for the Communications Technology industry, announced that Elcoteg Americas' Monterrey, Mexico facility has been awarded the 2003 Quality Award by the government of the state of Nuevo Leon, Mexico. The award recognizes those institutions, organizations, or companies who have achieved a level of total quality management. The PNLC (Premio Nuevo Leon a la Calidad) is the equivalent of the European Foundation for Quality Management Award or the Malcom Baldridge Quality Award. GREENSBORO, NC-RF Micro Devices, Inc. (RFMD), a provider of proprietary RF integrated circuits (RF ICs) for wireless communications applications, announced that it has successfully completed its first major customer qualification of its six-inch wafer-manufacturing capabilities. RFMD is converting from four-inch to six-inch wafer-manufacturing capacity at its gallium-arsenide herterojunction-bipolar-transistor (GaAs HBT) fabrication facility, which is located in Greensboro, NC.

RICHARDSON, TX-Anritsu Co. announced that it has recently received approval on an additional 10 RF test cases from the GCF (Global Certification Forum), giving the company a total of 50 GCF-approved test cases, the largest of any test-equipment provider. The recent approval further solidifies Anritsu's commitment to 3G, and provides mobile operators and UE (used-equipment) manufacturers with a single source for virtually any test requirement. WARREN, NJ-ANADIGICS, Inc., a supplier of wireless and broadband communications solutions, has been granted its third patent for the development of a wireless multiband amplifier circuit. US Patent No. 6,501,331 was granted for the development of a gallium-arsenide monolithic-microwave-integrated-circuit (GaAs MMIC) dual-band amplifier for use in wireless handsets for operation at either 800 MHz or the 1900-MHz band to provide gain and input/output impedance. MRF

Our systems
will enhance
Hong Kong's
commuters'
lifestyle,
enabling them
to stay in touch
while they are
on the move."



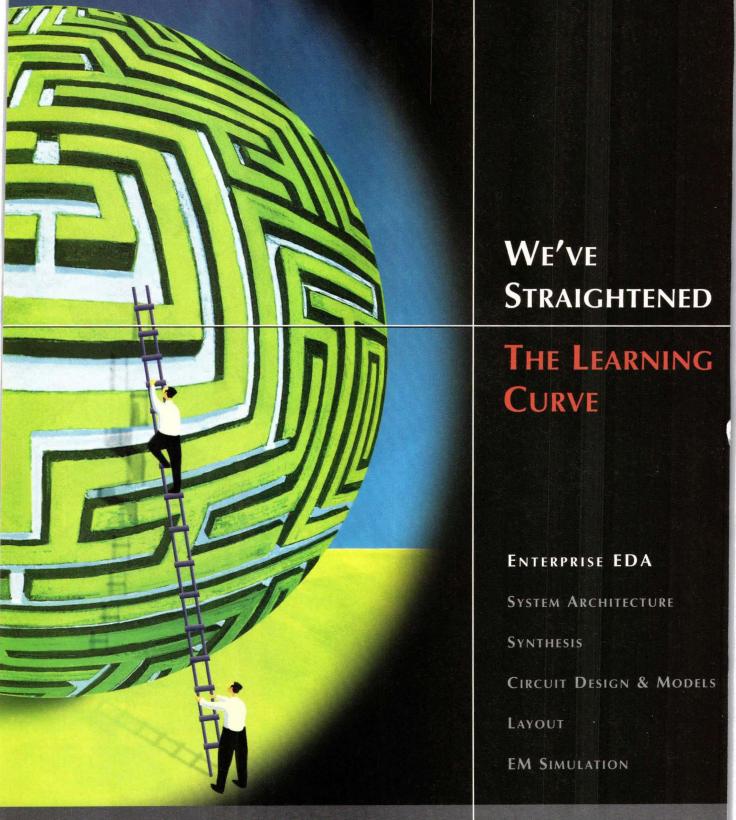






P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 For quick access to product information see MINI-CIRCUITS CATALOG & WEB SITE

The Design Engineers Search Engine Provides ACTUAL Data Instantly From MINI-CIRCUITS At wave ministration.



The shortest distance between two points is a line. So why put up with frustrating, extended learning curves in your microwave engineering software? Intuitive user interfaces, coupled with our comprehensive application notes, getting started guides and users' forum, get you into work mode in record time. Eagleware offers streamlined applications with all the speed, power and accuracy needed for taking you from system architecture through test and manufacturing. And the most responsive technical support in the industry is just a phone call away if needed.

Go straight to the solution. Turn to Eagleware.



+1 678.291.0995 www.eagleware.com



Frequency Synthesizers Yield Stable Signals

Analog and digital frequency synthesizers are available in a variety of shapes, sizes, and technologies, depending on the requirement.

requency synthesizers are used throughout commercial and military systems, in designs as large as complete radar systems and as small as cellular telephones. Based on the number of companies competing for the many markets served by frequency synthesizers (a general search of the Internet will reveal more than 40 suppliers), the demand for synthesized sources with a wide range of performance

> levels is growing, as tuning in high-frequency systems is now dominated by digital approaches (tuning frequencies in discrete steps) rather than earlier analog (continuous tuning) methods.

> Synthesizers are available in physical configurations ranging from packaged integrated circuits (ICs) to moderate-sized modules and hybrid circuits to larger rackmountable system-type synthesizers complete with power supplies and supporting digital monitoring and communications circuitry. Because of the limited scope of this article, it will focus on modules, racks, and instrument-grade frequency synthesizers, with a future article providing details on available IClevel synthesizers.

Various technologies are used in modern frequency synthesizers, including traditional sources based on phase-lockedloop (PLL) technology to lock the phase of a voltage-controlled oscillator (VCO) to that of an inherently more stable reference source, such as a temperaturecompensated crystal oscillator (TCXO) or an oven-controlled crystal oscillator (OCXO). Such synthesizers can be designed with a single loop for optimal frequency switching speed, or with mul-

tiple loops when lower noise performance is required. In essence, they can be called "integer-N" synthesizers where N is the multiplication factor used to determine the output frequency as a multiple of the reference source frequency.

In recent years, newer synthesizer technologies have gained in popularity, including fractional-N frequency synthesizers, which use non-integer values for N, and direct-digital synthesizers (DDS), which rely on the conversion of 32-to-48-b phase/frequency/amplitude digital data into analog output signals through the use of precision accumulators and digital-to-analog converters (DACs). Fractional-N synthesizers can achieve phase-noise levels that are very close to the reference source, although they tend to be limited in bandwidth. A DDS features nanosecond frequency switching speed, but is traditionally limited in spurious performance by the bit resolution of certain of its digital components, and limited in frequency by the clock rates of available digital components.

A DDS is an example of a "direct syn-

JACK BROWNE



NEWS

thesis" technique, in which an output signal is created as a one-to-one function of an input digital word. A large number of digital words that define signal phase (frequency) and amplitude can be stored in memory and pipelined to a DDS, allowing high-speed frequency

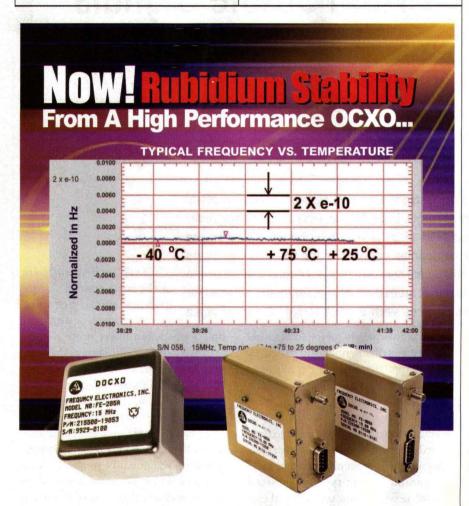
switching and execution of such functions as frequency hopping and generation of complex chirp signals. Direct synthesizers can also be realized by means of analog circuitry by generating, for example, a comb of frequencies and then filtering to select the desired output frequency. While

this approach offers switching speeds similar to that of a DDS, the amount of filtering needed for high-frequency and broadband coverage leads to a design that is complex and expensive.

In some cases, such as the MTS2000-DS multiloop frequency synthesizer from Synergy Microwave Corp. (Paterson, NJ), several technologies are combined in one package. This multiloop PLL frequency synthesizer that also employs DDS technology to achieve extremely small step sizes with relatively fast switching speed. This compact module (10.16 \times 10.16 \times 2.54 cm) tunes from 1 to 2 GHz in step sizes as small as 1 Hz and with phase noise of –94.97 dBc/Hz offset 1 kHz from the carrier (see *Microwaves & RF*, August 2003, p. 92).

Another company that combines analog and digital frequency-synthesis techniques is Elcom Technologies (Rockleigh, NJ), with their UFS series of products. These larger, rack-mount synthesizers are available in narrowband and wideband models through 18 GHz suitable for radar, surveillance, electronic-warfare (EW), and ATE applications. For example, the company's model UFS-15 synthesizer tunes from 1.2 to 3.6 GHz and from 9.6 to 15.0 GHz (two separate output ports per a customer's request) with 1-Hz frequency resolution and 200-ns switching speed. Although DDS sources are traditionally guilty of high levels of spurious content, this synthesizer achieves spurious levels of -67 dBc from 1.2 to 3.6 GHz and -70 dBc from 9.6 to 15.0 GHz. Harmonics are as low as -80 dBc, and single-sideband (SSB) phase noise is a mere -110 dBc/Hz offset 100 Hz from a 12-GHz carrier, -116 dBc/Hz offset 1 kHz from the same carrier, and dropping to -142 dBc/Hz offset 10 MHz from the 12-GHz carrier (a more complete review of the UFS-15 will be available in the November issue).

A long-time supplier of DDS sources, ITT Industries, Microwave Systems (Lowell, MA), which has built upon technology developed by Stanford Telecom during the 1980s and 1990s, offers several lines of DDS-based frequency symmestizers. The firm's WaveCor synthesizers, for example, features sources oper



FEI's new OCXO design concept features a precision double oven crystal oscillator capable of analog or digital tuning. The serial digital tuning is ideal for disciplined applications where holdover is important. The temperature coefficient is less than 1E-10 and is accomplished with no over or under shoot, with fast temperature slew rates of 4° C per minute.

OTHER FEATURES

- -40°C to +75°C Operation
- Low Aging <5 E-8 for 10 yrs.
- . LSB ≈ 1.7 E-14
- · Retrace 1E-10 after 1 hour, 24hrs off
- Any frequency 5 MHz to 25 MHz



FEI COMMUNICATIONS, INC.

A subsidiary of Frequency Electronics, Inc. 55 Charles Lindbergh Blvd., Mitchel field, NY 11553 TEL: 516-794-4500 • FAX: 516-794-4340 Visit Us At: www.freqelec.com



500MHz-5.9GHz

MMIC AMPLIFIERS



Built-In RF Choke, Resistors, Bypass & Coupling Capacitors

Simplify your 500MHz to 5.9GHz designs with Mini-Circuits easy to use MNA and VNA amplifiers. With DC blocking capacitors and a biasing network built-in, all you do is drop the amplifier in place on your PC board, connect, and the job is done! There's no biasing to figure out and no external components

to connect. Broadband low and high power models offer gain from 9 to 23dB and power output from 7 to 19dBm. High isolation, typically greater than 40dB, makes them terrific for use as an isolator. And the versatility to operate from a

Biasing
Configuration

perfect for today's miniature battery operated hand-held devices. Two different package styles are available; MNA's leadless 3x3mm MCLPTM (Mini-Circuits Low Profile) SM package with exposed metal bottom for excellent grounding and heat dissipation, and VNA's leaded

SOIC-8 for easier assembly...all value priced and ready to ship! So simplify your design, your manufacturing, and your life with Mini-Circuits all-in-one MNA and VNA MMIC amplifiers.

Mini-Circuits...we're redefining what VALUE is all about!

			(GHz)	(V)	Typ.	(dBm) Typ.	\$ea. (qty.30)
	ACTUAL SIZE	MNA-2	0.5-2.5	5.0 2.8	12.8 11.2	17.7 12.9	1.90
	0	MNA-3	0.5-2.5	5.0 2.8	16.1 15.0	11.4 9.7	1.60
		MNA-4	0.5-2.5	5.0 2.8	16.4 14.5	19.0 13.4	1.90
		MNA-5	0.5-2.5	5.0 2.8	21.9 20.5	12.2 10.1	1.60
		MNA-6	0.5-2.5	5.0 2.8	23.6 21.2	18.0 14.1	2.25
		MNA-7	1.5-5.9	5.0 2.8	15.9 13.7	15.6 12.7	2.25
		VNA-21	0.5-2.5	5.0 2.8	13.5 12.3	8.5 7.0	1.80
		VNA-22	0.5-2.5	5.0 2.8	13.8 12.6	17.0 14.0	2.20
		VNA-23	0.5-2.5	5.0 2.8	18.3 17.1	10.0 8.5	1.90
		VNA-25	0.5-2.5	5.0 2.8	18.6 17.4	18.2 12.0	2.50
		VNA-28	0.5-2.5	5.0 2.8	22.8 21.0	11.0 9.6	1.95

Amplifier Designer's Kits

K1-MNA: 10 of ea. MNA-2, 3, 5, 6...\$69.95 K2-MNA: 10 of ea. MNA-2, 3, 4, 5, 6, 7...\$99.95 Application note for PCB layout included.

Detailed Performance Data & Specs Online at: www.minicircuits.com/amplifier.html



P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 For quick access to product information see MINI-CIRCUITS CATALOG & WEB SITE

The Design Engineers Search Engine Provides ACTUAL Data Instantly From MINI-CIRCUITS At: www.minicircuits.com



WWW.WSDEXPO.COM

WIRELESS SYSTEMS DESIGN CONFERENCE AND EXPO 2004

MARCH 8 - 10, 2004 SAN DIEGO CONVENTION CENTER, SAN DIEGO, CALIFORNIA

The Wireless Systems Design **Conference and Expo examines** the development of wireless systems from a true systemlevel through a focus on both hardware and software. **Wireless Systems Design** explores the technology of the traditional wireless staple, the cell phone, but also examines base stations, software defined radios, antennas, digital signal processors and the wireless Internet as they pertain to such applications as medical, automotive and security.

Come and see the top engineering firms that have these products you need for success:

- ▶ Amplifiers/Oscillators
- ▶ Active Components/Semiconductors
- ▶ Basic Materials & Packaging
- ▶ Cables & Connectors
- ▶ Computer Aided Design
- ▶ Electronic Design Automation Tools
- Embedded Systems
- ▶ Fiber Optics
- ▶ Passive Components
- ▶ Services, Publications
- ▶ Software
- ▶ Systems & Subsystems
- ▶ Test Equipment & Instrumentation

The Wireless Systems Design Conference

At the Wireless Systems Design Conference, delve into the technical details of what today's wireless engineer needs to know to be successful.

FOR MORE INFORMATION

Exhibiting

Sharon Pierce, Director of Sales, 203/559-2968, spierce@penton.com Dave Rodriguez, Global Account Manager, 203/559-2805, drodriguez@penton.com

Speaking Opportunities

Stacey Orlick, Associate Director of Programming, 203/559-2948, sorlick@penton.com

Attending

Log onto http://www.wsdexpo.com

Sponsored















SYNTHESIZER SOLUTIONS NEW SERIES DS...



The DS synthesizers are exceptionally quiet, fast, broadband and precise. Their phase noise rivals the best microwave fixed-frequency sources. With one microsecond or less typical switching time, the DS delivers ample speed to meet the required response times of most automatic test systems and frequency-agile equipment.

- FAST SWITCHING
 DIRECT SYNTHESIZER
- -WIDE BANDWIDTH
- **-VERY LOW PHASE NOISE**

Frequency Range (MHz)	100Hz (dBc/Hz)	1 kHz (dBc/Hz)	10 kHz (dBc/Hz)	100 kHz (dBc/Hz)	1 MHz
10 GHz	-92	-110	-120	-120	-128
1 GHz	-111	-127	-137	-139	-147
100 MHz	-125	-135	-145	-150	-153

- Wide Bandwidth: 0.005 to 20.48 GHz Available in a Single Synthesizer
- Very Low Phase Noise: -120 dBc/Hz Typ. at 10 kHz Offset at 10 GHz
- 0.3 to 1 Microsecond Typical Switching Time
- Steps Sizes Down to 1 Hz
- Low Profile Chassis or Modular Configuration
- · Standard Bands:

2.56 to 10.24 GHz/250 kHz steps 2.56 to 10.24 GHz/1 Hz steps 640 MHz to 10.24 GHz/250 kHz steps 640 MHz to 10.24 GHz/1 Hz steps 5 MHz to 10.24 GHz/1 Hz steps

- Low Spurious
- Parallel BCD Programming
- · Low Power Consumption/High Reliability
- · Low Sensitivity to Microphonics

CET THE PERFORMANCE

YOU NEED for your

Automated Test Systems,

Radar, EW Simulation and

Surveillance Equipment

CALL THE EXPERTS!



9 Whippany Rd. • Whippany, NJ 07981 TEL: 973-884-2580 • FAX: 973-887-6245 www.cti-inc.com • e-mail: sales@cti-inc.com



ating in bands from 50 MHz to 20 GHz with spurious levels of less than -80 dBc and phase noise of -140 dBc/Hz offset 10 kHz from the carrier. Capable of switching frequencies in less than 200 ns, these high-performance sources are housed in a compact, six-inch cube.

In contrast, Advanced Radio Corp. (Reston, VA) is a newcomer on the list of synthesizer suppliers (see Microwaves & RF, April 2003, p. 94). The firm's ADV-3000S synthesizer module leverages DDS technology to achieve low phase noise and spurious performance of better than -90 dBc from 20 MHz to 3 GHz, with optional coverage to 18 GHz. The fast-switching synthesizer is well suited as a programmable LO for radar, signal-intelligence (SIGINT), and electronic-warfare (EW) applications. Through the use of innovative spurious-concealing circuitry, the company's engineers have managed to suppress DDS spurious noise by more than 30 dB compared to traditional DDS filtering methods.

Although advances occur quickly with digital synthesizer approaches, improvements are also being made with analog technologies. Micro Lambda Wireless (Fremont, CA), for example, bases its low-noise synthesizers on its buildingblock YIG oscillator technology, offering both wideband and narrowband frequency synthesizers. Its wideband models, for example, are suitable for use as LOs in communications equipment or a signal sources in test equipment. The MLSW wideband series includes the 0.6-to-3.0-GHz model MLSW-0603, the 2-to-8-GHz model MLSW-2080, and the 2-to-10-GHz model MLSW-2010. The synthesizes feature 1-Hz frequency resolution, power levels of +10 to +12 dBm, and spurious levels of -60 dBc. The phase noise is typically -100 dBc/Hz offset 1 kHz from the carrier and -108 dBc/Hz offset 10 kHz from the carrier. At a 1-MHz offset, the phase noise for the 3-GHz synthesizer is -140 dBc/Hz, with levels of -138 dBc/Hz from the 8-GHz synthesizer and -135 dBc/Hz for the 10-GHz unit. The synthesizers, which measure $7 \times 5 \times 1$ in. $(17.78 \times 12.7 \times 2.54 \text{ cm})$ and consume only 29 W, achieve full-band tuning in 13 to 18 ms, and tune across a

100-MHz step in only 10 ms.

The company's newly expanded MLSN series of narrowband synthesizers now includes models operating in 2-GHz bands from 2 to 16 GHz. These sources, which feature similar or improved phasenoise performance compared to the wideband MLSW models, also tune in 1-Hz steps and achieve better than +10 dBm output power through 9 GHz and better than +8 dBm output power through 16 GHz. As an example, the highest-frequency model, the 14-to-16-GHz MLSN-1416, features 1-Hz frequency resolution and 12-ms full-band tuning speed. Spurious noise is typically -60 dBc while phase noise is -94 dBc/Hz offset 1 kHz from the carrier, -101 dBc/Hz offset 10 kHz from the carrier, and -135 dBc/Hz offset 1 MHz from the carrier.

Another company that espouses the use of YIG technology in its frequency synthesizers is Endwave Corp. (Sunnyvale, CA). The firm offers compact modular frequency synthesizers in bands as wide as 2 GHz from 4.5 to 14.0 GHz with phase noise as low as -100 dBc/Hz offset 10 kHz from the carrier. For example, the company's 50 Series includes the 4.5-to-7.0-GHz model SYN-50A-00 and the 7-to-10-GHz model SYN-50B-00. Both tune over a 1500-MHz tuning range in 125kHz steps with phase noise of -100 dBc/Hz offset 10 kHz from the carrier, dropping to -143 dBc/Hz offset 1 MHz from the carrier. The typical output power is better than +10 dBm for both models, and spurious content is typically less than -70 dBc. The 50 Series synthesizers measure $3.9 \times 3.12 \times 1.38$ in. $(9.9 \times 7.9 \times 3.5 \text{ cm}).$

Endwave's 20 Series includes the 7.9-to-8.4-GHz model SNY2018E and the 8.0-to-8.3-GHz model SYN2018F. These models tune with maximum step sizes of 27.5 and 20 MHz, respectively, achieving spurious levels of –70 dBc. The sources feature +10 dBm output power and have phase noise levels of –85 dBc/Hz offset 10 kHz from the carrier and –140 dBc/Hz offset 1 MHz from the carrier. They measure $6.25 \times 2.98 \times 1.1$ in. $(15.9 \times 7.6 \times 2.8$ cm).

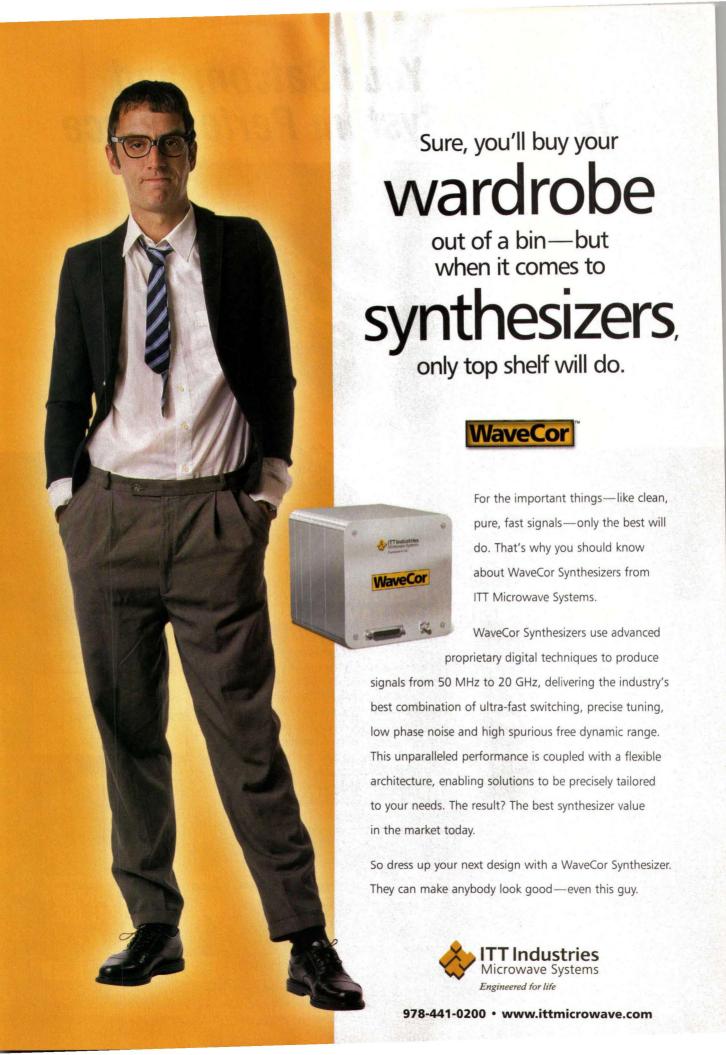
TRAK Microwave Corp. (Tampa, FL) is another well-known supplier of high-

38

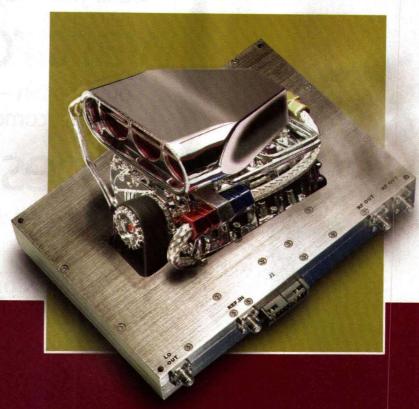
speed frequency synthesizers, employing both direct and indirect analog synthesis techniques. An example of a direct analog unit is a 7-to-9-GHz model with 1-MHz step size and 500 ns maximum switching speed. The synthesizer employs a bank of crystal oscillators, which undergo frequency conversion, switching, and filtering to generate the final output frequencies. This synthesizer generates relatively high output power of +19 dBm with spurious levels of -60 dBc, and phase noise of -110 dBc/Hz offset 10 kHz and -120 dBc/Hz offset 1 MHz from the carrier. The unit, which includes a power supply, measures $15 \times 8.5 \times 5$ in. $(38.1 \times 21.6 \times 12.7 \text{ cm})$.

The company's indirect analog synthesizers are based on selecting and filtering frequencies from a comb generator. The firm's lineup includes a 575-to-1075-MHz synthesizer capable of better than 100-ns switching speed. Although possessing large frequency steps (25 MHz), the source boasts good phase noise, with performance of –110 dBc/Hz at 1 kHz offset, –130 dBc/Hz at 10 kHz offset, and –140 dBc/Hz at 10 MHz offset from the carrier. The synthesizer measures $6.5 \times 4.6 \times 0.95$ in. (16.51 × 11.7×2.4 cm).

Communications Techniques, Inc. (Whippany, NJ) is a veteran supplier of microwave frequency synthesizers, offering one of the larger varieties of package styles of synthesizer topologies. For example, the company's Series DS synthesizers are rack-mount, instrument-grade synthesizers capable of achieving a full tuning range of 0.005 to 20.48 GHz in a single unit. Available as a rack-mount or modular unit, the DS synthesizers feature typical switching speeds of 0.3 to 1 μs, frequency steps as small as 1 Hz, and +13 dBm output power. The direct analog frequency synthesizers achieve spurious levels of -64 to -80 dBc, depending upon frequency. The SSB phase noise is -109 dBc offset 1 kHz from a 10-GHz carrier, -119 dBc/Hz offset 10 kHz from the same carrier, and -128 dBc/Hz offset 1 MHz from the same carrier. For a 1-GHz carrier, the phase noise is -127 dBc/Hz offset 1 kHz, -137 dBc/Hz offset 10 kHz, and -147 dBc/Hz offset 1 MHz.



Rev Up Your Satcom and Telecom System Performance



HIGH PERFORMANCE NARROW BAND FREQUENCY SYNTHESIZERS FIELD PROVEN FOR 256, 512 AND 1024 QAM SYSTEMS.

Micro Lambda Wireless, Inc. a leader in the development of next-generation YIG devices introduces a new line of high performance narrow band frequency synthesizers covering the 2 GHz to 10 GHz frequency range. Designed specifically for narrow band and low noise applications, these new frequency synthesizers can improve your Satcom or Telecom system performance immediately.

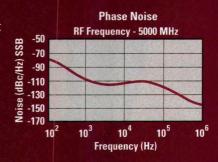
MLSN-SERIES NARROW BAND FREQUENCY SYNTHESIZERS.

This series of frequency synthesizers offers standard 2 GHz wide tuning ranges covering 2 GHz to 10 GHz. Output power levels of between +10 dBm and +12 dBm are offered depending on frequency band. Frequency step size of 1 Hz is standard, but is programmable with software for customer specific requirements. External reference

frequency of 10 MHz is utilized, but 5 to 50 MHz are offered as options. Excellent phase noise performance at 100 Hz offset of -80 dBc/Hz, at 1 kHz of -100 dBc/Hz, at 10 kHz offset of -108 dBc/Hz, at 100 kHz offset -120 dBc/Hz and at 1 MHz offset -145 dBc/Hz are provided for a 3.0 GHz to 5.0 GHz unit. The units operate from +15 Volt and +5 Volt supply lines and frequency control is via a 5-wire serial (SPI & busy) input protocol. Options include dual RF outputs and/or an L-band 2nd L.O. All units measure 5" x 7" x 1" and weigh 28 oz.

FEATURES

- 2.0 to 10.0 GHz Coverage in 2 GHz Bands
- · Excellent Phase Noise
- 1 Hz Step Size
- . Optional Dual RF Outputs
- Optional 2nd L.O. Output



"Look to the leader in YIG-Technology"









NEWS

The company's broadband Series BBS synthesizers includes models covering as wide as 0.01 to 5.12 GHz in a single unit with step sizes from 1 Hz to 10 MHz. The typical phase noise is -131 dBc/Hz offset 100 kHz from a 1-GHz carrier, while spurious levels range from -63 to -85 dBc, depending upon frequency. These compact synthesizers measure just $3.6 \times 5.8 \times 0.98$ in. $(9.1 \times 14.7 \times 2.5$ cm), excluding connectors, and deliver output levels from +13 to +17 dBm.

Another long-time supplier of frequency synthesizers, MITEQ (Hauppauge, NY), offers frequency synthesizers to 40 GHz. The company's SLS Series is optimized for fast switching applications including wireless-communications and satellite-communications systems, while the MFS series provides extremely low phase noise for critical satellite communications applications. The firm's unique CFS series of synthesizers offers dual output signals for systems requiring dual upconversion or downconversion. These synthesizers provide output signals in Ku-band (12.710 to 13.280 GHz) and L-band. The synthesizers switch in 125-kHz steps with +13 dBm output power with -70 dBc spurious content.

A long-time supplier of instantaneousfrequency-measurement (IFM) receivers, and user of frequency synthesizers, is now also a supplier: Wide Band Systems (Rockaway, NJ). The company's model PS-070-180A tunes from 7 to 18 GHz in 1-MHz steps and offers at least +13 dBm output power. It settles to a new frequency in 100 µs or less and boasts spurious levels of -50 dBc or better. The SSB phase noise is typically -60 dBc/Hz offset 1 kHz from the carrier, -65 dBc/Hz offset 10 kHz from the carrier, and -110 dBc/Hz offset 1 MHz from the carrier. The synthesizer measures $4 \times 4 \times 8$ in. $(10.16 \times 10.16 \times 20.32 \text{ cm}).$

The frequency synthesizers mentioned above rely on digital commands from a control bus for executing frequency and amplitude changes, making many of them suitable for automatic-test-equipment (ATE) applications. Some test applications, however, require a more flexible local interface for control, as evidenced by another class of frequency synthesiz-

er designed for instrumentation applications. Suppliers include Aeroflex (Plainview, NY), Agilent Technologies (Santa Rosa, CA), Anritsu (Morgan Hill, CA), Communications Techniques, Giga-tronics (San Ramon, CA), Rohde & Schwarz (Munich, Germany), Programmed Test

Sources (Littleton, MA), and Universal Microwave Corp. (Odessa, FL, see p. 55). For more information on these and other suppliers of frequency synthesizers, please refer to the *Microwaves* & *RF Product Data Directory* website at www.m-rf.com.



editor's choice

Module Replaces Wires With 868-MHz Links

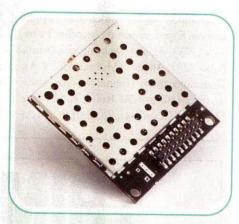
MILES OF CABLES in harsh environments can be replaced easily with the AC4486 transceiver module. The module interfaces to other designs by means of serial TTL connections for efficient, bidirectional communications at data rates to 115.2 kb/s. The transceiver module is available in two versions: model AC4486-5, which operates from 869.7 to 870.0 MHz, and model AC4486-500, which operates in dual frequency bands of 868 to 870 MHz and 902 to 928 MHz. The singlefrequency module consumes about 35 mA typical current on transmissions while the dual-frequency unit consumes 200 mA typical current during transmissions; current consumption is less in both cases for reception.

AeroComm, 10981 Eicher Dr., Lenexa, KS 66219; (913) 492-2320, FAX: (913) 492-1243, Internet: www.aerocomm.com.

Failsafe SMA Switch Handles 200 W Power

DESIGNED TO WITHSTAND high-shock environments, the model 401A-630832 singlepole, double-throw (SPDT) failsafe SMA switch is suitable for applications from DC to 18 GHz. It can handle as much as 200 W CW input power from DC to 4 GHz, as much as 160 W CW input power from 4 to 8 GHz, and at least 90 W CW input power from 8 to 18 GHz. Maximum insertion loss is 0.15 dB from DC to 4 GHz, reaching a maximum of 0.45 dB from 12 to 18 GHz. The minimum isolation between ports is 80 dB from DC to 4 GHz, 70 dB from 4 to 8 GHz, 65 dB from 8 to 12 GHz, and 60 dB from 12 to 18 GHz. The switch, which can handle peak power levels exceeding 400 W, is designed to withstand mechanical shock of 100 G's for 6 ms and pyrotechnic shock levels to 2000 G's.

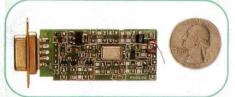
Dow-Key Microwave Corp., 4822 McGrath St., Ventura, CA 93003-7718; (805) 650-0260, (805) 650-1734, Internet: www.dowkey.com.



AEROCOMM'S AC4486 TRANSCEIVER MODULE



DOW-KEY'S MODEL 401A-630832 FAILSAFE **SMA SWITCH**



OTEK CORP.'S TRANSCEIVER MODULE MODEL TR200



RLC ELECTRONICS BROADBAND STRIPLINE COUPLERS

Wireless Transceiver Operates At 915 MHz

LOW-COST TRANSCEIVER module model TR200 is ideal for stationary wireless transmission and reception (two units are required) of process control and telemetry data at rates to 19.2 kb/s. The transceiver operates in the 916.5-MHz unlicensed industrial-scientific-medical (ISM) band and can achieve operating ranges of 100 ft. indoors and 300 ft. outdoors. Digital input/output (I/O) connections include RS-232C, 485, and TTL connections. The transceivers, which employ on-off-keving (OOK) or amplitude-shift-keying (ASK) modulation, operate with peak transmitter power of 1 mW. The transceiver measures only $1.85 \times 1.85 \times 0.4$ in.

OTEK Corp., 4016 E. Tennessee St., Tucson, AZ 85714-2130; (520) 748-7900. FAX: (520) 790-2808, e-mail: sales@otekcorp.com, Internet: www. otekcorp.com.

Stripline Couplers Range 0.7 To 7.0 GHz

A LINE OF BROADBAND stripline couplers feature outstanding electrical performance from 0.7 to 7.0 GHz. Three models are currently available with coupling values of 10 dB (model C-0770-10-R), 16 dB (model C-0770-16-R), and 20 dB (model C-0770-20-R). All three models offer minimum directivity of 20 dB with maximum VSWR of 1.25:1. Amplitude deviations across the frequency range are no worse than ±1.0 dB. Maximum insertion loss for any of the couplers is 0.6 dB across the full 0.7-to-7.0-GHz frequency range. The 50-Ω couplers are supplied with SMA female connectors and rated for operating temperatures from -55 to +85°C. The couplers are suitable for a wide range of measurements and communications applications.

RLC Electronics, Inc., 83 Radio Circle, Mount Kisco, NY 10549; (914) 241-1334, FAX: (914) 241-1753, e-mail: sales@rlcelectronics.com, Internet: www.rlcelectronics.com.

ynergy's new line of COMBLINE Rx/Tx band pass FILTERS and DUPLEXERS adds to our wide range of high performance Low Pass, Band Pass and High Pass filters. With its high rejection of greater than +70 dB and an insertion loss of less than +1 dB, these Filters and Duplexers are the perfect choice for your cellular and PCS band requirement. Varying from model to model, the power handling capacity of these new line of filters ranges from 20 watts to 100 watts. For additional information, contact Synergy's sales and application team. 201 McLean Boulevard, Paterson, NJ 07504

Phone: (973) 881-8800 Fax: (973) 881-8361

World Wide Web: www.synergymwave.com

E-mail: sales@synergymwave.com



Mimix Secures \$6.7M In Funding

MIMIX BROADBAND, INC., a fabless semiconductor company for wireless communications, announced that it has secured \$6.7 million in an initial close of its second round of institutional funding. This round of funding was

led by 3i, an international venture capital company, and First Capital Group of San Antonio, TX. The majority of existing shareholders also participated in this round. Proceeds will be used to expand Mimix's product portfolio of highly integrated and high-power monolithic microwave integrated circuits (MMICs).

Mimix designs, develops, and supplies MMIC solutions for the microwave and millimeter-wave wireless-communications markets. Mimix has assembled a team of scientists experienced in the design of highly integrated and high-power semiconductor devices, as well as complete communications systems design.

"The commitment received from our investors for this round of funding confirms the confidence our shareholders have in Mimix to achieve success as a long-term supplier of MMIC solutions," says Arthur Epley, Mimix's chairman of the board. "We are pleased with the progress that Mimix is making, and feel fortunate to have these world-class investors supplying deep resources and expertise and supporting our growth efforts."

"This second round of institutional funding led by 3i and First Capital Group allows us to aggressively continue building out our product portfolio and serving our expanding list of customers," states Rick Montgomery, CEO of Mimix. "Our strategy is to provide industry-leading, high-power, and multifunction MMIC devices designed for superior performance. We see our MMIC products as revolutionary technology that is enabling market growth."

"As a returning co-lead investor, First Capital Group remains enthusiastic about Mimix's future and its ability to successfully execute its business plan," comments Jeff Blanchard of First Capital Group. "Our investment in Mimix reflects how delighted we are with the progress that Mimix has made over the past two years."

The Next Generation Synthesizer

ADV-3000S VME Synthesizer Module

- · Low Phase Noise
- Fast Tuning <10μsec,
 450 nano-sec optional
- Phase Coherent/Continuous
- Frequency Coverage 1MHz to 18GHz
- FSK, BPSK, PSK, CHIRP, AM Operation
- Low Power <16 watts

Applications

- LO Subsystems
- Exciters
- Threat Simulators
- Test and Measurement
- Airborne/UAV Platforms



PHASE NOISE PERFORMANCE 1 Hz.......-52dBc/Hz 10 Hz.....-87 dBc/Hz 100 Hz.....-107 dBc/Hz 1 kHz....-126 dBc/Hz 10 kHz...-147 dBc/Hz 100 kHz...-152 dBc/Hz

Advanced Radio Corporation™

1800 Alexander Bell Drive, Suite P100, Reston, Virginia 20191 703-435-5900 Phone • 703-435-1100 Fax www.advradio.com • info@advradio.com

WISION = WALUE



Specialization within Wests Not Years

ARRelimes' new Vision Concept serves you of the antifumoney by latting you specify an amplifier within a defined trequency range from 5 beats modules offered!

- Choose the Power and Frequency You Need From
 the 5 Basic Modules Offered Each Covers a Portion
 of the 0.5 MHz 4.2 GHz, 6 500 Water Range
- · Owick Turnaround Time Without the Usual High Cost
- Allows a "Proof of Principle" Test Quickly and Accurately
- Unique Power Supply Makes It Easy
- · Mix and Match Components

- Build Any or All of Your System: Control Modules, Wring Hamesses, Switching Modules, Couplers, Combiners/Splitters
- · Complete Documentation is Supplied .

Your Specs. Our Components. To Build an Amplifier That Meets Your Unique Requirements Quickly.

To find out more about the ARKalmus Mision Concept; call us at 425,485,5000 to request a brothure or download one at www.arkalmus.com









companynews

CONTRACTS

QUALCOMM, Inc.—Announced that they and Science Applications International Corp. (SAIC) have been awarded a \$2 million contract from the US Department of Transportation's Federal Motor Carrier Safety Administration (FMCSA) for the development and field testing of an untethered trailer assetmanagement system for high-value or high-security-risk loads. The system will provide sophisticated on-board hardware, advanced power management, network services, and extensive data-integration capabilities using state-of-theart, tri-mode (digital cellular, PCS, and analog) communications. QUALCOMM and SAIC were one of three teams solicited to submit proposals in FMCSA's Request for Proposal process in early July.

Herley Industries, Inc.—Received multiple contracts totaling \$1.7 million to supply microwave hardware for US Missile Defense applications. The contracts include standard Herley products as well as requirements for Herley to design and develop application-specific hardware.

FRESH STARTS

RF Logic, LLC—Announced the appointment of Advanced Communications as their exclusive representative in the Northern California territory. RF Logic is a supplier of coaxial-cable assemblies and custom test equipment and components to both the RF microwave and high-speed digital markets. Trompeter Electronics—Has begun systematically relocating its California manufacturing operations to Mesa, AZ. Mesa is the headquarters of Semflex, a sister company to Trompeter.

Cookson Electronics Equipment [CEE] (also known as Speed-line Technologies, Inc.)—Announced that it has entered into an exclusive partnership with MMI Systems Pte Ltd. for the manufacture of certain MPM stencil printers. The deal has been concluded after an intensive search to find a partner in the Asian marketplace that will provide customers with added capacity, delivery, service, and competitive pricing. The new facility will be located in the Suzhou Industrial Park in the Shanghai region of China.

Rosenberger OSI Fiber Optics—Recently established a North American presence by opening a sales, engineering-support, and distribution facility in Lancaster, PA. Rosenberger OSI Fiber Optics is a division of Rosenberger of North America, LLC, a supplier of coaxial connectors and cable assemblies. Dr. Stephen Sacco is the technical director for the new fiber-optics division.

In addition to Lancaster, PA, Rosenberger OSI Fiber Optics also has facilities in Germany, Hungary, Brazil, and China.

MEMGen Corp.—Has changed its name to Microfabrica, Inc. The name change is effective immediately. It was imple-

visit PlanetEE.com

mented in order to more accurately represent the company's microdevice manufacturing capabilities.

Dynaloy, Inc.—Announced the recent opening of a direct field sales office in Taiwan to support growth in the customer base located in the region.

Texas Instruments Radio Frequency Identification (TI-RFid™) Systems—Has named Digi-Key Corp. of Thief River Falls, MN as an authorized distributor of TI-RFid products for the Americas. Digi-Key has added Texas Instruments RFid Systems' full line of low-frequency and high-frequency transponders and readers, integrated circuits (ICs), reader ASICs, and RFID Evaluation Kits to its line of product offerings.

The agreement with Digi-Key extends the distribution of TI-RFid products to design engineers who are building RFID-based systems. Texas Instruments' RFID products are used in a variety of applications, including automotive security, vehicle and personnel access control, product and asset tracking, wireless payment, sports timing, product authentication, ticketing, document management, and supply-chain tracking.

Universal Microwave Corp. (UMC)—Announced the opening of UMC's new Worldwide Sales and Customer Support Center. The new facility in Tempe, AZ will produce enhanced and expanded sales and customer service support for UMC's customers, representatives, and distribution network. The contact information for UMC's Worldwide Sales and Customer Support Center is: 4703 S. Lakeshore Dr., Suite #2, Tempe, AZ 85282; (480) 756-6070, FAX: (480) 756-6026, e-mail: sales@vco1.com.

Andrew Corp.—Announced that the 2004 Lincoln Aviator luxury Sports Utility Vehicle (SUV) is using an Andrew concealed Global Positioning System (GPS) antenna as an integral part of the vehicle's navigation system. Using GPS and map-matching technologies, the Lincoln Aviator's DVD-based navigation system can pinpont the vehicle's location (to within a 10-ft. radius) and guide the driver to the destination with easy-to-read visual directions on a 6.5-in.(16.5-cm) color touch-screen display. When integrated with the vehicle's sound system, the navigation system also imparts turn-by-turn audio directions.

The Andrew GPS Antenna System used on the Lincoln Aviator is a low-profile design, with an output signal matched to give the navigation system optimal performance. The Andrew ceramic patch antenna with its low-noise amplifier provides a 26-dB signal gain for tracking space-based satellites that determine the vehicle's location. The antenna is concealed beneath the vehicle's dashboard. To ensure ease and accuracy of installation, the Andrew antenna is mounted integrally on the vehicle's instrument panel assembly. The DVD Navigation System is a factory-installed option on the Lincoln Aviator.

Andrew also supplies GPS antennas for Lincoln's 2004 Navigator SUV, Town Car, and LS vehicles. Andrew provides concealed and roof-mount GPS antennas for Jaguar and Land Rover Discovery Vehicles.



Mini-Circuits VAT and HAT fixed attenuators rank at the top of their class for high performance, big selection, and low cost! Choose from 14 different attenuation values; from 1 to 10dB in 1dB steps plus 12, 15, 20, and 30dB. All in stock, ready for immediate shipment, and value priced from only \$9.95 for SNC (HAT) and \$11.95 for SMA (VAT). Performance wise, these devices offer excellent attenuation flatness, low VSWR, and handle up to 500mW input power. Plus, rugged unibody construction makes them very easy to use in systems, testing, and product development applications. So get the best economy from your design with Mini-Circuits fixed attenuators.

Mini-Circuits...we're redefining what VALUE is all about!

	dels	Attenu	ation* (dB)	
SMA-M/F	BNC-M/F	Nominal	Flatness	VSWR (:1)
DC-6GHz	DC-2GHz		Midband Typ.	Midband Typ.
VAT-1	HAT-1	1 1	0.20 0.11	1.10 1.2
VAT-2	HAT-2	2 2	0.20 0.10	1.20 1.2
VAT-3	HAT-3	3 3	0.15 0.12	1.15 1.1
VAT-4	HAT-4	4 4	0.15 0.08	1.15 1.1
VAT-5	HAT-5	5 5	0.10 0.06	1.15 1.1
VAT-6	HAT-6	6 6	0.10 0.02	1.15 1.1
VAT-7	HAT-7	7 7	0.10 0.05	1.15 1.1
VAT-8	HAT-8	8 8	0.10 0.04	1.20 1.1
VAT-9	HAT-9	9 9	0.10 0.02	1.15 1.1
VAT-10	HAT-10	10 10	0.20 0.03	1.20 1.1
VAT-12	HAT-12	12 12	0.10 0.05	1.20 1.1
VAT-15	HAT-15	15 15	0.30 0.05	1.40 1.1
VAT-20	HAT-20	20 20	0.75 0.18	1.20 1.1
VAT-30	HAT-30	30 30	0.30 0.38	1.15 1.1

ALL MODELS IN STOCK

Power: 0.5W at 70°C ambient.

* Attenuation varies by ± 0.3 dB max. (VAT), ± 0.2 dB max. (HAT) over temperature.

•VAT MODELS \$11.95 ea. (qty.1-9) •HAT MODELS \$9.95 ea. (qty.1-9)

DESIGNER'S KITS AVAILABLE

K1-VAT: 1 of Ea. VAT-3, -6, -10, -20, -30 (5 total) \$49.95 K2-VAT: 1 of Ea. VAT-1, -2, -3, -4, -5, -6, -7, -8, -9, -10 (10 total) \$99.95 K3-VAT: 2 of Ea. VAT-3, -6, -10 (6 total) \$59.95 K1-HAT: 1 of Ea. HAT-3, -6, -10, -20, -30 (5 total) \$48.95 K2-HAT: 1 of Ea. HAT-1, -2, -3, -4, -5, -6, -7, -8, -9, -10 (10 total) \$97.95 K3-HAT: 2 of Ea. HAT-3, -6, -10 (6 total) \$58.95



P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 For quick access to product information see MINI-CIRCUITS CATALOG & WEB SITE

The Design Engineers Search Engine Provides ACTUAL Data Instantly From MINI-CIRCUITS At: www.minicircuits.com

LNA / Gain Block Converter **Power Amp** Sub-Modules **LMDS & MMDS** RFHIC MMIC Converte Sub-Modules CATV Line Amp Tel: 82-31-420-5511 Fax: 82-31-420-5588 www.rfhic.com rfsales@rfhic.com

people



Rohde & Schwarz Appoint Vohrer As President & COO

Rohde & Schwarz GmbH & Co. KG has named MICHAEL VOHRER to the position of president and COO. Prior to taking on his current role, Vohrer served as executive vice president and head of the Test and Measurement Division.

RF Logic, LLC—ARTHUR E. BUTTS to director for new business development; formerly employed in global sales, marketing, and operations positions.

Park Electrochemical Corp.—MURRAY O. STAMER to CFO and senior vice president; formerly senior vice president for finance. Also, STEVEN P. SCHAEFER to senior vice president for technology; formerly vice president of business development.

Recognition Source—TRAY RAYMOND to the position of regional sales manager for the Southwestern sales region; formerly director of new business development for Senercomm.

ADC—ROBERT E. "BOB" SWITZ to president and CEO; formerly president and general manager of ADC's Broadband Access and Transport group. Also, JOHN A. "GUS" BLANCHARD to non-executive chairman of the board; remains as an ADC board member.

Arrowhead Global Solutions—MAJOR GENERAL HOWARD J. "MITCH" MITCHELL, USAF (RET.) to the position of vice president for Western operations; previously served 30 years in the US Air Force, retiring in July 2003.

Raltron Electronics Corp.—STANLEY VOGT to general manager for Raltron's US manufacturing operations in Miami, FL; formerly plant manager for Flextronics in Memphis, TN. Also, CHUCK HUSTED to engineering director; formerly employed in engineering management at NDK. In addition, SCOTT STEMPER to vice president of worldwide quality assurance; formerly director of quality.

Dynaloy, Inc.—NICK LEONARDI to director of sales and marketing for the Semiconductor Materials Division; formerly

worldwide sales manager for Tiros Corp. Maury Microwave Corp.—RUSTY MYERS to the engineering team to lead the development of Maury's microwave component line; formerly developed microwave components at Agilent Technologies.

Proxim Corp.—DAVID L. THOMPSON to CFO; formerly CFO at Entrust, Inc.

Zyray Wireless—THOM F. DEGNAN to senior vice president of sales; formerly president and COO of Verticalband Ltd.

Andrew Corp.—KAREN A. QUINN-QUINTIN to vice president and chief human resources officer; formerly vice president of human resources for Textron International Products. Also, CHARLES R. NICHOLAS to chairman of the board; formerly vice chairman and CFO.





ITT Industries, Cannon—ALLAN W. HENDRY to director of sales for the Americas; formerly worked in sales management in the connector industry. Universal Microwave Corp. (UMC)—STEVEN C. REVERT to vice president of sales and marketing located in the Tempe, AZ Worldwide Sales and Customer Support Center; formerly vice president of the RF Power Product Business Unit for the Avnet RF and Microwave Division.

RF Active Mixer ICs High Linearity, DC-3GHz





IIP3 Up to +21dBm at 950MHz; +17dBm at 1900MHz

Our new LT®5511 and LT5512 are precision up and down-converting active mixer ICs, respectively, which feature "Best In Class" linearity and excellent port-to-port isolation. Reduced external component count and simplified input/output matching make these ICs easy to use. LO drive requirements are greatly eased by an integrated LO driver with single-ended or differential input. Low distortion operation makes these mixers ideal for use in wireless and cable infrastructure as well as RF instrumentation and radio links.

Features

	Upconverter LT5511	Downconverter LT5512
Conversion Gain	0dB	1dB
IIP3 950MHz 1900MHz	+17dBm +15.5dBm	+21dBm +17dBm
IIP2	+52dBm	NA
SSB Noise Figure	15dB	13.3dB
LO-Input Leakage	NA	-53dBm
LO-Output Leakage	-46dBm	-46dBm
LO Drive Level	-15 to -5dBm	-15 to -5dBm
Supply Current	56mA	57mA
Supply Voltage	4V to 5.25V	4.5V to 5.25V
Package	16-Lead SSOP	4mm x 4mm QFN

Data Sheet

www.linear.com/go/5511

Online Store

www.linear.com/lineardirect

More Information

Call: 1-800-4-LINEAR Visit: www.linear.com

Info: 408-432-1900

Fax: 408-434-0507



D, LTC and LT are registered trademarks and SwitcherCAD is a trademark of Linear Technology Corporation, 1630 McCarthy Blvd., Milpitas, CA 95035



Become a Linear Insider www.linear.com/insider

MID-ATLANTIC RF SYSTEMS... SPECIALIZES IN SMALL QUANTITY ORDERS. DESIGN & MANUFACTURING CUSTOM & STANDARD APPLICATIONS QUALITY SERVICE

Mid-Atlantic RF Systems offers creative solutions for your most demanding requirements for RF microwave components and systems.

Mid-Atlantic Products

Amplifiers
Switches
Power Dividers
Hybrid Couplers
Directional Couplers



PO Box 745, Forest Hill, MD 21050

Tel.: 410/893-2430 Fax: 410/638-5193

email: info@midatlanticrf.com www.midatlanticrf.com

education

►SHORT COURSES

UCLA Extension Short Courses

All courses at UCLA Extension Building, Los Angeles, CA

October 27-31 Designing and Manufacturing Better Products Faster Using The Theory of Inventive Problem Solving (TRIZ)

November 3-6 Project Management Principles and Practice

November 7 Project Risk and Opportunity Management

November 12-14 Wireless Sensor Networks and Their Tactical Applications

November 17-21 Communication Systems
Using Digital Signal Processing

December 1-2 Automatic Test Equipment (ATE) Selection, Design, and Programming December 3-5 Design for Testability and Embedded Self Test

For further information, contact:

Dr. William R. Goodin

UCLA Extension, Short Course Program 10995 Le Conte Ave., Suite 542

Los Angeles, CA 90024-2883

(310) 825-5010, FAX: (310) 206-2815 e-mail: bgoodin@unex.ucla.edu

Internet: www.uclaextension.edu/ shortcourses

Technology Strategy for R&D and Product Development

October 27-28 (Pasadena, CA)
March 25-26, 2004 (Pasadena, CA)
Course Location: California Institute of Technology Industrial Relations Center
For further information, contact:
California Institute of Technology
Industrial Relations Center, I-90
Pasadena, CA 91125-9000
(626) 395-4043, FAX: (626) 795-7174

(626) 395-4043, FAX: (626) 795-7174 e-mail: execedu@caltech.edu Internet: www.irc.caltech.edu

Active Phased Array Antenna Design, Development and Manufacturing

October 28-30 (Baltimore, MD) Hyatt Regency Baltimore For further information, contact: Phased Array Technology 10276 Wetherburn Rd. Ellicot City, MD 21042-1663

(410) 480-9570, FAX: (410) 480-9570 e-mail: patcorp@comcast.net

AVS Short Courses

November 3-7 (Baltimore, MD) Baltimore Convention Center Short Courses are being offered in the following areas:

Applied Vacuum Technology

Surface Analysis and Materials Characterization Materials, Thin Films, & Coatings: Processing and Properties

For further information, contact:

AVS

120 Wall St., 32nd Floor New York, NY 10005-3993 Internet: www.avs.org

ATI Short Courses

November 17-20 (Dayton, OH)
Microwave & RF Circuit & Component Modeling
November 17-18 (Dulles, VA)
Fundamentals of Synthetic Aperture Radar (SAR)
November 19-20 (Dulles, VA)
Advanced Synthetic Aperture Radar (SAR)
November 18-20 (Arlington, VA)
Hyperspectral & Multispectral Imaging
For further information, contact:
Applied Technology Institute (ATI)
12960 Linden Church Rd.
Clarksville, MD 21029
(888) 501-2100, FAX: (410) 531-1013
e-mail: ati@aticourses.com
Internet: www.aticourses.com/schedule.htm

►MEETINGS

ARMMS RF & Microwave Society

November 3-4 (Rockingham, Corby, Northamptonshire, England) Hotel Elizabeth For further information, contact: J.J. Heath-Caldwell 01962 761 565 e-mail: ji@jihc.co.uk

Internet: www.armms.org
25th Annual IEEE GaAs IC Symposium

November 9-12 (San Diego, CA) For further information, contact:

445 Hoes Lane
Piscataway, NJ 08855-1331
Internet: www.gaasic.org

The 36th Annual International Symposium on Microelectronics and Electronic Packaging

November 16-20 (Boston, MA) Hynes Convention Center (202) 548-4001 e-mail: imaps@imaps.org Internet: www.imaps2003.org

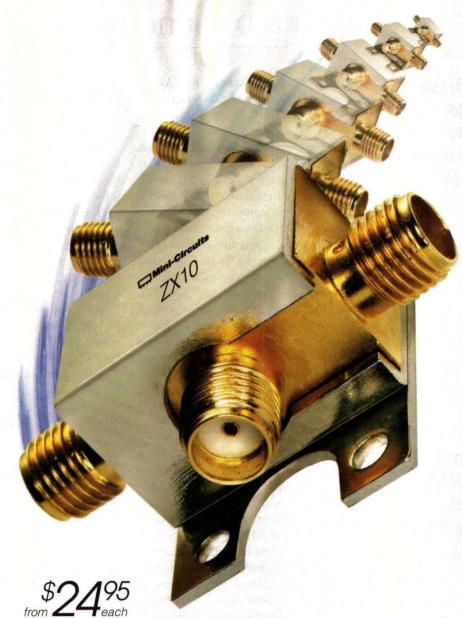
►CALL FOR PAPERS

2004 International Conference on Compound Semiconductor Manufacturing Technology

May 3-6, 2004 (Miami Beach, FL)
Sheraton Bal Harbour Beach Resort
Abstracts due: October 31
Authors must submit 1-to-2-page abstract by
e-mail in PDF or Word format to:
Abstracts@gaasmantech.org
Internet: www.gaasmantech.org

IEEE MTT-S International Microwave Symposium

June 6-11, 2004 (Fort Worth, TX)
Fort Worth Convention Center
Technical paper summaries due: December 8
All submissions must be electronic. Hard
copies are not accepted. The .pdf format is
preferred.
Submissions must be made at:
www.ims2004.org



POWER SPLITTERS

2Way-0° 2MHz to 12.6GHz

A new breed of SMA power splitters are small in size, small in price, and big on features. They're ZX10 power splitters from Mini-Circuits! These splitters have extremely wide bandwidths so you can cover all of your applications with only a few units. Each easily mountable model is less than $^{3}4^{+}$ in size, so you conserve real estate in laboratory, production, and system environments. And thanks to exclusive patent pending unibody construction, ZX10 splitters are rugged and phenomenally low in price. All models are *IN STOCK!* So contact Mini-Circuits now for individual units, or buy the 2MHz to 12.6GHz Designer's Kit for the lab, and never get caught short. Have the signal splitting power you need, on hand when you need it, with ZX10!

Mini-Circuits...we're redefining what VALUE is all about!

Typical Spec Model	ifications Frequency (GHz)	Isolation (dB)	Insertion Loss (dB) Above 3.0dB	Price \$ea. (Qty. 1-24)
ZX10-2-12	.002-1.2	21	0.5	24.95
ZX10-2-20	.2-2	20	0.8	24.95
ZX10-2-25	1-2.5	20	1.2	26.95
ZX10-2-42	1.9-4.2	23	0.2	34.95
ZX10-2-71	2.95-7.1	23	0.25	34.95
ZX10-2-98	4.75-9.8	23	0.3	39.95
ZX10-2-126	7.4-12.6	23	0.3	39.95

Dimensions: 0.74"x0.50"x0.54"



K1-ZX10 Designer's Kit 1 of Each Model (7 total) \$199.95 FREE Deluxe Wood Storage Case!

Detailed Performance Data & Specs Online at: www.minicircuits.com/zx10-series.pdf



P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 For quick access to product information see MINI-CIRCUITS CATALOG & WEB SITE

The Design Engineers Search Engine Provides ACTUAL Data Instantly From MINI-CIRCUITS At: www.minicircuits.com

R&D roundup

Active Biasing Improves Amplifier Power-Added Efficiency

HIGH-FREQUENCY POWER AMPLIFIERS (PAs) are often formed by a chain of GaAs metal-epitaxial semiconductor field-effect transistors (MESFETs) or high-electron-mobility-transistor (HEMT) devices. Under large-signal conditions, the reverse gate output current (combined with internal device resistances) causes a drop in a PA's power-added efficiency (PAE). Fortunately, German Torregrosa-Penalva and fellow researchers at the Departamento de Fisica y Arquitectura de Computadones of the Universidad Miguel Hernandez (Elche, Spain) have developed an active bias network that cannot only improve the PAE performance of GaAs MES-FET and HEMT PAs, but also compensate for small-signal gain drift as a function of temperature. The active-biasing approach was applied to GaAs monolithic-microwave-integratedcircuit (MMIC) amplifiers operating at millimeter-wave frequencies. When the active bias network is used, the network automatically

sets a new external gate voltage when gate currents appear under large-signal conditions. As a result, the internal gate voltage and the drain current remain constant. The DC bias point does not change, even under large-signal conditions, and higher PAE performance is possible. In addition, when the active bias network is used, the drain current is held constant under varying temperatures. In a comparison (actual measurements) of the active bias network with resistive divider bias networks, using two millimeter-wave MMIC amplifiers as part of the experiment, the active network delivered about two times the PAE value attained by the passive network, without degradation of the amplifier's linearity performance. See "PAE Improvement and Compensation of Small-Signal Gain Drift Due to Temperature on Power Amplifiers Through Active Biasing," Microwave and Optical Technology Letters, September 5, 2003, Vol. 38, No. 5, p. 389.

Low-Phase Noise CMOS VCO Uses Superharmonic Coupling

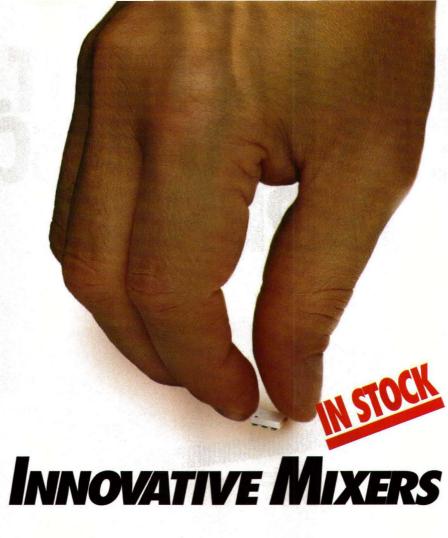
NOVEL DESIGN CONCEPTS often result in dramatic improvements in RF performance. Such is the case with an inductive-capacitive (LC) CMOS voltage-controlled oscillator which uses a new concept for quadrature coupling to achieve low phase noise at 5 GHz. The CMOS VCO employs coupling of the second-harmonic signals for stabilization, which provides broadband operation without addition of phase noise or increase in power consumption. The design approach yields phase noise of better than -124 dBc/Hz offset 1 MHz from the carrier over the entire tuning range. The worst-case image rejection is 33 dB. The CMOS circuit draws just 8.75 mA from a +2.5-VDC supply. Designed nominally for IEEE 802.11a 5-GHz wirelesslocal-area-network (WLAN) systems, the concept of superharmonic quadrature coupling

allows two differential oscillators to oscillate in quadrature by allowing a coupling network to enforce an antiphase relationship between the second-order harmonics. In developing a functional source, Sander L.J. Gierkink and coworkers from the Communications Circuit Research Department of Agere Systems (Allentown, PA) created a quadrature oscillator consisting of two separate differential oscillators whose common-mode second harmonics are coupled by means of a pair of inductors. The design was realized in a quarter-micron CMOS process, and delivered worst-case phase noise of -71 dBc/Hz offset 10 kHz from the carrier. See "A Low-Phase-Noise 5-GHz CMOS Quadrature VCO Using Superharmonic Coupling," The IEEE Journal of Solid-State Circuits, July 2003, Vol. 38, No. 7, p. 1148.

Compact Coplanar Amplifier Yields 4 W Power At X-Band

SOLID-STATE POWER AMPLIFIERS continue to gain ground on the domain once held exclusively by vacuum-electronics devices. Alexandre Bessemoulin from United Monolithic Semiconductors (Orsay, France) and associates from the Fraunhofer Institute for Applied Solid-State Physics (Freiburg, Germany) have developed a compact coplanar GaAs MMIC amplifier capable of 4-W output power at 1-dB compression at 10 GHz, with 18 dB gain and generous (25 percent) power-added efficiency. Based on pseudomorphic HEMT

(PHEMT) device technology, the two-stage, 4×4 -mm amplifier was fabricated on a 4-in. wafer and tested on wafer under rigorous conditions from 9.0 to 11.5 GHz. In addition, the amplifier achieved better than 40 dB reverse isolation, with PAE as high as 50 percent under saturated output-power conditions. See "A 4-W X-Band Compact Coplanar High-Power Amplifier MMIC With 18-dB Gain and 25% PAE," *The IEEE Journal of Solid-State Circuits*, September 2003, Vol. 38, No. 9, p. 1433.



smaller size .better performance .lower cost 50kHz to 4200MHz

Searching high and low for a better frequency mixer? Then take a closer look at the innovative Innovative Technology built into Mini-Circuits technology ADE mixers. Smaller size is achieved using an

ultra-slim, patented package with a profile as low as 0.082 inches (2mm) in height. Electrically, ADE mixers deliver better performance than previous generation mixers through all welded connections with unique assembly construction which reduces parasitic inductance. The result is dramatically improved high frequency and IP2-IP3 performance. Plus, ADE's innovative package design allows water

wash to drain and eliminates the possibility of residue entrapment. Another ADE high point is the lower cost...priced from only \$1.99 each. So, if you've been searching high and low for a mixer to exceed expectations...ADE is it



ACTUAL SIZE

ADE Mixers...Innovations Without Traditional Limitations!

MODEL LO	O Power (dBm)	Freq. (MHz)	Conv. Loss Midband (dB)	L-R Isol. Midband (dB)	IP3 @ Midband (dBm)	Height (mm)	Price (\$ea.) Qty. 10-49
ADE-1L ADE-3L ADEX-10L ADE-1 ADE-1ASK ADE-2 ADE-2ASK ADE-6 ADEX-10	+3 +3 +4 +7 +7 +7 +7 +7 +7	2-500 0.2-400 10-1000 0.5-500 2-600 5-1000 1-1000 0.05-250 10-1000	5.2 5.3 7.2 5.0 5.3 6.67 5.4 4.6 6.8	55 47 60 55 50 47 45 40 60	16 10 16 15 16 20 12 10 16	3 4 3 4 3 3 5 5 3	3.95 4.25 2.95 1.99 3.95 1.99 4.25 4.95 2.95
ADE-12 ADE-4 ADE-14 ADE-901 ADE-5 ADE-5X ADE-13 ADE-11X	+7 +7 +7 +7 +7 +7 +7 +7	50-1000 200-1000 800-1000 800-1000 5-1500 5-1500 50-1600 10-2000	7.0 6.8 7.4 5.9 6.6 6.2 8.1 7.1	35 53 32 32 40 33 40 36	17 15 17 13 15 8 11	23233323	2.95 4.25 3.25 2.95 3.45 2.95 3.10 1.99
ADE-20 ADE-18 ADE-3GL ADE-3G ADE-28 ADE-30 ADE-32 ADE-35	+7 +7 +7 +7 +7	1500-2000 1700-2500 2100-2600 2300-2700 1500-2800 200-3000 2500-3200 1600-3500	5.4 4.9 6.0 5.6 5.1 4.5 5.4 6.3	31 27 34 36 30 35 29 25	14 10 17 13 8 14 15	3 3 2 3 3 3 3 3 3	4.95 3.45 4.95 3.45 5.95 6.95 6.95 4.95
ADE-18W ADE-30W ADE-1LH ADE-1LHW ADE-1MH ADE-10MH ADE-10MH ADE-12MH ADE-25MH	+7 +7 +10 +10 +13 +13 +13 +13 +13	1750-3500 300-4000 0.5-500 2-750 2-500 0.5-600 800-1000 10-1200 5-2500	5.4 6.8 5.0 5.3 5.2 5.2 7.0 6.3 6.9	33 35 55 52 50 53 34 45 34	11 12 15 15 17 17 26 22 18	3 3 4 3 3 4 4 3 3	3.95 8.95 2.99 4.95 5.95 6.45 6.95 6.45 6.95
ADE-35MH ADE-42MH ADE-1H ADE-1HW ADEX-10H ADE-10H ADE-12H ADE-17H ADE-20H		5-3500 5-4200 0.5-500 5-750 10-1000 400-1000 500-1200 100-1700 1500-2000	6.9 7.5 5.3 6.0 7.0 7.0 6.7 7.2 5.2	33 29 52 48 55 39 34 36 29	18 17 23 26 22 30 28 25 24 1 is 0.320"x	3 3 4 3 3 3 3 3 3 3 3	9.95 14.95 4.95 6.45 3.45 7.95 8.95 8.95 8.95

P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 For quick access to product information see MINI-CIRCUITS CATALOG & WEB SITE The Design Engineers Search Engine Provides ACTUAL Data Instantly From MINI-CIRCUITS At: www.minicircuits.com

OK, WE ADMIT IT... WE'RE INTO MUSCLE AMPLIFIERS



Our custom High-Power Amplifiers outperform the competition's right from the bench.

e've taken the lead again! Daico Industries is lifting amplifier stats higher in a new high-effiency, high-gain amplifier that's hard to beat.

Our amplifiers provide a new standard in power, efficiency and reliability in the L-Band range. And this 2kW design with an output of +63.3 dBm provides extra advantages and features others can't, all in one package. Like uniform thermal performance for large and short pulse, thermal sharing between transistors, controls for monitoring power output, reverse power and temperature, and excellent flatness across bandwith. Plus, they're fully protected for VSWR mismatch all phases. What's more, our unique modular design supports manufacturability, repeatability and serviceability developed and refined over more than 35 years in the IF/RF/microwave field.

That's why we can offer, "More power to your radar systems designers!" by simply calling: 310 507 5670.

ELECTRICAL SPECIFICATIONS

PARAMETER	MIN	TYP	Max	UNIT	Notes
Frequency	1.2		1.4	GHZ	
Small Signal Gain	53	55	58	dB	
VSWR In/Out			1:2/1		In 50 ohm
RF Out, P1DB Comp.		+63	63.3	dBm	
Harmonics Out II, III	50	55		dBc	
Gain Tracking	-0.3	0.2	+0.3	dB	Unit-to-unit
Phase Tracking between amplifiers	-1.0	±-0.5	+1.0	degree	Unit-to-unit
VSWR Withstand Under Full Power			∞:1		All phases
Efficiency		-30			
Duty			10	%	
Pulse Width	0.001		1.0	Msec	
Pulse Droop	0.0	0.02	0.1	db	



DAICO Industries, Inc. 1070 East 233rd Street Carson, California 90745 Phone: 310 507 3242 Fax: 310 507 5701 www.daico.com

DESIGN

Smart Synthesizers Simplify RF Integration

These compact narrowband and broadband frequency synthesizers can be reconfigured in frequency and step size using simple programming and standard interfaces.

ystem designers stress the need for higher levels of integration in RF function blocks. Such modules provide simple digital and RF interfaces and, thus, speed the time to market and simplify system-level integration and production. Unfortunately, the RF/microwave signal sources currently available do not provide a satisfactory solution that addresses these needs. Fortunately, a line of Plug-N-Play

> frequency synthesizers offers a practical solution, providing a high-performance synthesized source that features quick deployment.

> Currently, there are two synthesized source approaches that include (1) the integrated circuit (IC) that incorporates a phase-locked loop (PLL) and an onboard voltage-controlled oscillator (VCO) and (2) the VCO module with PLL circuitry added internally. In the first approach, the integrated VCO comes with a compromise in performance, compared to discrete, lumpedelement VCO designs. In addition, most of these single-chip synthesizers require additional external circuitry, such as an external tank or loop filter. Such sources can also require significant effort in writing control software.

When discrete VCOs are integrated with the best of PLL chips and supplied in module form, the system

designer is still faced with a number of problems. First, each new application calls for a custom design. Each new requirement has an impact on the frequency range, step size, reference frequency, and loop bandwidth. Once these have been established, the signalsource designer must create a unique product to fit these criteria where even the subtlest change can affect circuit values or even design topology. Additionally, the system designer is still left with the task of understanding the inner workings of the entire module prior to integration, so that control software can be developed. The risk of designing with this solution is much higher since changes during the design phase (frequency plan, step size, etc.) can be costly and time-consuming. Also, the lack of stan-

FUNCTION SELECT (4 BITS)			MULTIPLIER (4 BITS)			FREQUENCY/CHANNEL (24 BITS)							
DB31	DB30	DB29	DB28	DB27	DB26	DB25	DB24	DB23	DB22	DBn	DB2	DB1	DB0
FS3	FS2	FS1	FS0	M3	M2	M1	MO	FC23	FC22	FCn	FC2	FC1	FC0

1. PNP frequency synthesizers typically require only 32-b command words to execute changes in frequency and step size, with 40-b data used to chance settings on an I²C bus.

DAVID LYLE President/CTO

Universal Microwave Corp., 2339 Destiny Way, Odessa, FL 33556; (877) 375-9332, FAX: (727) 376-7271, Internet: www.vco1.com.



5114 E. Clinton Way. #101 Fresno, CA 93727 Tel: 559-255-7044 Fax: 559-255-1667 Email: sales@ditom.com

"The Leader in Broadband and High Frequency



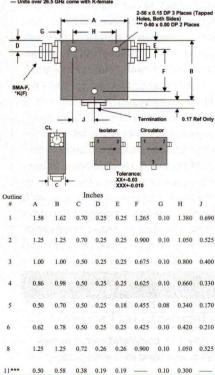
Iso	lators					
Model	Freq	Isol	Insertion	VSWR	Outli	ne Price
# F	Range GHz	Min	Loss Max	Max	#	Per Unit
D3I0890	.89	20	.40	1.25	8	\$235.00
D3I0116	1.4-1.6	20	.40	1.25	8	\$235.00
D3I0118	1.6-1.8	20	.40	1.25	3	\$210.00
D3I0120	1.7-2.0	20	.40	1.25	3	\$210.00
D3I0223	2.0-2.3	20	.40	1.25	3	\$210.00
D3I2040	2.0-4.0	18	.50	1.30	- 1	\$215.00
D3I2060	2.0-6.0	14	.80	1.50	1	\$250.00
D3I2080	2.0-8.0	10	1.50	2.00	1	\$395.00
D3I3060	3.0-6.0	19	.40	1.30	2	\$195.00
D314080	4.0-8.0	20	.40	1.25	3	\$185.00
D316012	6.0-12.4	17	.60	1.35	6	\$195.00
DMI6018	6.0-18.0	14	1.00	1.50	11	\$275.00
D3I7011	7.0-11.0	20	.40	1.25	4	\$185.00
D317012	7.0-12.0	20	.40	1.25	4	\$205.00
D3I7018	7.0-18.0	15	1.00	1.50	5	\$225.00
D3I8012	8.0-12.4	20	.40	1.25	4	\$180.00
D3I8016	8.0-16.0	17	.60	1.35	5	\$205.00
D318020	8.0-20.0	15	1.00	1.45	5	\$230.00
D3I1020	10.0-20.0	16	.70	1.40	5	\$220.00
D3I1218	12.0-18.0	20	.50	1.25	5	\$180.00
D3I1826	18.0-26.5	18	.80	1.40	5	\$225.00
D3I1840	18.0-40.0	10	2.00	2.00	5*	\$1300.00
D3I2004	20.0-40.0	12	1.50	1.65	5*	\$950.00
D3I2640	26.5-40.0	14	1.00	1.50	5*	\$700.00

Circulators

Model	Freq	SO	Insertion	VSWR	Outlin	e Price
# 1	Range GHz	Min	Loss Max	Max	#	Per Unit
D3C0890	.89	20	.40	1.25	8	\$235.00
D3C0116	1.4-1.6	20	.40	1.25	8	\$235.00
D3C0118	1.6-1.8	20	.40	1.25	3	\$210.00
D3C0120	1.7-2.0	20	.40	1.25	3	\$210.00
D3C0223	2.0-2.3	20	.40	1.25	3	\$210.00
D3C2040	2.0-4.0	18	.50	1.30	1	\$215.00
D3C2060	2.0-6.0	14	.80	1.50	1	\$250.00
D3C2080	2.0-8.0	10	1.50	2.00	1	\$395.00
D3C3060	3.0-6.0	19	.40	1.30	2	\$195.00
D3C4080	4.0-8.0	20	.40	1.25	3	\$185.00
D3C6012	6.0-12.4	17	.60	1.35	6	\$195.00
DMC6018	6.0-18.0	14	1.00	1.50	11	\$275.00
D3C7011	7.0-11.0	20	.40	1.25	4	\$185.00
D3C7018	7.0-18.0	15	1.00	1.50	5	\$225.00
D3C8016	8.0-16.0	17	.60	1.35	5	\$205.00
03C8020	8.0-20.0	15	1.00	1.45	5	\$230.00
D3C1218	12.0-18.0	20	.50	1.25	5	\$180.00
D3C1826	18.0-26.5	18	.80	1.40	5	\$225.00
D3C1840	18.0-40.0	10	2.00	2.00	5*	\$1750.00
D3C2004	20.0-40.0	12	1.50	1.65	5*	\$1350.00
D3C2640	26.5-40.0	14	1.00	1.50	5*	\$900.00

45 products can be bought online with Credit Card. Delivery within 24Hrs ARO.

Delivery within 24Hrs ARO.
 DiTom stocks over 25 units of each device at all times.





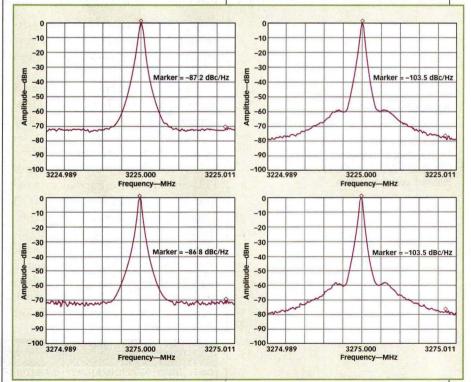
I	Table 1: Reviewing factory presets									
ATTRIBUTE	FUNCTION SELECT	MULTIPLIER	FREQUENCY/ CHANNEL	RESULT						
START frequency	01	8	32	3200 MHz						
STOP frequency	02	8	33	3300 MHz						
STEP size	03	6	1	1 MHz						
REF frequency	04	7	Z Tartess	10 MHz						
CHANNEL number	00	0	0	3200.00 MHz						
CHANNEL number	00	0	1	3201.00 MHz						
CHANNEL number	0	0	2	3202.00 MHz						
CHANNEL number	0	0	3	3203.00 MHz						
CHANNEL number	0	0	100	3300.00 MHz						

dardization in package size and interfaces leaves system designers with precious new options.

Because of the problems posed by these two synthesizer "solutions," the engineers at Universal Microwave Corp. (Odessa, FL) have developed the Plug-N-Play family (PNP series) of frequency synthesizers. These are truly configurable modules, which take mere minutes, rather than weeks, to deploy. They are designed to simplify integration for both RF designers and system software developers. The frequency synthesizers are supplied in compact surface-mount packages for ease of

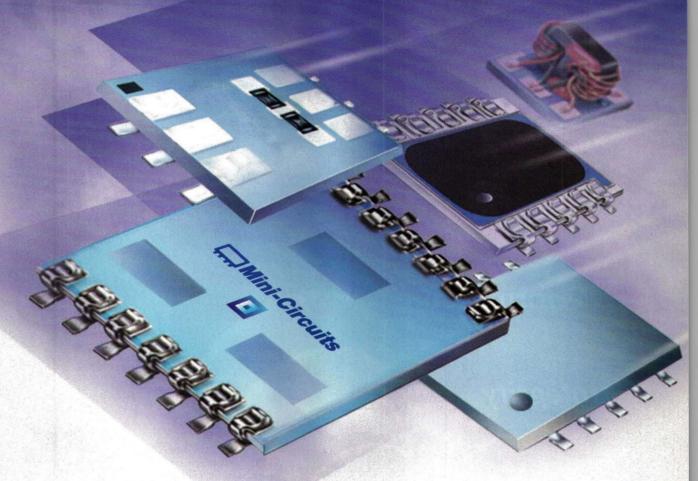
integration in even the smallest system designs.

These compact sources offer a host of improvements compared to traditional VCO/PLL combinations. Both I²C bus and SPI bus designers will find the PNP series straightforward with a digital interface shared by the most popular modern protocols. Code writers will find the simplicity of developing software for functional control. Any number of PNP devices can reside on the same bus, and while these modules are always on-line waiting to receive data, their internal architecture provides inherent isolation between the



2. The phase noise of the PNP-3250-L22 frequency synthesizer remains low when measured close to the carrier (top left) and far from the carrier (top right) with large step sizes or close to the carrier (bottom left) or further from the carrier (bottom right) with smaller step sizes.

POVER SPLITTERS



1 to 2700MHz from 99 (see On 100)

The search for your 2way or 4way Low Temperature Co-fired Ceramic power splitter stops here, because Mini-Circuits offers the widest selection of families in the history of LTCC technology! Pick from dozens of highly reliable, extra rugged, temperature stable splitters with unprecedented low prices, immediately available off-the-shelf for your 50&75 ohm, 0°, 90°, and 180° military and commercial applications. Choose from broad band and narrow band families with low insertion loss, high isolation, excellent amplitude and phase unbalance, and high performance repeatability in sizes as tiny as 0.12"x0.06" and profiles down to 0.035"...ideal for your cellular, PCS, GSM, GPS, ISM, WLAN, UHF/VHF designs and more. And finding your splitter at minicircuits.com is a snap. Simply type-in a

family model prefix, then select the unit that has the performance, package, and price that's right for you, or contact us for your custom needs.

Mini-Circuits...we're redefining what VALUE is all about!

Power Splitter Families:

1	JANOI O	DILLOI I	arrillos.						
	N ay Deg	Family Model Prefix	No. of Models in Family	Freq. Range of Family (MHz)	Isol. Range Typ. (dB)	Alns. Loss Range Typ. (dB)	Phase Unbal. Range Deg. (Max.)	Price \$ea. (Qty. 10)	
2	2 0	SCN	5	800-2700	20-23	0.5	3-6	.99*	
2	2 0	SBTC	7	5-2500	20-28	0.3-1.4	3-14	1.99*	
2	2 0	SBA	4	1200-2600	16-22	0.4-0.8	5-10	8.95	
2	2 0	SBB	5	800-2300	22-24	0.6	3-4	4.95	
2	2 0	SCL	1	800-1000	30	0.5	4	4.95	
2	90	QBA	7	340-2400	21-28	0.25-0.80	3-7	6.95	
2	90	QCC	2	1200-2500	23-25	0.5-0.7	3-4	4.95	
2	90	QCN	5	425-2700	17-30	0.4-0.6	4-13	3.95	
2	180	SBTCJ	1	1-750	22	0.6	7	5.95	
4	0	SBD	1	1800-2600	20	1.0	8	9.95	
4	1 0	SCA	4	5-2000	15-20	0.9-1.5	4-11	6.95	
* 0	no O	iontity 1	00						

*\$ea. Quantity 100.
Alnsertion loss above theoretical.

BLUE CELL

Protected by U.S. patents 5534830, 5640132. Add'l Pat. Pend.













New Blue Cell™ LTCC 164 Page Handbook...FREE!



P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 For quick access to product information see MINI-CIRCUITS CATALOG & WEB SITE The Design Engineers Search Engine Provides ACTUAL Data Instantly From MINI-CIRCUITS At: www.minicircuits.com

ISO 9001 ISO 14001 CERTIFIED

343 Rev. C



digital bus and the RF output.

The PNP synthesizers are extremely flexible, giving the designer the ability to configure all of the synthesizer's vital functions "on the fly," using simple strings of code that comprise the Configuration Data.

These initialization blocks of code contain commands for start frequency (START), stop frequency (STOP), frequency step size (STEP), and reference frequency (REF). Once these four variables are set, a finite number of channels are created and entering a new frequency is accomplished by updating the CHANNEL register. By delivering these simple words over the bus, the PNP architecture recognizes its new role and resets the loop to accommodate its new setup. The PNP module optimizes its internal settings for best overall integrated phase noise, switching speed, and spurious suppression, all automatically and in less than 100 µs. For example, if the system requires 100-kHz steps in one mode and 1-MHz steps in another mode, a PNP synthesizer can make the adjustments instantly without compromises in accuracy, speed, or performance.

The PNP synthesizers offer ease of integration for both RF and software engineers. The signal sources can be deployed in virtually any system without the complexity of code writing typically associated with frequency-synthesizer modules. The PNP family of intelligent frequency synthesizers can be controlled through the use of a microprocessor interface or bus. The PNP synthesizers support several protocols, such as SPI bus, Microwire interfaces, and I²C bus implementations. For SPI and Microwire applications, PNP devices require a single 32-b string of serial data to set frequency or to change internal settings (Fig. 1). The I²C bus utilizes some unique control bits and requires the addition of an Address byte, increasing the serial bit stream for this protocol to 40 b per command.

Each PNP synthesizer is programmed at the factory with presets for all of the registers. If these factory values are acceptable, there is no reason to reload



We'll be here when you need us

With over 25 years of specializing in both custom and off the shelf shielding enclosures, fast, accurate & dependable deliveries where else would we be?







The Shielding Specialists

Call Us Toll Free (888)546-3313
Tel. (631) 585-3400 • Fax: (631) 585-3534
Visit our website: www.compac-rf.com

any of these registers. If an application requires values other than the factory presets, the PNP synthesizer must first be initialized by loading data into each of the affected FUNCTION registers. These might include START, STOP, STEP, or REFERENCE. It is not necessary to re-load any registers that are already set properly for the application. START defines the lowest desired frequency of operation. STOP defines the highest desired frequency of operation. STEP is used to channelize the band, and REFERENCE defines the frequency of the external reference. Once the PNP

synthesizer is initialized, a fixed number of channels are available. Loading the CHANNEL register sets the operating frequency of the PNP device. The formula for calculating the operating frequency is simply: START (in Hz) + $[CHANNEL \times STEP (in Hz)] = Fre$ quency (Hz).

Every PNP synthesizer is loaded with factory default settings so that when a module is powered up, it has a valid operating state. It then monitors the bus for instructions as to its new configuration. As an example, the model PNP-3250-L22 synthesizer has an available range

of 3200 to 3300 MHz. With its factory presets, the unit will tune over the full operating band of 3200 to 3300 MHz in 1 MHz when operating with a 10-MHz external reference oscillator (Table 1).

When the step size is changed, the spurious and phase-noise performance of the PNP-3250-L22 synthesizer does not suffer, indicating that the loop in the PNP source has been reoptimized for best overall performance. When adjusting for smaller steps, the microprocessor first sends new settings to the PNP synthesizer. The only register affected by this new setup is the STEP

Table 2: A sampling of synthesizers									
MODEL NUMBER	MINIMUM FREQUENCY (MHz)	MAXIMUM FREQUENCY (MHz)	MINIMUM FREQUENCY (MHz)	The second second second	LOOP BW (kHz) TYP	OUTPUT POWER (dBm) TYP.	PHASE NOISE, 1-kHz OFFSET (dBc/Hz)	PHASE NOISE, 10-kHz OFFSET (dBc/Hz)	
PNP-850-L22	800	900	25	10000	2.8	0	-95	-108	
PNP-3250-L22	3200	3300	25	10000	2.8	0	-85	-103	
PNP-3950-L22	3900	4000	25	10000	2.8	0	-80	-100	
PNP-1028-N22	. 55	2000	25	10000	2.8	0	-85	-100	
PNP-1500-P22	1000	2000	25	10000	2.8	0	-82	-100	



Now entering our fourth decade, JFW Industries is a proven leader in the design and production of innovative RF solutions. Whether your project calls for fixed attenuators and terminations, manually and electronically controlled attenuators, RF switches, power dividers or programmable RF test

systems and switch matrices; JFW's dedicated customer service and engineering personnel can provide application specific components and sub-systems at catalog prices with an off-the-shelf attitude. For more information, please contact us or visit our well site at www.jfwindustries.com

JFW Industries, Inc.

Specialists in Attenuation and RF Switching

TEL (317) 887-1340 • Toll Free 1 (877) 887-4539 • Fax (317) 881-6790

5134 Commerce Square Dr. • Indianapolis, Indiana 46237

Internet- http://www.jfwindustries.com E-mail-sales@jfwindustries.com ISO 9001 Certified

Alengingering Choices Should Be This Obvious

New Low Phase Noise/ Low Cost Synthesizers

The superior performance of

Narda's new family of microwave synthesizers makes them the obvious choice for the demanding requirements of wireless communication systems, satcom converters digital radio, and optical networks.

These synthesizers are awailable in the 6 to 28. GHz frequency range. Using Narda's proprietary phase-locked dielectric resonator oscillator tachnology and PLL circuitry, these units achieve tunable outputs with munimum performance degradation.

To learn more about our new family of microwave

synthesizers contact us at:

NARDA MICHOWAWEJEAST

435 Woreland Street, Hauppauge, NY 11788

USA Tel: 631.231.1700

Int'l Tel: 631.231.1390.

FW. POTOGODATUDO C

e-mail: nerdeast@L-3com.com

www.nardamicrowave.com





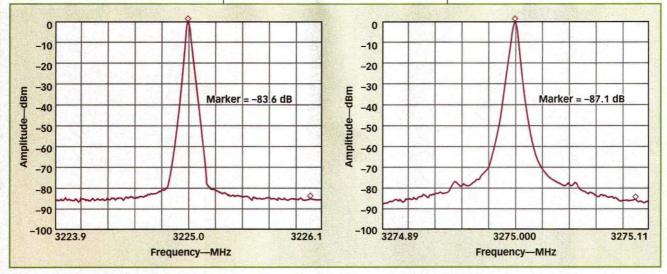
DESIGN

register. As a result, a user need only send a single string of data to accomplish a move from 1-MHz steps to 100-kHz steps. However, the number of available channels increases accordingly.

The PNP frequency synthesizers can

handle virtually any step size from 5 kHz to 10 MHz without degradation in phase noise. While spurious performance will obviously change with very small steps, the PNP series was designed with the goal of maintaining outstanding

phase-noise performance regardless of step size. In the previous example, the PNP-3250-L22 is set for 1-MHz steps (factory default settings) and then reprogrammed to take 100-kHz steps. In spite of the change, the phase-noise



3. The spurious performance of the PNP-3250-L22 frequency synthesizer remains consistent with different step sizes.

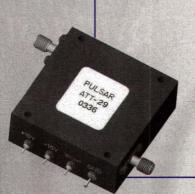
online catalog

www.pulsarmicrowave.com



products: mixers · power dividers · i&q networks 90° & 180° hybrids · directional couplers · rf transformers frequency doublers · attenuators/switches · bias tees

analog and digital attenuators



for a complete online catalog, visit:

0.25-18.0 GHz
Octave and Multi-Octave
64 dB Attenuation Range
0.125 dB Least Significant Bit
8 Bits
RF Input Power to 3 Watts
TTL or Voltage Control

ISO 9001 REGISTERED FIRM

www.pulsarmicrowave.com

SMA Female Connectors

Pulsar Microwave Corporation • 48 Industrial West • Clifton, NJ 07012 • Tel: 800-752-2790 • Fax: 973-779-2727 • sales@pulsarmicrowave.con

DESIGN

performance remains consistent no matter what step size is used (Fig. 2). Similarly, spurious contributions are also well controlled and consistent with changes in step size (Fig. 3).

Another example of the PNP line, the PNP-1500-P22, is designed for full-octave coverage from 1000 to 2000 MHz (Fig. 4). It achieves such wideband coverage without the use of high supply voltages typically associated with wideband frequency synthesizers. The PNP-1500-P22 is powered by supplies of +3 VDC (digital circuitry) and +12.5 VDC (analog circuitry). The compact source measures just $0.60 \times 0.60 \times 0.220$ in. $(1.5 \times 1.5 \times 0.56$ cm) and includes the VCO, buffer amplifier, PLL, loop filter, and PNP interface within the package.

The PNP synthesizers are currently available in over 40 bands covering the frequency range from 50 MHz to 5.5 GHz (**Table 2**). Narrowband designs employ +3-VDC supplies for the digital circuitry and +5-VDC supplies for the analog circuitry. Wideband models are powered by +3 VDC for the digital circuitry and +12.5 VDC for the analog circuitry.

In addition to the units shown in the table, model PNP-950-L22 operates from 900 to 1000 MHz, model PNP-1250-L22 operates from 1200 to 1300 MHz, model PNP-1350-L22 runs 1300 to 1400 MHz, and model PNP-1450-L22 runs from 1400 to 1500 MHz. All these frequency synthesizers provide programmable frequency step sizes from 25 to 10,000 kHz with typical output power of 0 dBm. The phase noise for the PNP-950-L22 is typically –110 dBc/Hz offset 10 kHz from the carrier. The phase noise for the PNP-1250-L22 and PNP-1350-L22 synthesizers is -108 dBc/Hz offset 10 kHz from the carrier, and the phase noise for the PNP-1450-L22 is -107 dBc/Hz offset 10 kHz from the carrier.

The PNP-525-N22 frequency synthesizer is an example of a unit with similar frequency coverage but at much lower carrier frequencies. The PNP-525-N22 is designed for use from 50 to 1000 MHz and also can be programmed to





HUBER+SUHNER - Excellence in Connectivity Solutions

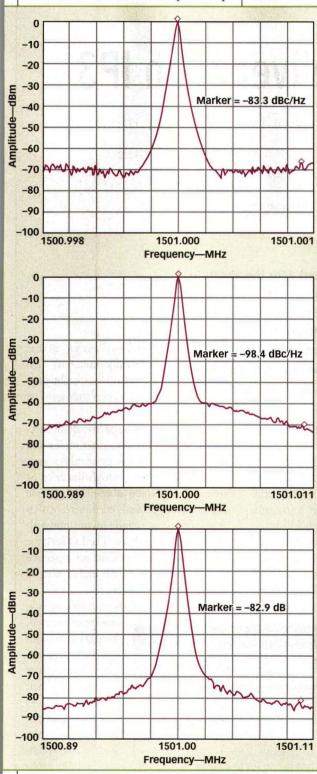
DESIGN

tune in frequency steps from 25 to 10,000 kHz. While the earlier-described synthesizers are built for +5-VDC power sup-

plies, the PNP-525-N22 operates on a +15-VDC supply (with typical current draw of 35 mA). The PNP-525-N22

achieves typical output power of 0 dBm across its full frequency range, with typical phase noise of -105 dBc/Hz offset 10 kHz from the carrier.

The compact synthesizer modules measure only $0.5 \times 0.5 \times 0.180$ in. $(1.27 \times 1.27 \times 0.46)$ cm). Any model can be preprogrammed at the factory for operation as a phase-locked oscillator (PLO) when a digital interface is not available or required. By loading a PNP source with a preset frequency of operation, a unit can be supplied for operation at any fixed frequency from 50 MHz to over 5 GHz, with only a power supply and external reference source needed for operation. The miniature synthesizers are well suited for a wide range of applications, including as precision sources in test instruments, as local oscillators (LOs) in digital microwave radios, or as compact building-block frequency sources for larger commercial or military frequency-synthesizer systems. For additional information on the programmable frequency synthesizers, please visit the company's website www.vco1.com (specifications and outline drawings are available for more than 30 different representative models, with custom units also available). MRF



4. The PNP-1500-P2 frequency synthesizer features good phase noise when measured close to the carrier (top) or further from the carrier (middle), as well as extremely low spurious noise (bottom).



VHF SC-Cut Quartz Crystals

75 MHz to 130 MHz

3rd or 5th OT HC-35 & HC-43

TURN POINT RANGE 75°C to 105°C

Aging = /<: ±3 X 10⁻⁹ / Day

PO Box 89
Scotch Valley Road
Hollidaysburg, PA 16648
814-695-4428 Phone
814-696-0403 Fax
www.aextal.com
e-mail: sales@aextal.com







Active Mixers Deliver High IP3

A pair of active double-balanced mixers provides the frequency range and linearity needed for a host of broadcast and wireless communications applications.

ctive mixers have long been associated with the ability to work at low local-oscillator (LO) levels, but falling short on linearity performance. Fortunately, a pair of active mixers has been developed based on a high-frequency bipolar process from Linear Technology. These plastic-packaged mixers are suitable for frequency upconversion and downconversion functions, respectively, with linearity comparable

to passive diode mixers.

Passive diode mixers are widely used in wireless and cable-television (CATV) infrastructure equipment for their high linearity. Their need for high LO signals requires the addition of LO amplifiers, which also add cost and compromise isolation. The high LO levels can lead to signal leakage, and the need for additional filtering. Passive diode mixers also suffer from high sensitivity to the LO-signal input amplitude, therefore requiring tight control of LO sig-

nal flatness. Passive mixers also typically have 6 to 7 dB of conversion loss, calling for additional amplifier gain to

As an alternative to passive diode mixers, the LT5511 upconverter mixer and the LT5512 downconverter mixer were developed to provide high linearity at lower LO levels (see table). They provide comparable input third-order-intercept (IP3) performance as a diode mixer, but with 20 dB lower LO drive. The LO leakage is about 20 dB better than for a passive mixer, with about 7 dB higher output IP3 than a diode mixer.

compensate for the loss.

The linearity of these active mixers

has been achieved, in part, through careful optimization of the mixer core designs. Their integrated LO amplifiers are optimized for stable, high-speed switching. Stability problems common to other designs often require the addition of ferrite

TOM SCHILTZ Senior RF IC Design Engineer BILL BECKWITH

Senior RF IC Design Engineer

Linear Technology Corp., Colorado Design Center, 950 Chapel Hills Dr., Colorado Springs, CO 80920-3984; (719) 593-1579, FAX: (719) 598-0977, Internet: www.linear.com.

The LT5511 and LT5512 mixers at a glance

RF = 950 MHz, LO = 1 GHz, IF = 70 MHz							
	LT5511 (UPCONVERTER)	LT5512 (DOWNCONVERTER)	PASSIVE MIXER				
Conversion gain (dB)	0 (IF to RF)	1 (RF to IF)	-7				
Input IP3 (dBm)	+17	+21	+17				
LO-RF leakage (dBm)	-46	-52	-25				
LO-IF isolation (dB)	-	36	26				
LO power (dBm)	-10	-10	+10				

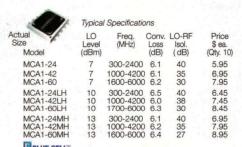
visit PlanetEE.com



LTCC MIXERS \$395 from 3 ea.(Qty. 1000)

For Commercial, Military, and Industrial Use, Mini-Circuits proudly introduces MCA1, the world's first commercially available line of low temperature cofired ceramic (LTCC) frequency mixers! Highly reliable, extremely broad band, and very low in cost, these patent pending double balanced mixers have excellent electrical performance and are available in level 7, 10, and 13 (LO) models for your 300MHz to 6GHz designs. As for ruggedness and reliability, MCA1 mixers have all circuitry hermetically embedded inside the ceramic making them impervious to most environmental conditions. The process also gives you superior stability under temperature, high repeatability, and compact 0.080" profile. They're ideal for the COTS program, as well as your commercial and industrial applications. So contact Mini-Circuits now. Our team is ready to handle your needs worldwide with quick shipments, custom designs, high volume production capability, and fast turn-around.

Mini-Circuits...we're redefining what VALUE is all about!

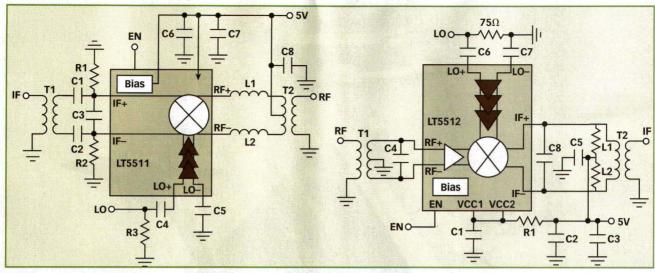


Detailed Performance Data & Specs Online at: www.minicircuits.com/mixer2.html



P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 For quick access to product information see MINI-CIRCUITS CATALOG & WEB SITE The Design Engineers Search Engine Provides ACTUAL Data Instantly From MINI-CIRCUITS At: www.minicircuits.com

ACTIVE MIXERS



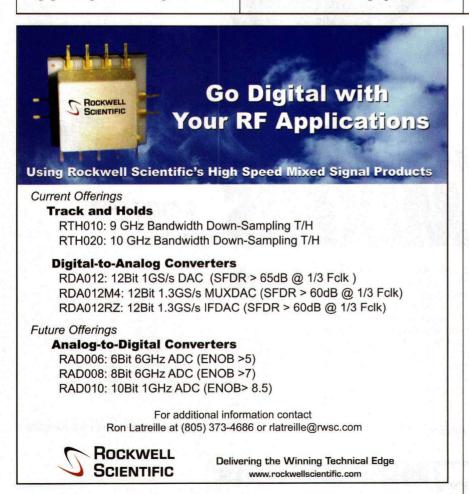
1. Diagrams for the LT5511 upconversion mixer (left) and LT5512 downconversion mixer (right) include matching elements.

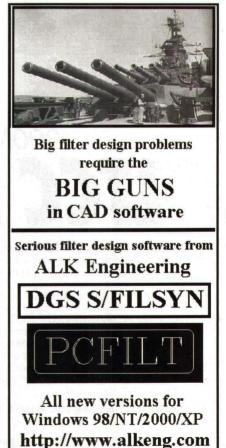
beads and resistors to the application board on which the mixer is mounted. The active mixers can be driven by single-ended LO sources, even beyond 2.5 GHz. They are designed to tolerate wide variations in input LO power with negligible impact on mixer performance.

Both the LT5511 upconverter (Fig. 1, top) and LT5512 downconverter (Fig.

1, bottom) mixers use an optimized double-balanced mixer core with the transistors' bases driven by an integrated LO buffer amplifier. Precision integrated bias circuits ensure high performance

over temperature; both ICs provide an enable control input for a power-down function. The mixers have differential RF, LO, and intermediate-frequency (IF) ports that allow flexibility of impedance matching for use in a wide variety of applications. Careful die lay-





(410) 546-5573



We know you have better things to do...

The RFMD® Advantage

High-performing, reliable, low-cost solutions Broad technology base

Industry-leading capacity

Design expertise

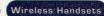
Knowledgeable sales team

Application and design support

On-time delivery

Our communication solutions will give you a whole new perspective.

RF Radio Wireless LAN Bluetooth® Infrastructure Wireless Handsets CATV PCS Systems





ProvidingCommunicationSolutions™

www.rfmd.com

out and well-planned package pinouts yield good port-to-port isolation and linearity. The LT5511 is packaged in a 16-lead TSSOP while the LT5512 is supplied in a 16-lead, 4 × 4-mm QFN housing.

The LT5511's IF input is simple to match. Two resistors set the current through the mixer core, while two DC blocks (for symmetry) provide DC isolation between the IF+ and IF- input ports. A capacitor across the IF ports reduces LO leakage. An IF balun performs an impedance transformation and single-ended-to-differential conversion. With a differential signal source, such as a digital-to-analog converter (DAC), it may be possible to eliminate the input balun.

The RF output match is realized with a pair of inductors, or transmission lines, followed by a balun. The match can be optimized with a shunt capacitor at the output. The LO port

44 MHz 1230 MHz
BPF 5511 BPF 5512

RFOUT 54-870 MHz

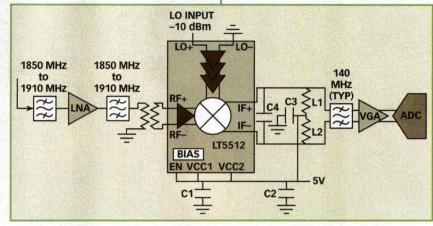
LO1 1274 MHz 1284-2100 MHz

2. The upconversion and downconversion mixers enable this downlink transmitter circuit for CATV systems.

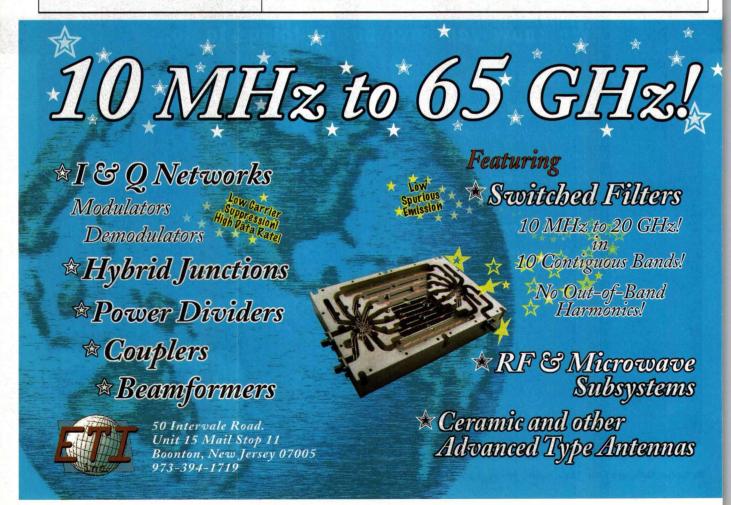
is matched with a shunt $62-\Omega$ resistor and a DC blocking capacitor for fre-

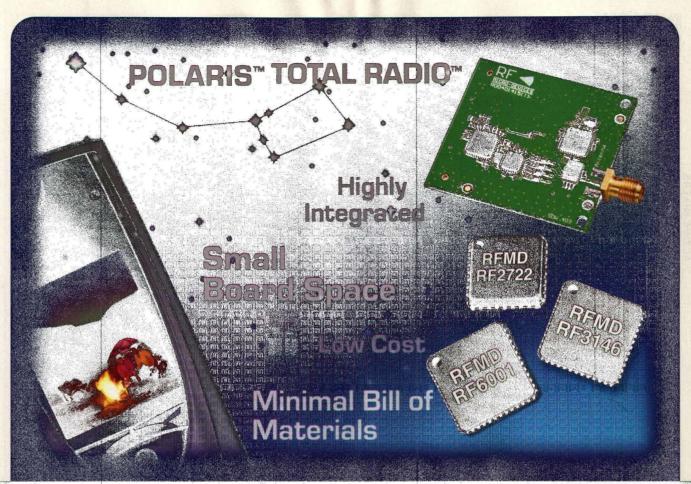
quencies below 1.5 GHz. At higher LO frequencies, the match requires only a shunt-series inductor-capacitor (LC) combination.

The LT5512's RF input port is easily matched for applications between 10 MHz and 3 GHz. RF match-



This multichannel wireless infrastructure receiver is based on the use of the LT5512 downconverter mixer to translate PCS frequencies to a 140-MHz IF.





... then to worry about your next GSM/GPRS solution.

RF Micro Devices leads the way for developing highly integrated solutions for nextgeneration applications that require low cost and reduced board space. RFMD's POLARIS'M TOTAL RADIO'M transceiver is a complete system level GSM/GPRS solution, including power amplifier, providing handset manufacturers the benefits of minimal bill of materials, flexible baseband interfaces and lower manufacturing cost. Let the POLARIS chipset guide your next handset design — giving you more free time to lay beneath the stars.

Features

- Quad-band operation 850, 900, 1800, 1900 MHz
- Low-cost, highly integrated TOTAL RADIO solution
- Low component count reduces board area
- Very low IF and DCR architecture.
- Integrated VCOs and associated loop filters
- Digital and analog I/Q baseband interfaces provide compatibility with new and existing baseband devices
- Integrated power amplifier ramp controller
- Fully integrated fractional-n synthesizer
- Unique digital modulator with very low power consumption

POLARIS TOTAL RADIO Chipset

RF2722 Quad-band Receiver

- SiGe BiCMOS process technology
- 5x5mm leadless plastic package

RF6001 Fractional-N Synthesizer, Digital Channel Filter and GMSK Modulator

- CMOS process technology
- 7x7mm leadless plastic package

RF3146 Quad-band PowerStar" PA

- GaAs HBT process technology
- 7x7mm Lead Frame Module package

For sales or technical support, contact 336.678.5570 or callcenter@rfmd.com.



ProvidingCommunicationSolutions™

www.rfmd.com

CDMA CDMA2000

EDGE



M IEEE 802.11b

TDMA

WCDMA

ACTIVE

DESIGN

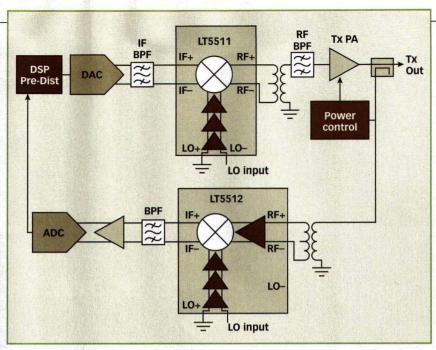
ing consists of one capacitor and a balun for single-ended-to-differential conversion. The center tap on the RF balun also provides a DC return path for the RF buffer amplifier. The IF output is also simple to match, requiring two bias chokes and a capacitor to set the output IF. An IF balun may be used for differential-to-single-ended conversion. The LO port is matched with a shunt resistor and DC blocking caps. A balun is not required for the LO port.

The active mixers are well suited for use in a CATV downlink transmitter for analog and digital television. In a simplified block diagram for this application (Fig. 2), variable attenuators required for precise output power control are not shown. In this architecture, a 44-MHz input signal from the DAC is filtered and upconverted to 1230 MHz by the LT5511 using a fixed LO. A bandpass filter attenuates the image frequency and any unwanted spurious. The resulting signal then drives the RF input of the LT5512. A wideband LO feeds the LT5512 to downconvert the 1230-MHz IF to the desired output frequency in the 54-to-870-MHz band. In this application, all spurious products within the CATV band must be 60 dB below the desired signal level.

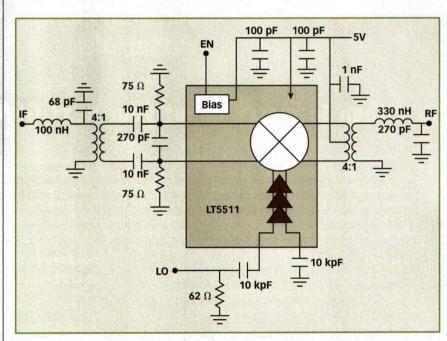
The good linearity of these active mixers also makes them well suited for low-distortion cellular applications, including multichannel receivers (Fig. 3). In this receiver, the LT5512 downconverts PCS input signals to a 140-MHz IF. The mixer's differential IF output is matched directly to a differential SAW filter, eliminating the need for an IF balun while preserving the benefits of differential signal processing to the ADC.

On the multiple-carrier transmit side, the LT5511 can be used to upconvert multiple carriers from a DAC directly to the transmit frequency (Fig. 4). The LT5512 is then used in a pre-distortion feedback loop to downconvert a sample of the transmit signal for digital processing.

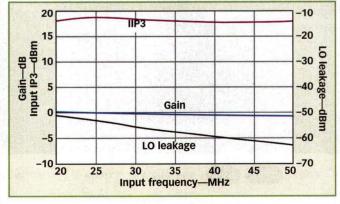
To demonstrate its versatility, the LT5511 was evaluated in a low-frequency downmixer application requiring high linearity (**Fig. 5**). In this case, the mixer had an input frequency range



4. This multichannel wireless infrastructure transmitter features predistortion feedback.



With the proper impedance matching components, the LT5511 upconversion mixer can be used at HF.



6. The measured performance of the LT5511 shows that it is fully capable of handling low-frequency applications with the proper external impedance matching.

SPLITTER HYBRID COUPLER



SYNSTRIP TECHNOLOGY PATENT PENDING

For additional information, contact Synergy's sales and application team.

201 McLean Boulevard, Paterson, NJ 07504

Phone: (973) 881-8800 Fax: (973) 881-8361

E-mail: sales@synergymwave.com

World Wide Web: www.synergymwave.com

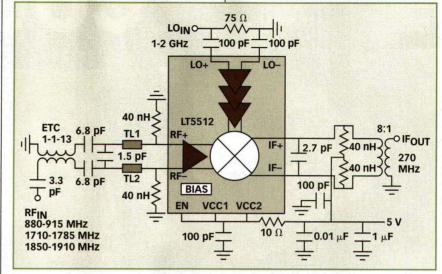


of 20 to 50 MHz and an output frequency of 10 MHz. On the IF input, the values of the components have been increased to accommodate the lower frequencies and a series-shunt LC combination prior to the transformer was added to optimize the impedance match. The output match is very simple, requiring only the balun, a series inductor, and shunt capacitor. On the LO port, a larger DC blocking capacitor was used for the lower-frequency coverage. At an IF of 25 MHz and an LO level of -10 dBm, conversion gain was 0 dB, input IP3 was +18.8 dBm, and LO leakage to the output was -41 dBm (Fig. 6). The measured input second-order intercept (IP2) performance was +61 dBm.

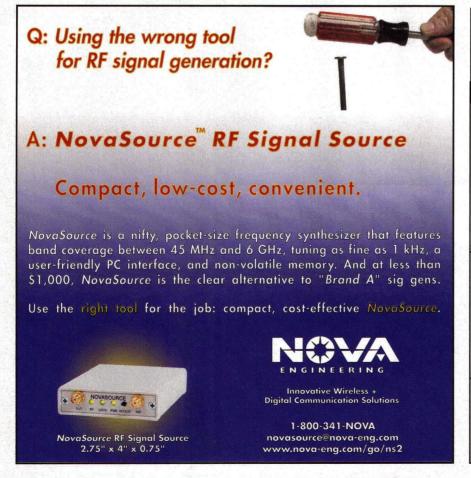
Another example of the flexibility of these mixers is a triband downconversion application for the LT5512 in which a bandpass RF input matching network supports operation at the 900,

1800, and 1900 MHz GSM bands (**Fig. 7**). The IF port is matched for 270-MHz operation. The design achieves 0.7 dB conversion gain at 900 MHz with 0.3 dB conversion gain at 1800 MHz

and only 0.2 dB conversion loss at 1900 MHz. The input IP3 levels at 900, 1800, and 1900 MHz, respectively, are +18.3, +18.2, and +20.6 dBm.



7. This application circuit uses the active mixers to handle downconversion for the 900-, 1800-, and 1900-MHz GSM bands.



We Design And Manufacture To Meet Your Requirements Prototype or Production Quantities

800-522-2253

This Number May Not Save Your Life...

But it could make it a lot easier! Especially when it comes to ordering non-standard connectors.

RF/MICROWAVE CONNECTORS CABLES & ASSEMBLIES

Specials our specialty. Virtually any SMA, N, TNC, BNC, SMB, or SMC delivered in 2-4 weeks.

Connectors supplied to your drawings and specs.

Extensive inventory of passive RF/Microwave components including attenuators, terminations and dividers.

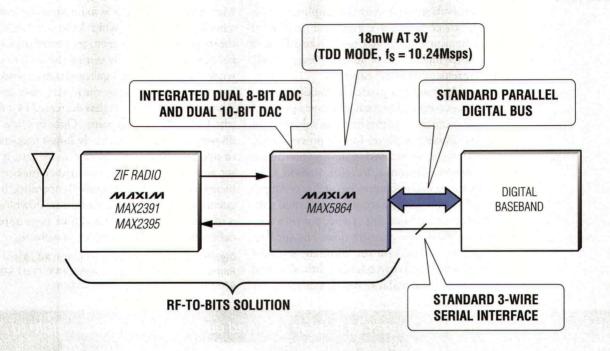
NEMAL ELECTRONICS INTERNATIONAL, INC.

12240 NE 14 AVENUE • NORTH MIAMI, FL 33161 TEL: 305-899-0900 • FAX: 305-895-8178 BRASIL: (011) 5535-2368

E-MAIL: INFO@NEMAL.COM URL: WWW.NEMAL.COM

INDUSTRY'S FIRST ULTRA-LOW-POWER ANALOG FRONT END ACHIEVES HIGH DYNAMIC PERFORMANCE AT 18mW

30% Smaller, 80% Less Power, and Lower Cost than Competing Solutions!



- Integrated High-Speed,
 Dual 8-Bit ADC and Dual 10-Bit DAC
- ◆ SINAD = 48.4dB (ADC) at f_{IN} = 1.8MHz, and ACLR = -57dB (DAC) with W-CDMA
- FDD and TDD Operating Modes
- ◆ 3-Wire Serial Interface Controls Rx-Tx Modes and Power Management
- Applications Include: W-CDMA, TD-SCDMA, 802.11b Wireless Devices

Part	Speed (Msps)	Power (mW) (FDD Mode)	Power (mW) (TDD Mode)	Price [†] (\$)
MAX5863	7.5	23	15	4.95
MAX5864	22	42	31	5.35
MAX5865	40	78	66	6.45

†1000-up recommended resale. Prices provided are for design guidance and are FOB USA. International prices will differ due to local duties, taxes, and exchange rates. Not all packages are offered in 1k increments, and some may require minimum order quantities.



www.maxim-ic.com

FREE High-Speed ADC/DAC Design Guide—Sent Within 24 Hours!

CALL TOLL-FREE 1-800-998-8800 (6:00 a.m.-6:00 p.m. PT)
For a Design Guide or Free Sample







application notes

Measure The Gain Compression Of Power Amplifiers

ACCURATE MEASUREMENTS OF AN amplifier's 1-dB gain compression can simplify comparisons of different products. Basic test instruments required for such measurements include a high-quality RF or microwave frequency synthesizer (to supply stimulus signals) and a high-performance power meter (to evaluate the output signal levels generated by the amplifier under test). Power meters are used in a traditional measurement setup because they can be calibrated and offer high levels of accuracy over a wide measurement dynamic range.

An alternative approach to making amplifier gain-compression measurements also relies on the frequency synthesizer, but substitutes a scalar network analyzer for the power meter. The method, as outlined in the an application note from Giga-tronics, Inc. (San Ramon, CA), "Measuring Gain Compression of Power Amplifiers," can achieve the accuracy associated with a power-meter-based test system, but with considerably less measurement time. The application note is based on the company's model 12000A microwave frequency synthesizer and the model 8003 scalar network analyzer.

As the note describes, in order to verify the worst-case 1-dB compression point of an amplifier under test with a power meter, many repetitions may be necessary at different frequencies. A scalar network analyzer allows swept-frequency measurements to be made over the full operating range of the amplifier. Measurement accuracy is maintained by using a frequency synthesizer which locks and stabilizes the frequency at each point to an internal or external reference source. By setting the scalar network analyzer to display gain and output power, it is possible to determine the input power level where an amplifier's gain has decreased by 1 dB (the 1-dB compression point). Once this first 1dB point has been located for the lowest frequency of operation for the amplifier under test, it is set as a reference point for further measurements throughout the amplifier's operating frequency range. For more information, download a free copy of the illustrated four-page application note from the company's website.

Giga-tronics, Inc., 4650 Norris Canyon Rd., San Ramon, CA 94583; (925) 328-4650, FAX: (925) 328-4700, Internet: www.gigatronics.com.

By setting the scalar network analyzer to display gain and output power, it is possible to determine the input power level where an amplifier's gain has decreased by 1 dB.

Optimizing VCO And Frequency-Synthesizer Designs

visit PlanetEE.com

voltage-controlled oscillators (vcos) and phase-locked loops (PLLs) are used throughout wireless communications systems as signal sources for frequency downconversion and upconversion in receivers and transmitters. Optimizing the performance of these components requires the experience and expertise of a small handful of seasoned design engineers. Fortunately, an application note from Agilent Technologies, "Agilent 4352S VCO/PLL Signal Test System: Optimizing VCO/PLL Evaluations and PLL Synthesizer Designs," provides some guidance into the fine art of VCO and PLL optimization (including the loop filters) for those engineers with even limited experience.

The application note reviews the key characteristics of VCOs, including oscillation frequency, power level, phase noise, tuning sensitivity, and harmonic/spurious noise, and also details the problems with the conventional method of evaluating VCOs and PLLs. For example, the use of a general-purpose DC power supply as the DC control voltage source

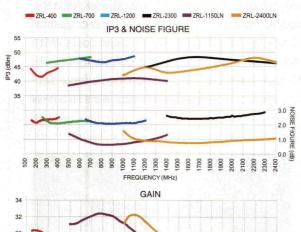
for the VCO can degrade the measured VCO phase-noise characteristics and provide misleading information about the performance of the VCO under evaluation.

The solution lies in the use of the 4352S measurement system for characterizing and evaluating PLLs and VCOs. The system is self-contained, and includes its own low-noise DC power source for tuning VCOs under test. Additional instrument functions in the system include a digital multimeter, modulation source, RF power meter, frequency counter, and Fast Fourier Transform (FFT) analyzer. The system is relatively simple to operate, since its automatic frequency-control capability works with the frequency counter and DC source to precisely control DC tuning voltage based on desired operating frequencies entered by the test operator. Copies of the 24-page note, which includes extensive details on different system configurations, can be downloaded from the company's website.

Agilent Technologies, (800) 452-4844, Internet: www.agilent.com.







(dB) GAIN 500 600 700 800 900 1000 1100 1200 1300 1400 1500 1700 1800 1800 1900 2200 2300 2400 FREQUENCY (MHz

from 0.8dB NF and up to 46dBm IP3

Using Mini-Circuits award winning ZRL amplifiers, you're ready to handle just about all your high dynamic range applications across the entire 150-2400MHz band! Thanks to Low Temperature Co-fired Ceramic (LTCC) technology and balanced amplifier design, these ZRLs provide rock-solid reliability, are extremely rugged, and phenomenally low in cost. Now you can get ahead of your competition with ZRL amplifiers from Mini-Circuits!

Mini-Circuits...we're redefining what VALUE is all about!

SPECIFICATIONS (Typical) T=25°C

Model	Freq. (MHz)	Gain (dB)	Noise Fig. (dB)	IP3 (dBm)	Max. Pwr. Out @1dB Comp. (dBm)	Price \$ ea. (1-9)
ZRL-400	150-400	30	2.5	42	25.0	119.95
ZRL-700	250-700	29	2.0	46	24.8	119.95
ZRL-1150LN	500-1400	31	0.8	40	24.0	119.95
ZRL-1200	650-1200	27	2.0	46	24.3	119.95
ZRL-2300	1400-2300	24	2.5	46	24.6	119.95
ZRL-2400LN	1000-2400	27	1.0	45	24.0	139.95

DC Power 12V DC, Current 550mA, Dimensions: (L) 3.75" x (W) 2.00" x (H) 0.80"

Detailed Performance Data & Specs Online at: www.minicircuits.com/ZRL-SERIES.pdf

P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 For quick access to product information see MINI-CIRCUITS CATALOG & WEB SITE The Design Engineers Search Engine Provides ACTUAL Data Instantly From MINI-CIRCUITS At: www.minicircuits.com

cover story

SiGe Direct Modulators Ease Upconverter Design

These efficient direct quadrature modulators support digital modulation formats with I and Q bandwidths as wide as 250 MHz for carrier frequencies from 250 to 7000 MHz.

irect quadrature modulators provide many benefits to transceiver/transmitter designers working with modern digital-modulation formats. Compared to superheterodyne upconversion approaches, direct quadrature modulation enables simpler, smaller designs at lower costs. With advances in RF integrated circuit (RF IC) and silicon-germanium (SiGe) process technologies, the engineers at Hittite Microwave have succeeded in bringing direct quadrature modulator components to a new

level, extending direct modulation to 7 GHz. The company's models HMC495LP3 and HMC496LP3 SiGe direct quadrature modulators work

from 250 to 3800 MHz and from 4.0 to 7.0 GHz, respectively, housed in compact 3 × 3-mm leadless surface-mount packages. With these modulators, designers can simplify a transmit-signal chain by eliminating one mixer stage, along with its associated matching, filtering, voltage-controlled oscillator (VCO), phase-locked loop (PLL),



1. The HMC495LP3 and HMC496LP3 direct quadrature modulators are supplied in compact, 3 \times 3-mm leadless surface-mount packages.

MARK T. FALLICA
Marketing Engineer, Product
Development Group
Hittite Microwave Corp., 12
Elizabeth Dr., Chelmsford, MA
01824; (978) 250-3343, FAX:
(978) 250-3373, Internet:
www.hittite.com.

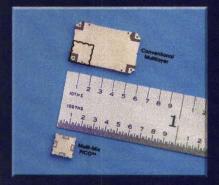


LTI-MIX PIC

World's Smallest Size:Power RF Products

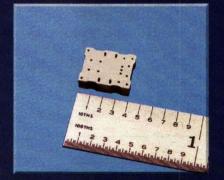
- 85% Smalller
- Up to 100 Watts of Power
- Low Cost
- Less Loss

Quads & Couplers



- Lowest Loss: < 0.20 dB
- Smallest Size: 0.18" x 0.18"
- Power: Up to 100 Watts
- Frequencies: 1.9, 2.1, 2.45, 3.5 GHz
- Tape & Reel

Filters



- No Tuning
- Surface Mount
- · Low Loss
- Up to 42 GHz
- Passbands as narrow as 1%
- · Tape & Reel

Power Dividers



- Surface Mount
- Less Size
- Less Cost
- Less Weight
- Tape & Reel



Tel: 1.888.434.6636 Fax: 973.882.5990 www.Multi-Mix.com

and LO buffering circuitry.

The HMC495LP3 and HMC496LP3 wideband SiGe direct quadrature modulators (Fig. 1) are based on high-frequency SiGe heterojunction-bipolar-transistor (HBT) technology. The silicon semiconductor process supports high-level integration at extremely high transition frequencies and with relatively low power consumption. The lower-

frequency HMC495LP3 is suitable for Global System for Mobile Communications (GSM), code-division multiple access (CDMA), wideband CDMA (WCDMA), personal handyphone system (PHS), fixed-wireless, MMDS, and wireless-local-loop (WLL) systems. The higher-frequency HMC496LP3 serves IEEE 802.11a wireless-local-area-network (WLAN), UNII, and microwave radio applications.

The HMC495LP3 employs a polyphase network which separates the local oscillator (LO) into two equal amplitude signals, with 90-deg. phase difference between them (Fig. 2). The signal-splitting and limiting-amplification circuitry comprising the polyphase network is designed for optimum performance over a wide range of LO input power levels. LO signal paths are closely matched on chip to minimize phase offsets; the differential-mode transmission lines provide excellent immunity to noise. Each divided LO signal drives an active Gilbert-cell mixer, upconverting the IP/IN in-phase and QP/QN quadrature baseband data inputs, respectively. The upconverted IP/IN and OP/ON signals are then recombined in-phase, and converted from a balanced transmission line to a single-ended RF output.

The dynamic range of a direct quadrature modulator is critical in maintaining the integrity of digitally modulated signals. The dynamic range of a direct modulator can be defined as the ratio of its output power at 1-dB compression (in dBm) to its output noise floor (in dBm/Hz). The HMC495LP3 achieves output power at 1-dB compression of

The HMC495LP3 direct modulator at a glance				
PARAMETER	SPECIFICATION			
Frequency range	250 to 3800 MHz			
Output power at 1-dB compression	0 dBm			
Output third-order intercept	+13 dBm			
Output noise floor	-158 dBm			
Carrier suppression (uncalibrated)	-34 dBc			
Sideband suppression (uncalibrated)	-28 dBc			
Third-order intermodulation suppression	-50 dBc			
Typical ACPR for CDMA IS-95 (at 880 and 1960 MHz)	-72 dBc			
Typical ACPR for WCDMA 3GPP (at 2140 MHz)	-59 dBc			

Note: Values are worst case for full band.

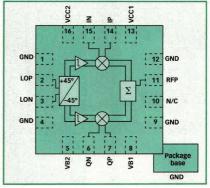
typically +2 dBm at 450 MHz and -2 dBm at 3800 MHz. The device's output noise floor is typically –157 dBm/Hz at 450 MHz and at 3800 MHz (**Fig. 3**), with the output noise floor measured at an offset of 20 MHz from the carrier, with supply voltage ($V_{\rm cc}$) of +3.3 VDC and baseband bias voltage ($V_{\rm DC}$) of +1.15 VDC. These values translate into a dynamic range of 155 to 159 dB across the 450-to-3800-MHz band.

Another important aspect of a direct quadrature modulator's performance is its sideband and carrier suppression, as well as its ability to control third-harmonic output levels. The HMC495LP3 direct quadrature modulator typically attains sideband and carrier suppression of -30 and -35 dBc, respectively, with output third-harmonic distortion of -50 dBc across the full band (see table). These suppression levels were measured for typical output power of -6 dBm, $V_{\rm cc}$ of +3.3 VDC, baseband frequency

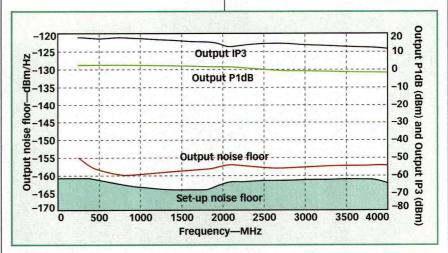
of 200 kHz at 800 mV peakto-peak differential, and baseband bias voltage of +1.15 VDC. In specific bands, the performance is often considerably better, with third-harmonic suppression of –59 dBc from 450 to 960 MHz and –56 dBc from 3400 to 3800 MHz (Fig. 4).

The high dynamic range of the HMC495LP3 is evident in its outstanding adjacent-chan-

nel-power-ratio (ACPR) performance under WCDMA conditions (Fig. 5). When driven to –14 dBm of WCDMA channel power at 2140 MHz, the HMC495LP3 provides ACPR performance of better than –59 dBc in both upper and lower adjacent channels. This performance is as good or better



2. The HMC495LP3 direct quadrature modulator includes carefully matched signal paths with a pair of mixers offset by 90 deg.



3. This plot shows the output third-order-intercept point, output noise floor, and measurement setup noise floor as functions of frequency for the HMC495LP3.

2W&5W DC to 18GHz ATTENUATORS



Rugged Stainless Steel Construction, High Repeatability, Miniature Size, Low Cost, and Off-The-Shelf Availability are some of the features that make Mini-Circuits "BW" family of precision fixed attenuators stand above the crowd! This extremely broad band DC to 18GHz series is available in 5 watt Type-N and 2&5 watt SMA coaxial designs, each containing 15 models with nominal attenuation values from 1 to 40dB. Built tough to handle 125 watts maximum peak power, these high performance attenuators exhibit excellent temperature stability, 1.15:1 VSWR typical, and cover a wealth of applications. So contact Mini-Circuits today, and capture this next generation of performance and value!

Mini-Circuits...we're redefining what VALUE is all about!

±0.40 ±0.40 S6W2 S6W5 N6W5 +0.40 ±0.60 N7W5 S7W2 S7W5 S8W2 S9W2 **N9W5** ±0.60 S10W2 S10W5 N10W5 ±0.60 S12W2 +0.60 S15W2 N15W5 ±0.60 S20W2 S20W5 N20W5 ±0.60 S30W2 S30W5 N30W5 30 +0.85S40W5 N40W5

*At 25°C includes power and frequency variations up to 12.4GHz. Above 12.4GHz add 0.5dB typ. to accuracy.



Type-N to SMA

SMA to SMA \$495 ea. \$595 ea. \$895 ea

For detailed adapter specs visit: www.minicircuits.com/adapter.html



P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 For quick access to product information see MINI-CIRCUITS CATALOG & WEB SITE The Design Engineers Search Engine Provides ACTUAL Data Instantly From MINI-CIRCUITS At: www.minicircuits.com

PIN DIODE CONTROL DEVICES

PIN DIODE

TENUATORS

- 0.1–20GHz
- **Broad & narrow band** models
- Wide dynamic range
- Custom designs



Attenuator types offered are: Current Controlled, Voltage Controlled, Linearized Voltage Controlled, Digitally Controlled and Digital Diode Attenuators

PIN DIODE

- **Broad & narrow** band models
- 0.1-20GHz
- Small size
- Custom designs



SPST thru SP8T and Transfer type models are offered and all switches are low loss with isolation up to 100dB. Reflective and nonreflective models are available along with TTL compatible logic inputs. Switching speeds are 1µsec.—30nsec. and SMA connectors are standard. Custom designs including special logic inputs, voltages, connectors and package styles are available. All switches meet MIL-E-5400

PIN DIODE

PHASE SHIFTERS

- 0.5-20GHz
- Switched Line
- Varactor Controlled
- Vector Modulators
- Bi-Phase Modulators
- QPSK Modulators



Passive Components and Control Devices can be integrated into subassemblies to fit your special requirements. Call for more information and technical assistance.

Custom Designs

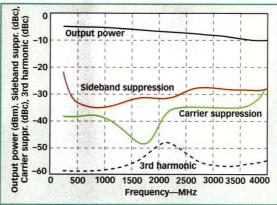
CALL OR WRITE



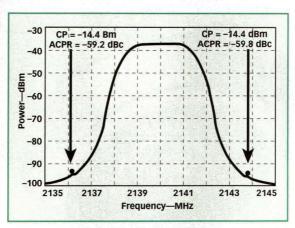
P.O. Box 718, West Caldwell, NJ 07006 (973) 226-9100 Fax: 973-226-1565 E-mail: wavelineinc.com

cover story

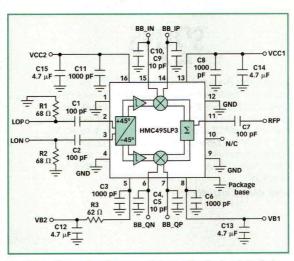
than other, more narrowband direct modulator RF ICs. Note that the WCDMA ACPR was measured at an offset of 3.84 MHz using a spectrum ana-



4. The HMC495LP3's output power, sideband suppression, carrier suppression, and third-harmonic distortion are shown here as functions of frequency.



5. The ACPR performance of the HMC495LP3 is plotted here under WCDMA signal conditions at 2140 MHz.



6. This schematic diagram shows a typical printed-circuit-board (PCB) application for the HMC495LP3 direct quadrature modulator.

lyzer with 30-kHz resolution-bandwidth filters, V_{cc} of +3.3 VDC, and baseband bias voltage of +1.15 VDC.

The versatile HMC495LP3 direct

quadrature modulator accepts a wide range of LO input power levels from -6 to +6 dBm, and delivers an extremely wide I and Q modulation bandwidth of DC to 250 MHz (in support of virtually all existing and many emerging modulation formats) when using the recommended 10-pF shunt capacitors. The HMC495LP3 will provide stable operation over a supply voltage range of +3.0 to +3.6 VDC, and a temperature range of -40 to +85°C.

The LO port of the HMC495LP3 can be driven in either single-ended or differential mode. Driving the LO port in singleended mode will eliminate the need for an external balun, the cost of which will depend on the frequency and bandwidth of operation. Driving the LO port in differential mode will improve the carrier suppression level by about 3 dB at 3500 MHz, although the relative improvement will be less at lower frequencies. Modulator carrier suppression can be improved by adjusting the DC offset in the I and Q input ports. The ideal DC offset of the I and Q signals depends on the final circuit layout, so the DC offset should be adjusted accordingly to correct for any slight asymmetries in the final circuit layout.

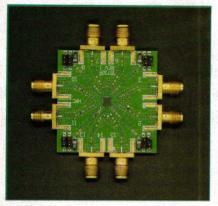
Similarly, HMC495LP's sideband suppression can be optimized by adjusting the gain



Electrically: There is almost no difference, compared to our straight connectors. We are having the most advanced tools available to always design state-of-the-art connectors.

Mechanically: They are small! And if we say small, we mean small! They are only as big as the connector series requires! We do not sell connectors by the pound! We design connectors to the smallest possible configuration, as lightweight as possible!

The management philosophy at Spectrum Elektrotechnik GmbH is based upon the innovative concept of "Entrepreneurship". A group of individuals act as a creative team within the corporate structure. Each team specializes in a particular product and completely understands and manages one of the product families. Spectrum Elektrotechnik GmbH has adopted the entrepreneurial system for one simple reason: Customer satisfaction. The effort of undivided attention is addressed to each single product, from design to manufacturing. No compromises are made, no details are overlooked. The team remains most alert to all customer requirements and is able to maintain complete communication with the customer. The result is complete understanding. Understanding begins already as the team studies the specifications. Goals are identified, a course is plotted. Questions are answered before they become problems; doubts are clarified before they are misunderstood. The team pilots each project through design, manufacturing and testing, until the ultimate objective is achieved: A quality product on time.



7. This photograph shows a packaged HMC495LP3 mounted on one of the company's evaluation boards.

and phase offset between the I and Q input ports. As with the carrier-suppression DC offset adjustment, the ideal gain and phase offset between the I and O signals depends on the actual application circuit.

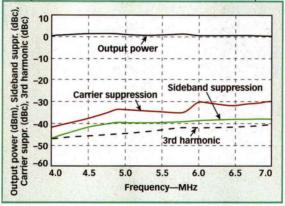
The HMC495LP3 can be used to create virtually any analog- or digitalmodulation format including binary

phase-shift keying (BPSK), quadrature phase-shift keying (QPSK), eight-state phase-shift keying (8PSK), orthogonal frequencydivision multiplex (OFDM), and quadrature amplitude modulation (QAM). The direct quadrature modulator's wide bandwidth and low noise floor make it a suitable choice for base-station, access point, and customer-premisesequipment (CPE) applications in the cellular, personal-communications-services (PCS), UMTS, fixed wireless, and Hiper-LAN/HiperMAN WLAN bands. This wideband capability allows the transceiver designer to use a common printed-circuit-board (PCB) design for multiple frequency bands. The HMC495LP3 is also well suited for applications in software-defined radios (SDRs) where the upconverter must dynamically vary its modulation format depending on changing conditions and requirements (Fig. 6).

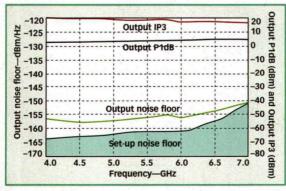
in this article, data were taken applied to the HMC495LP's LOP noise as functions of frequency.

port, with the LON port terminated to ground through a $50-\Omega$ resistor (Fig. 7). A shunt $68-\Omega$ resistor is used on each of the LON and LOP ports to improve LO port return loss, while a 100pF series capacitor prevents DC voltage from appearing on the application PCB.

The HMC495LP3 has two supply and two bias input lines. To reduce any power-supply noise, each of these lines is decoupled by shunt 4.7-µF capacitors placed close to the input connector, and shunt 1000-pF capacitors placed in close proximity to the 3×3 -mm package. The nominal supply voltage for V_{cc1} and V_{cc2} is +3.3 VDC. Voltage V_{bb1} is tied to V_{cc} , while the V_{bb2} voltage is dropped to +3.0 VDC through a series $62-\Omega$ resistor; this reduction in V_{bb2} will improve the sideband suppression and output noise, while reducing the overall power consumption. The RF output of the HMC495LP3 is single ended and



8. These curves show the HMC496LP3's output power, sideband suppression, carrier suppression, and thirdharmonic distortions as functions of frequency.



For the measurements shown 9. These curves show the HMC496LP3's output thirdorder intercept point, output power at 1-dB compreswith a single-ended LO source sion, output noise floor, and measurement setup

a series 100-pF capacitor is used for DC blocking.

The IP/IN and QP/QN ports of the HMC495LP3 are DC coupled to allow modulation frequencies down to DC. All four ports are shunted to ground with a 10-pF capacitor. This capacitance value was chosen for a low impedance to ground at the LO frequency, in order to improve the carrier suppression and to filter noise. The HMC495LP's modulation bandwidth can be increased beyond 250 MHz by removing these capacitors or reducing their values.

In addition to the HMC495LP3, the company has also announced the HMC496LP3 4.0-to-7.0-GHz SiGe direct modulator for higher-frequency applications. It offers typically -39 dBc sideband suppression and -35 dBc carrier suppression, with third-harmonic intermodulation levels of typically -44 dBc (Fig. 8). These suppression levels

> were measured with typical output power of +3 dBm, V_{cc} of +3.0 VDC, baseband frequency of 200 kHz at 1.2 V peak-to-peak differential voltage and V_{dc} of +1.3 VDC.

> The HMC496LP3 achieves output power at 1-dB compression of typically +3 dBm at 4.0 GHz and +4 dBm at 6.0 GHz. The output noise floor is typically -157 dBm in a 1-Hz bandwidth from 4.0 to 6.0 GHz (Fig. 9), when measured at an offset of 20 MHz, with V_{cc} of +3.0 VDC and V_{dc} of +1.3 VDC. These values translate into a dynamic range of approximately 160 dB from 4.0 to 6.0 GHz.

> Both the HMC495LP3 and the HMC496LP3 wideband SiGe direct quadrature modulators are available from stock. Complete specifications can be found on the company's website. The company also offers evaluation boards fabricated on high-performance 4350 PCB material from Rogers Corp. (Rogers, CT) with SMA connectors for ease of testing. Hittite Microwave Corp., 12 Elizabeth Dr., Chelmsford, MA 01824; (978) 250-3343, FAX: (978) 250-3373, Internet: www.hittite.com.

SPACE QUALIFIED

AMPLIAIARS MIXERS . SYNTHESIZERS . SUPERCOMPONENTS



PRODUCT APPLICATIONS

- · SATOOM UNAS .
- · Spaceborge Radar
- · Transmitter Drivers
- · Radiometric Sensors

OFFERING DESIGNS

- · Fran 2 kHz to 50 GHz .
- · Optimized for Low Power Consumption
- · Maring MIL-PREZUSZA Class K or MIL-STD-ILLE Class S
- . Capable of Withstanding the Rigorous Demands of Long Mission Life

For further information, please contact David Krautheimer at (531) 439-9413 or direntheimer omiteq.com



100 Davids Drive. Hauppauge, WY 11788 TEL: (631) 436-7400 FAX: (631) 436-7430 .

www.miteq.com



PRODUCT technology

Carrier-To-Noise Generators Enhance BER Testing

These communications test instruments offer increased accuracy through the careful control of potential causes of measurement uncertainty.

arrier-to-noise (C/N) generators continue to be essential ingredients in evaluating the performance of receivers employed in CATV, cellular, satellite communications, and WLAN systems. These instruments essentially combine a carrier supplied by the user with internally generated additive white Gaussian noise (AWGN) source to produce an output signal that contains a precise ratio of carrier and noise.

They are particularly well suited for BER, SINAD, and channel-impairment testing, in which they can help determine a receiver's ability to perform under a wide range of signal conditions. C/N generator architecture has changed little over the years, while the expected performance of communications systems has dramatically increased. To address the need for greater instrument capability, accuracy, and reliability, dBm Corp.

The CNG Series (see figure) is a family of instruments with models targeted at intermediate-frequency (IF) applications (typically 70 and 140 MHz) and RF applications from 800 MHz to 6.0 GHz (with specialized

(Wayne, NJ) has created the CNG Series C/N generators using an architecture that

delivers significant improvements in

performance, ease of use, and long-

term reliability.

models covering frequencies to 30 GHz). The frequency bands of the standard models correspond to the interference conditions required by applications such as

satellite or cellular/PCS communications, WLAN, and CATV, and the instruments are compatible with all ana-

log and digital modulation schemes. Fully automated operating modes include C/N, C/N_o , E_bN_o , and C/I modes. The instruments feature noise bandwidths from 50 to 180 MHz.

The instruments can be used in benchtop environments or as part of an automatic-test-equipment (ATE) system for production testing. In the latter application, the use of solid-state attenuators extends the service life and reliability of the instrument and increases execution speed, key considerations in high-volume production testing. The front-panel controls include separate keys to invoke each main function with LED indicators and a bright LCD display to provide a clear indication of all settings.

The CNG Series instruments are available with one or two independent RF channels, for simplex, diversity, or duplex testing. As many as 10 test scenarios can be stored in memory, and the instrument will automatically measure the carrier signal and precisely adjust the power of the internal noise source to maintain the desired ratio. External

MICHAEL CAGNEY Vice President of Sales and Marketing

dBm Corp., 6 Highpoint Dr., Wayne, NJ 07470; (973) 709-0020, FAX: (973) 709-1346, e-mail: info@dbmcorp.com, Internet: dbmcorp.com.



The CNG Series of carrier-to-noise generators provide one or two channels of precisely calibrated ratios of carrier signals and AWGN for IF and RF testing.



7755\$2

Easily combines RF+DC signals for your modulation or test requirements.

Now up to 500mA DC current 100kHz-6GHz

With Mini-Circuits Bias-Tees, you can DC connect to the RF port of an active device without effecting its RF properties...modulate a laser, apply DC to an amplifier output, and more! Using statistical process control plus combining

magnetics and microstrip, large DC currents may pass through the Bias-Tee without saturation and degradation of performance. At 1/3 to 1/4 the price of competitive units, these new Bias-Tees are available in surface mount, pin, and connectorized models. So why wait, solve your connection problems with Mini-Circuits Bias-Tees.

Mini-Circuits...we're redefining what VALUE is all about!

Model	Freq (MHz)		rtion I B Typ			solation		VSWR (Typ.)	Price \$ ea
	F,-F.	L	M	U	L	M	U	U	1-9 qty.
▲ZFBT-4R2G	10-4200	0.15	0.6	0.6	32	40	50	1.13:1	59.95
▲ZFBT-6G	10-6000	0.15	0.6	1.0	32	40	30	1.13:1	79.95
▲ZFBT-4R2GW	0.1-4200	0.15	0.6	0.6	25	40	50	1.13:1	79.95
▲ZFBT-6GW	0.1-6000	0.15	0.6	1.0	25	40	30	1.13:1	89.95
▲ZFBT-4R2G-FT	10-4200	0.15	0.6	0.6	N/A	N/A	N/A	1.13:1	59,95
▲ZFBT-6G-FT	10-6000	0.15	0.6	1.0	N/A	N/A	N/A	1.13:1	79.95
▲ZFBT-4R2GW-FT	0.1-4200	0.15	0.6	0.6	N/A	N/A	N/A	1.13:1	79.95
▲ZFBT-6GW-FT	0.1-6000	0.15	0.6	1.0	N/A	N/A	N/A	1.13:1	89.95
★ZNBT-60-1W	2.5-6000	0.2	0.6	1.6	75	45	35	1,35:1	82.95
■PBTC-1G	10-1000	0.15	0.3	0.3	27	33	30	1.10:1	25.95
■PBTC-3G	10-3000	0.15	0.3	1.0	27	30	35	1.60:1	35.95
■PBTC-1GW	0.1-1000	0.15	0.3	0.3	25	33	30	1.10:1	35.95
■PBTC-3GW	0.1-3000	0.15	0.3	1.0	25	30	35	1.60:1	46.95
•JEBT-4R2G	10-4200	0.15	0.6	0.6	32	40	40	-0	39.95
•JEBT-6G	10-6000	0.15	0.7	1.3	32	40	40		59.95
•JEBT-4R2GW	0.1-4200	0.15	0.6	0.6	25	40	40		59.95
•JEBT-6GW	0.1-6000	0.15	0.7	1.3	25	40	30		69.95

L = Low Range M = Mid Range U = Upper Range

NOTE: Isolation dB applies to DC to (RF) and DC to (RF+DC) ports.

A SMA Models, FT Models Have Feedthrough Terminal *Type N, BNC Female at DC

PIn Models *Surface Mount Models

RF+DC

P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 For quick access to product information see MINI-CIRCUITS CATALOG & WEB SITE The Design Engineers Search Engine Provides ACTUAL Data Instantly From MINI-CIRCUITS At: http://www.minicircuits.com

PRODUCT technology

interference signals can also be injected in place of the internal sources, for measurements of carrier power, noise power, and interference power, and set the C/N and C/I ratios.

The CNG Series instruments employ a thermal termination as the noise

source, rather than the traditional noise diode, eliminating diode-based amplitude distribution errors and providing a high crest factor with no asymmetry in noise-voltage distribution. Compensation is automatically provided for bit rate, signal bandwidth, duty cycle,

and power-level settings, and inputsignal variations can be automatically tracked and negated to ensure the desired ratio is maintained. The instruments downconvert carrier signals to 140 MHz, measure the power at that frequency, and then add a precise level of noise. The signal with noise is then upconverted to its original frequency. By performing the power measurement and noise addition at IF, very high accuracy can be achieved.

Ratio accuracy is the most important specification for a C/N generator, since it has a direct and dramatic effect on UUT performance. For example, if a 64QAM system is being tested for BER and the C/N ratio uncertainty is a seemingly insignificant ±0.5 dB, the measured BER could nonetheless be inaccurate by a factor of more than 10,000. Consequently, it is imperative that ratio accuracy be as precise as possible—and verifiable. The CNG Series achieves verifiable ratio accuracy of less than 0.2 dB (and typically 0.1 dB) by compensating for every possible source of error.

Errors can arise from variations in noise-density and signal-path flatness, step-attenuator resolution, impedance mismatch, and the method and test equipment used for calibration. To minimize all sources of potential error and ensure ratio accuracy, dBm uses various compensation techniques, and overall ratio accuracy is measured in every instrument over the operating frequency and input power range.

In order to maintain a precise level of Eb/No over frequency, the instrument must account for signal-path gain variations and noise-density variations over the entire operating frequency of the instrument rather than at a single discrete point. The CNG Series accomplishes this by compensating for noise density and signal gain at all frequencies in 1-MHz increments. For signals that occupy a large bandwidth, there is also a possibility of additional C/N uncertainty caused by variations in the signal-path gain and the noise spectral distribution flatness. The instrument also accounts for these effects, utilizing its internal calibration factors and the

CONCERTO - The Software Tool For Microwave Design



CONCERTO is a state-of-the-art software package for the design of 3D millimeter and microwave devices. Using the Finite Difference Time Domain method with conforming elements, it gives fast and accurate results.

Includes:

Optimization Module 3D Geometric Modeler 2D Axi-Symmetric Geometries

Applications:

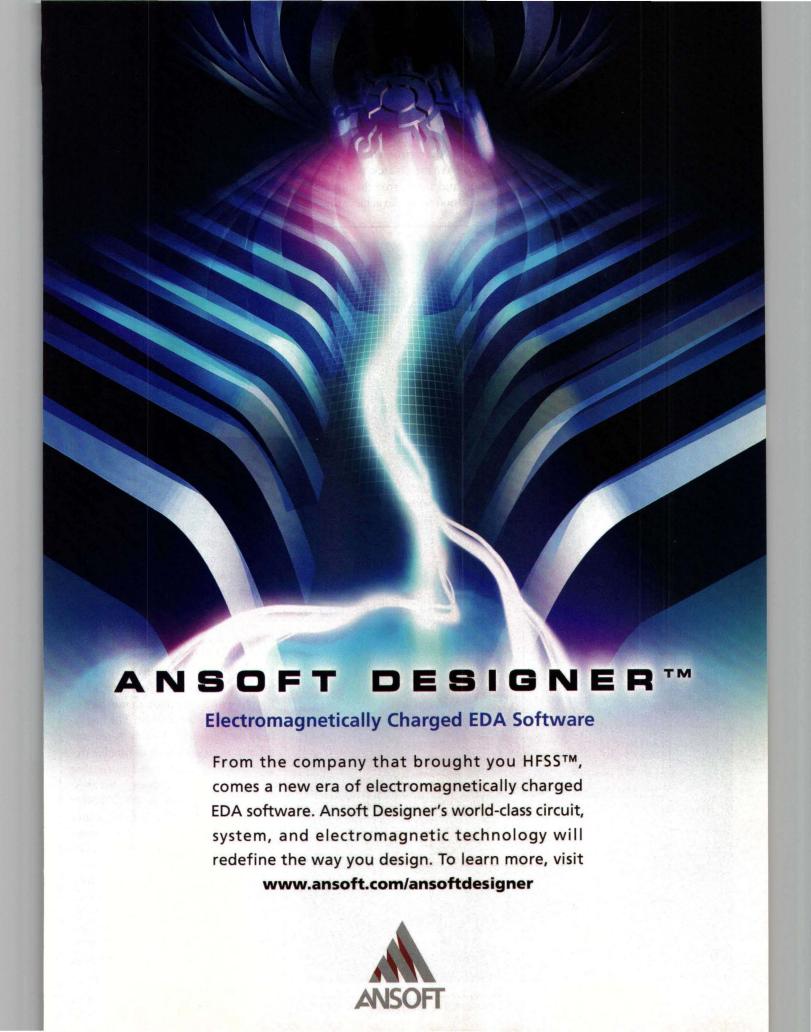
- Couplers, filters, junctions, polarizers
- Antennas
- Microwave power applications
- Resonators
- Plane wave scattering

Output Data:

- S-parameters versus frequency
- Input impedance versus frequency
- Eigenvalues
- Radiation patterns versus angle and radiation efficiency for multiple frequency
- Space distribution of electric and magnetic field, dissipated power, SAR

VF VECTOR FIELDS

1700 N. Farnsworth Avenue Aurora, IL 60505 USA
Tel: 630-851-1734 Fax: 630-851-2106 Email: info@vectorfields.com
Web: www.vectorfields.com



bit-rate parameter value.

The CNG Series employs the substitution method for establishing ratio accuracy, which relies on the accuracy of the noise attenuator and its resolution. The substitution method eliminates errors caused by power-measurement linearity. However, since accuracy is directly determined by the attenuator (perhaps the most critical component in the instrument), it is essential that it have the greatest possible resolution and least error throughout its attenuation range. To achieve this, dBm

created its own attenuator design, which has resolution of 0.016 dB, and is compensated in 1-MHz steps at every attenuation setting with a dedicated microprocessor. All attenuators are calibrated and verified over their range of operating frequencies and attenuation. This technique reduces resolution uncertainty to less than 0.008 dB and typical error to less than 0.02 dB.

Similar attention was paid to the internal power meter, which to reduce error must provide compensation for hardware inaccuracy over the full input power range. To eliminate this problem, the CNG Series instruments employ a dedicated microprocessor to provide the compensation, and the user can specify the sampling rate and number of samples. Signal-path gain is also well controlled. Input-to-output gain is typically better than 0 dB ±0.1 dB, and calibration is performed in 1-MHz steps over the instrument's frequency range.

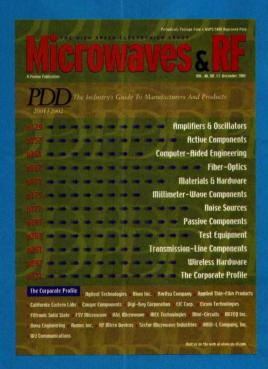
One of the largest contributors to error is mismatch uncertainty. While a return loss of 20 dB is more than adequate for most applications, it results in a mismatch uncertainty of nearly ±0.1 dB. Good matching and careful component selection in the CNG Series help achieve return losses in excess of 26 dB, reducing mismatch uncertainty to less than 0.02 dB.

Calibration of each instrument is fully automated and executed by a single program, and the procedure is performed with software-correction factors resident in the instrument. The instrument is calibrated in 1-MHz increments using a precision reference tunable frequency converter, which ensures that all power measurements are made at 50 MHz, the frequency at which power sensors are typically calibrated, eliminating power-meter uncertainty versus frequency. There are 65 calibration factors collected and stored for each 1 MHz of operating bandwidth, which translates into more than 8500 calibration points for a typical instrument. dBm Corp., 6 Highpoint Dr., Wayne, NI 07470; (973) 709-0020, FAX: (973) 709-1346, e-mail: info@dbmcorp.com, Internet: www.dbmcorp.com. MRF



Your Online Resource

For RF and Microwave
Products and Manufacturers

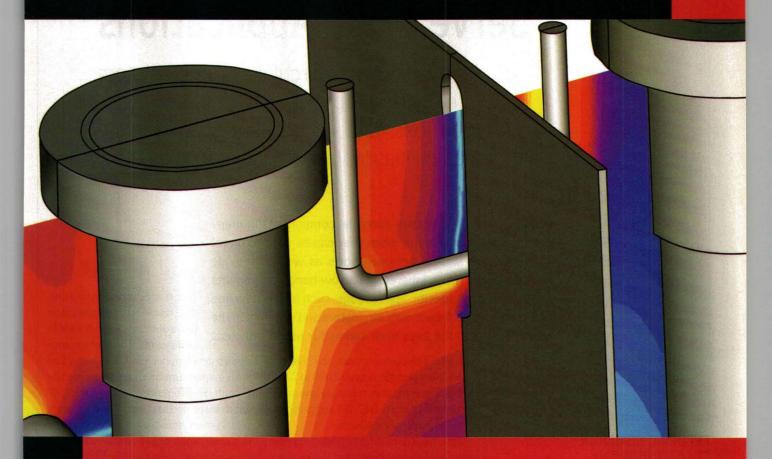


If you need a part, you'll find it at:

www.m-rf.com

Still trying, tuning, trying again?

3D EM Simulation



→ ... Prototyping and testing without simulating your design first can be very costly to your business. CST's virtual prototyping technology offers designers the benefit of mature parameterisation, parameter sweeps, and automatic optimisation which reduces cut-and-try iterations and so considerably speeds up time-to-market.

CST's award winning »STUDIO software family« is used world-wide by market leaders such as Motorola, Nokia, Philips, Raytheon, Siemens, and Sony. Typical applications include the simulation of antennas, coax and multipin connectors, couplers, LTCCs, MMIC packages, multiplexers, planar structures, power splitters, RLC-extraction, waveguides, and, of course, filters.

Connect yourself to CST's open design environment and experience the cutting edge of simulation technology. Get it right first time.

CST. CHANGING THE STANDARDS.

CST of America®, Inc.

To request literature or a free demo CD, @ 781-416-2782, or info: www.cst-world.com

CST
COMPUTER SIMULATION
TECHNOLOGY

Circulators/Isolators Serve UMTS Applications

These compact circulators and isolators are designed for high isolation, low insertion loss, and generous power-handling capabilities for UMTS base-station designs.

irculators and isolators are essential components in many communications systems, since they can be used to direct RF/microwave signals between ports as well as provide high isolation. These inherently narrow-band components are designed for specific applications, such as the new line of drop-in and surface-mount circulators and isolators in the NE3101 and NE1101 lines from Temex for use in Universal

Mobile Telecommunications System (UMTS) applications from 2080 to 2200 MHz. The components feature low intermodulation distortion (IMD) and generous power-handling capabilities.

The high data rates (2 MB/s) expected of UMTS translates into demanding specifications for communications system components such as circulators and isolators. For example, typical UMTS third-order IMD requirements are on the order of –80 to –90 dBc when measured with two test tones at about 28 W (+44.5 dBm) each.

The new drop-in circulators and isolators from Temex consist of a stripline center conductor sandwiched between two ferrite disks. The disks are placed between ground planes and magnetically biased by permanent magnets. Using electromagnetic (EM) simulation and analysis computer-aided-engineering (CAE) software, the structure is optimized for the best balance of isolation, loss, and IMD performance in the UMTS band from 2080 to 2200 MHz.

The EM simulations are backed by pre-

cision measurements using dual test sources to generate a two-tone test signal for IMD evaluations. The performance

of each device under test (DUT) is checked with a spectrum analyzer to gauge the amplitude differences between the CW test tone and the IMD tone. The company's test system achieves a spurious-free dynamic range of better than –120 dBc with two test tones of +44.5 dBm (28 W) each and a through-path calibration standard in place of the DUT, and IMD products below –90 dBc have been measured with the system.

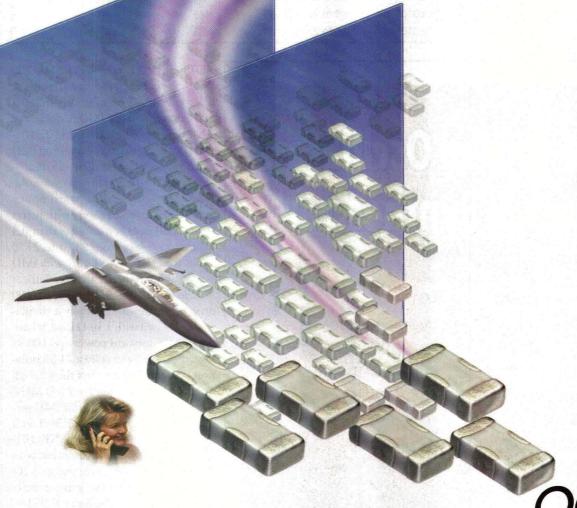
The new circulator/isolator lines feature five models operating at frequencies from 2080 to 2200 MHz (see table). These include circulator models NE3101-100 and NE3101-200 for use from 2080 to 2200 MHz, isolator model NE1101-300 for use from 2110 to 2170 MHz, attenuator model NE1101-200 for use from 2080 to 2200 MHz, and load model NE1101-100 for use from 2080 to 2200 MHz. All derive from the basic ferrite circulator architecture, with all but the model NE1101-300 capable of handling as much as 200 W CW forward power and at least 100 W CW reverse power. The other unit, drop-in isolator model

FREDERIC BEAUJOIN COLETTE RUINEAU BEAUDOIN TAMEN

Members of the Technical Staff

Temex, 399, route des Crêtes—06904 Sophia Antipolis Cedex, France; (33)(0)4 97 233 000, FAX: (33)(0)4 97 233 915, e-mail: info@temex.fr, Internet: www.temex.net. Low Pass & High Pass

LTCC FILTERS



Actual Size

DC to 6.3GHZ only

ea. atv. 1000

Deliver a wallop of very high rejection outside the passband and virtually eliminate PC board space demand using Mini-Circuits LFCN low pass filters and HFCN high pass filters! Choose from a broad range of models with plenty of cutting-edge features starting with a tiny 0.12"x 0.06" hermetically sealed package and an equally small price, so you can use them in a multitude of military and commercial applications without putting a strain on your budget. Toss in Low Temperature Co-fired Ceramic construction for superior temperature stability, excellent performance repeatability, and high power handling capability, and you've got a high-value low-cost solution designed to give you the edge - competitive or tactical!

system great using LFCN and HFCN filters.

Mini-Circuits...we're redefining what VALUE is all about!

LFCN-800 LFCN-900 DC-900 DC-1000 DC-1200 LFCN-1000 1700 LFCN-1200 1750 LFCN-1325 LFCN-1750 2325 LFCN-2000 LFCN-2400 3600 480 HECN-1200 1340-4800 1180 940 HFCN-1500 1700-6300

LFCN = Low Pass, HFCN = High Pass. Patent Pending. Price: \$1.99 ea. (Qty. 10)

New Blue Cell™ LTCC
164 Page Handbook...FREE!

Detailed Performance Data & Specs Online at: www.minicircuits.com/filter.html



P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 For quick access to product information see MINI-CIRCUITS CATALOG & WEB SITE

The Design Engineers Search Engine Provides ACTUAL Data Instantly From MINI-CIRCUITS At: www.minicircuits.com

ISO 9001 ISO 14001 CERTIFIED

393 Rev B-1

PRODUCT technology

NE1101-300, is designed for low-power applications where the reverse power does not exceed 1 W.

The models NE3101-100 and NE3101-200 circulators offer better than 21 dB isolation and less than 0.3 dB insertion loss from 2080 to 2200 MHz, each with

Ti	ie UMTS ci	rculators	isolators at a	a glance
MODEL	FREQUENCY RANGE (MHz)	ISOLATION (dB)	INSERTION LOSS (dB)	INTERMODULATION DISTORTION (IMD) (dBc)
NE1101-100	2080 to 2200	>21	<0.3	<-85
NE1101-200	2080 to 2200	>21	<0.3	<-85
NE1101-300	2110 to 2170	>23	<0.3	<-70
NE3101-100	2080 to 2200	>21	<0.3	<-70
NE3101-200	2080 to 2200	>21	<0.3	<-85



VSWR of 1.20:1. They are rated for 100 W CW power in the forward and reverse directions. The drop-in model NE3101-100 exhibits -70 dBc IMD performance while the surface-mount model NE3101-200 circulator achieves outstanding IMD performance of better than -85 dBc.

The NE1101-300 low-power isolator handles 10 W of forward power and 1 W of reverse power, with better than 23 dB isolation and less than 0.3 dB insertion loss from 2110 to 2170 MHz. It has VSWR of 1.15:1 with IMD performance of better than -70 dBc.

The low-IMD model NE1101-100 drop-in isolator is essentially a circulator terminated with a 50- Ω load. It handles 200 W forward power and 100 W reverse power, with at least 21 dB isolation (attenuation) and less than 0.3 dB insertion loss from 2080 to 2200 MHz. It achieves better than -85 dBc IMD performance with VSWR of 1.20:1 in a drop-in package. Similarly, the NE1101-200 is also a drop-in isolator, but with the terminated port connected to a 20or 30-dB attenuator for reverse power detection. The NE1101-200 drops IMD levels below -85 dBc while handling 200 W forward power and 100 W reverse power. Like the NE1101-100, it achieves better than 21 dB isolation with less than 0.3 dB insertion loss and 1.20:1 VSWR from 2080 to 2200 MHz.

The NE3101-100 circulator and the NE1101-300 isolator are each supplied in a 19.05 × 19.05-mm drop-in package while the NE3101-200 circulator is provided in a circular package with 19.05-mm diameter. The NE1101-100 and NE1101-200 isolators are housed in packages measuring 19.05 × 25.4 mm. Temex Electronics, Inc., 17235 N. 75th Ave., Suite G-100, Glendale, AZ 85308; (623) 780-1995, FAX: (623) 780-2431, e-mail: sales.usa@temex.fr, Internet: www.temex.net.

ATC RF/Microwave/Millimeter-wave Components & Packaging

RESISTORS • INDUCTORS • CAPACITORS



RESISTORS & TERMINATIONS

- High RF Power (2 to 250 Watts)
- 10 to 300 Ω
- DC to 18 GHz
- Low VSWR 1.1:1
- ATC Qualified @ DC and RF

MLC & SLC CAPACITORS

- 0.03 pF to 10 μF
- 10 to 7200 WVDC
- Low ESR
- High Self Resonance
- ATC Qualified @ DC and RF

ADVANCED SUBSTRATE PACKAGING

- Thin Film Circuit Fabrication Services
- Co-fired Ceramic Products (LTCC and HTCC)

WIRE WOUND INDUCTORS

- 1 to 4700 nH
- High Q
- High SRF
- Stable TCL
- EIA Case Sizes

DESIGN KITS

- Resistors, Inductors, Capacitors
- Over 50 Kits Online



AMERICAN TECHNICAL CERAMICS



ATC North America 631-622-4700 sales@atceramics.com

ATC Europe +46 8 6800410 sales@atceramics-europe.co ATC Asia +86-755-8399-5205 ales@atceramics-asia.com HE
ENGINEERS'
CHOICETM
ISO 9001 REGISTEREI

Third-Generation ICs Speed Bluetooth Integration

This series of single-chip solutions slashes the power and development time needed to include Bluetooth functionality into a wide range of portable products.

luetooth is finally reaching the million-piece volumes that members of the Bluetooth Special Interest Group (SIG) fore-saw more than five years ago. Some of the widespread acceptance is due to the diminishing costs of Bluetooth integrated circuits (ICs), and some is due to the availability of highly integrated solutions. In the case of latest Bluetooth ICs from Cambridge Silicon Radio (Cambridge,

received-signal-strength-indication (RSSI) function for real-time control.

Both Bluetooth ICs feature advanced baseband and logic circuitry that includes a memory management unit (MMU), burst-mode controller (BMC), 32 kB of random-access memory (RAM), 4 Mb of read-only memory (ROM), Universal Serial Bus (USB) and synchronous serial-port interfaces, universal asynchronous receiver transmitter (UART) interface, audio pulse-code-modulation (PCM) interface, and on-chip RISC microcontroller. Both ICs have an on-chip linear regulator that produces +1.8 VDC when supplied with +2.2- to +4.2-VDC inputs.

The BlueCore3-Multimedia chip is available in a 10 × 10-mm, 96-ball LFBGA package. The BlueCore3-ROM solution can be supplied in a 4 × 4-mm chip-scale package (CSP) as well as in RF Plug & Go and ball-grid-array (BGA) packages. The RF Plug & Go package integrates impedance-matching circuitry for connection to an antenna. Cambridge Silicon Radio, Cambridge Science Park, Milton Rd., Cambridge CB4 0WH, England; (44) (0) 1223-692-000, FAX: (44) (0) 1223-692-001, e-mail: sales@csr.com, Internet: www.csr.com.

JACK BROWNE
Publisher/Editor

England), both factors apply. The company's BlueCore3 family of products represents a third-generation (3G) development, fully compliant with the latest version of the Bluetooth standard (Version 1.2) and designed for low-power operation at +1.8 VDC.

The BlueCore3 family represents the first complete implementation of the 2.4-GHz Bluetooth Version 1.2 standard. The new ICs include the BlueCore3-Multimedia chip and the BlueCore3-ROM chip. The former includes user-programmable digital-signal-processing (DSP) circuitry while the latter is designed to be a lower-power replacement for the company's second-generation (2G) BlueCore2-ROM chip (using 18 percent less power than its predecessor).

Both Bluetooth radio ICs are designed to provide as much as +6-dBm transmitter power with an on-chip 6-b digital-to-analog converter (DAC) for 30-dB dynamic power control. The on-chip receiver (which operates in a near-zero-IF mode) features integrated channel filters digital demodulator, and digitized

RF TRANSFORMERS



3-2500MHz as low as 99 each (qty

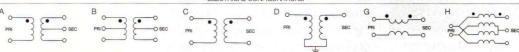
It used to be that small RF transformers with high end performance cost a lot, but not since Mini-Circuits introduced the all ceramic leadless TC and high strength plastic leaded TCM families. Now you can get impedance ratios from 0.1:1 to 16:1 ohms with good return loss and broad bandwidths from 0.3 to 2500MHz at price buster values. Plus, these ultra-small performers are all-welded and have solder plated leads for high reliability and solderability, excellently suited for your automated pick-and-place assembly operations. So have it both ways; high performance AND low price with Mini-Circuits TC and TCM surface mount transformers.

Detailed Performance Data & Specs Online at: www.minicircuits.com/model

S LI	EADLESS (Deramic Bas	е		LE	ADS Plas	tic Base		
(actual size) MODEL	Ω Ratio & Config.	Freq. (MHz)	Ins. Loss* 1dB (MHz)	Price \$ea. (qty. 100)		Ω Ratio & Config.	Freq. (MHz)	Ins. Loss* 1dB (MHz)	Price \$ea. (qty. 100)
TC1-1T TC1-1 TC1-15	1A 1C 1C	0.4-500 1.5-500 800-1500	1-100 5-350 800-1500	1.19 1.19 1.29	TCM1-1 TCML1-11 TCML1-19	1C 1G 1G	1.5-500 600-1100 800-1900	5-350 700-1000 900-1400	.99 1.09 1.09
TC1.5-1 TC2-1T TC3-1T	1.5D 2A 3A	.5-2200 3-300 5-300	2-1100 3-300 5-300	1.59 1.29 1.29	TCM2-1T TCM3-1T	2A 3A	3-300 2-500	3-300 5-300	1.09
TC4-1T TC4-1W TC4-14	4A 4A 4A	.5-300 3-800 200-1400	1.5-100 10-100 800-1100	1.19 1.19 1.29	TTCM4-4 TCM4-1W TCM4-6T	4B 4A 4A	0.5-400 3-800 1.5-600	5-100 10-100 3-350	1.29 .99 1.19
TC8-1 TC9-1	8A 9A	2-500 2-200	10-100 5-40	1.19 1.29	TCM4-14 TCM4-19 TCM4-25	4A 4H 4H	200-1400 10-1900 500-2500	800-1000 30-700 750-1200	1.09 1.09 1.09
TC16-1T TC4-11 TC9-1-75	16A 50/12.5D 75/8D	20-300 2-1100 0.3-475	50-150 5-700 0.9-370	1.59 1.59 1.59	TCM8-1 TCM9-1	8A 9A	2-500 2-280	10-100 5-100	.99 1.19

Dimensions (LxW): TC .15" x .15" TCM .15" x .16" Referenced to midband loss.

ELECTRICAL CONFIGURATIONS



Mini-Circuits®

P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 For quick access to product information see MINI-CIRCUITS CATALOG & WEB SITE

The Design Engineers Search Engine Provides ACTUAL Data Instantly From MINI-CIRCUITS At: www.minicircuits.com

Engineered Substrates Yield High Stability

A proprietary covalent bonding process attaches die to substrates and substrates to carriers at room temperature, clearing the way for a new generation of temperature-stable components.

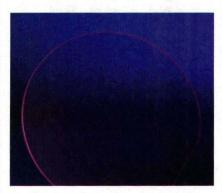
emperature stability is a key to the successful integration of numerous components, including filters and resonators, in wireless and other designs. For example, surface-acoustic-wave (SAW) devices offer superb selectivity, although with performance highly dependent on temperature. For this reason, some designers have sought filters based on alternative technologies, such as larger ceramic filters or

ic-wafer-bonding processes, the ZiROC process is performed at room temperature to create low-stress bonds and

materials with minimum defects and low thermal resistance. The process can bond materials with different coefficients of thermal expansion (CTE), supports standard through-bond processing, and enables multilayer circuitry using a threedimensional interconnect topology.

The company has applied its revolutionary process to create a "standard" line of substrates aimed at developers of SAW filters and oscillators (see figure). Each of these temperature-compensated SAW substrates is actually a wafer pair consisting of a low-cost piezoelectric material, such as lithium tantalite and lithium niobate, bonded to glass, quartz, or other base wafer with low CTE. The resulting engineered wafer exhibits the electrical properties of the piezoelectric top wafer layer with the thermal stability of the base substrate. These new materials will enable designers to create temperature-stable piezoelectric-based components for a variety of functions in communications systems, including resonators, oscillators, and filters. Ziptronix, Inc., Research Triangle Park, NC; Internet: www.ziptronix.com.

JACK BROWNE
Publisher/Editor



The first line of engineered substrates from Ziptronix includes glass- or quartz-bonded piezoelectric wafers for low-cost, temperature-stable SAW devices.

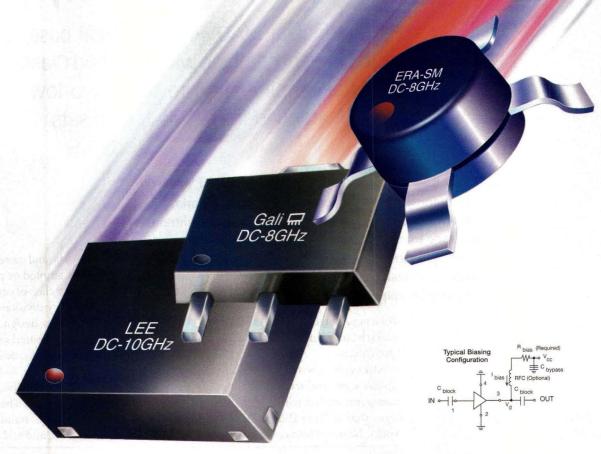
more expensive film-bulk acoustic resonator (FBAR) devices. Fortunately, for those in need of the small size, low cost, and high performance of SAW filters (and resonators), Ziptronix (Research Triangle Park, NC) provides a solution in the form of engineered substrates: the company's unique, covalent bonding process yields piezoelectric and other substrates that can be bonded to carriers such as glass for enhanced temperature stability.

Founded in 2000, the company uses its proprietary ZiROCTM covalent bonding technology at room temperature to perform wafer-to-wafer bonding and die-to-wafer bonding on 4-to-8-in. wafers. The covalent bonding process includes precise polishing of the materials to be bonded to form two materials into one with high bond energy between the two material components. The non-adhesive process is performed at room temperature, without the high processing temperatures that can be destructive to some sensitive semiconductor die and surfacemount components.

Compared to fusion-bonding or anod-

MMIC AMPLIFIERS

DC-10GHz as low as 99¢ ea. (qty. 30)



GAIN FROM 8 up to 23dB, OUTPUT POWER up to +20dBm

If you need to find a MMIC amplifier with just the right performance and size to fit your design, your job just got easier! Introducing Mini-Circuits LEE, Gali, and ERA-SM families. Now you can select from a variety of over 40 broadband InGaP HBT and low noise silicon based models with flat gain from 8 up to 23dB, low to high output power of +2.8 to +20dBm, and very high IP3 up to 36dBm typical. These affordable, rugged, compact amplifiers have low thermal resistance for high reliability, and come in three different

Detailed Performance Data & Specs Online at: www.minicircuits.com/amplifier.html

package styles to suit your design layout requirements; the leadless 3x3mm "Mini-Circuits Low Profile" (MCLPTM) package with exposed metal bottom for superior grounding and heat dissipation,

plus the SOT-89 and Plastic Micro-X with leads for easier assembly. You'll find all the performance specs and data on our web site, plus a wide selection of amplifier Designer's Kits with free test fixture included! So broaden your MMIC amplifier choices and maximize performance with Mini-Circuits LEE, Gali, and ERA-SM.

Mini-Circuits...we're redefining what VALUE is all about!

Actual Size









P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 For quick access to product information see MINI-CIRCUITS CATALOG & WEB SITE

The Design Engineers Search Engine Provides ACTUAL Data Instantly From MINI-CIRCUITS At: www.minicircuits.com

New Supplier Debuts Innovative WLAN Chips

Power-efficient MAC, RF, and digital baseband circuitry combine with switched Class F power amplification to form two lowpower, extended-range WLAN chip sets.

f it is true that one day the last shall be first, then the designers at IceFyre Semiconductor (Kanata, Ontario, Canada) have an edge. The company, a relatively late entrant in the race for wireless-local-area-network (WLAN) market share, has joined the competition in a big way, sampling its high-performance SureFyre™ 802.11a and TwinFyre™ 802.11a/b/g chip sets with promises of improved power

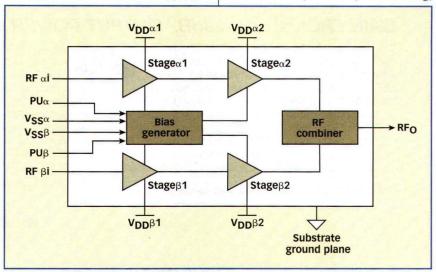
efficiency, range, and sensitivity, particularly for demanding multimedia applications.

Although new to the market, the fabless semiconductor firm boasts a management team with impressive lineages that include IBM, Nortel Networks, National Semiconductor, Inter-

power sil, and Nokia, and more than 31 patents granted or pending for a new class of orthogonal-frequency-division-multiplexing (OFDM) radio design. The

company's first two integrated-circuit (IC) sets are the SureFyre family, designed to support the 5-GHz IEEE 802.11a standard for bit rates to 54 Mb/s, and the TwinFyre family, which can be used for the three leading WLAN standards, IEEE 802.11a, 802.11b, and 802.11g,

JACK BROWNE Publisher/Editor



The ICE5352 OFDM power amplifier employs two active GaAs PHEMT stages and a patented Chireix combiner to reach new levels of efficiency at 5 GHz.

Super Fast Very High Isolation

SWITCHES



Mini-Circuits wideband SPDT switches offer very high isolation up to 90dB at 1GHz, built-in TTL driver with blazing fast 10nsec switching speed, and the ability to withstand severe operating temperatures ranging from -40°C to +85°C. But that's not all! Reflective and absorptive models are available to suit your design requirements; M3SW's 3x3mm MCLPTM surface mount package with exposed metal bottom for excellent grounding and heat dissipation and ZASW's tough built coaxial design with SMA-F connectors. No matter which model you choose, you'll get strong performance and rugged reliability at a price that crushes the competition. So look no further. You'll find just the right switch for your commercial, industrial, or military application right here at Mini-Circuits!

Mini-Circuits...we're redefining what VALUE is all about!

SPECIFICATIONS (@ 1GHz)

	Model	Freq. (GHz)	In-Out Isol. dB(typ)	Ins. Loss dB(typ)	1dB Comp. dBm(typ)	Price \$ea. (Qty. 10)
	M3SW-2-50DR M3SWA-2-50DR	DC-4.5 DC-4.5	60 65	0.7 0.7	25 25	4.95 * 4.95 *
	ZASW-2-50DR ZASWA-2-50DR	DC-5 DC-5	90 90	1.7	20	(Qty. 1-9) 89.95 89.95
•	Supply voltage +5V Switching time 10n Reflective Abso	sec (typ).	_ control.		3x3mm Mini-Circuits Low Profile (MCLI	

Detailed Performance Data & Specs Online at: www.minicircuits.com/model



P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 For quick access to product information see MINI-CIRCUITS CATALOG & WEB SITE

The Design Engineers Search Engine Provides ACTUAL Data Instantly From MINI-CIRCUITS At: www.minicircuits.com

ISO 9001 ISO 14001 CERTIFIED

379 Rev G

PRODUCT _______

at both 2.4 and 5 GHz.

The SureFyre system is comprised of three chips: the ICE5351 802.11a combination baseband processor and RF radio IC, the ICE5125 802.11 general-purpose media-access-controller (MAC) IC, and the ICE5352 power-amplifier

(PA) IC. The SureFyre chip set supports WLAN designs from 4.90 to 5.85 GHz using OFDM modulation, and can achieve high transmit power levels (and improved range) with reduced power consumption compared to competing 802.11b solutions. The first two

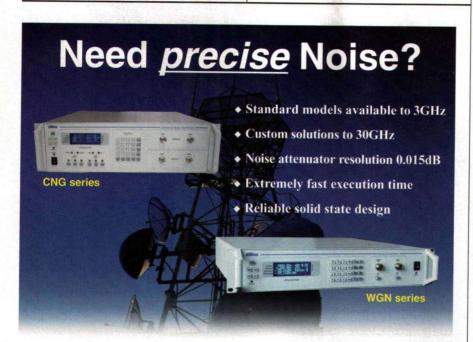
chips are fabricated with an 0.18-µm RFCMOS silicon process while the PA is fabricated with GaAs. The chips combine to achieve more than 200 mW transmitter average RMS output power and receiver sensitivity that exceeds the 802.11a standard by as much as 10 dB. The system error-vector-magnitude (EVM) performance is 2 dB better than the 802.11a requirement, and the system-level noise figure is less than 8 dB. System power consumption is extremely low at 1015 mW for 100 mW EIPR. Of note for multimedia system designers, the delay spread for the SureFyre

The chip set's individual components include the ICE5351, which combines low-power differential RF circuitry and the digital baseband

system is an almost-negligible 150 ns.

The SureFyre chip set can achieve high transmit power levels (and improved range) with reduced power consumption compared to competing solutions.

architecture on the same device. The integrated partitioning is well suited for support of proprietary MACs and embedded host-based MAC platforms, in contrast to the limitations of chips that integrate a baseband processor with the MAC. The ICE5351 can handle data rates of 6, 9, 12, 18, 24, 36, 48, and 54 Mb/s. It employs unique algorithms to limit the peak-to-average power ratio (PAPR) of OFDM signals (maintaining a constant amplitude envelope) for maximum efficiency when used with the ICE5352 PA. Its receiver architecture does not require an external intermediate-frequency (IF) filter or baseband filter components, yet achieves receive sensitivity is -89 dBm at 6 Mb/s and -70 dBm at 54 Mb/s. The ICE5351 includes an automatic-gaincontrol (AGC) circuit with 0-to-70-dB range, and a transmit-power-control range of better than 20 dB. The nique



Give us a call to discuss your Noise Generator needs...

CNG Series

The CNG series allows carrier to noise (C/N) or carrier to interference (C/I) ratios to be easily programmed in a user specified occupied signal bandwidth. The instrument can automatically track and remove signal variations to maintain a precise noise ratio. At the heart of the instrument is a temperature stabilized "smart" noise attenuator with 0.015dB resolution and 95dB dynamic range.

Carrier/Noise (CNG) Series				
Model	Frequency range			
CNG-26/180	26MHz - 180MHz			
CNG-70/140	50MHz - 180MHz			
CNG-800/1000	800MHz - 1000MHz			
CNG-870/1750	870MHz - 1750MHz			
CNG-800/2400	800MHz - 2400MHz			
CNG-1700/2400	1700MHz - 2400MHz			
CNG-2200/2700	2200MHz - 2700MHz			
CNG-800/2700	800MHz - 2700MHz			

dillim, LLC

6 Highpoint Drive • Wayne, NJ 07470 Tel (973) 709-0020 • Fax (973) 709-1346

www.dbmcorp.com

WGN Series

The WGN series is a cost effective, highly accurate Additive White Gaussian Noise generator with a oven stabilized noise source (with high crest factor) and a precision temperature stabilized noise attenuator. It is ideally suited for noise applications requiring extremely accurate and repeatable White Gaussian Noise.

Broadband Noise (WGN) Series					
Model	Frequency range				
WGN-1/200	1MHz - 200MHz				
WGN-5/1005	5MHz - 1005MHz				
WGN-800/1000	800MHz - 1000MHz				
WGN-870/1750	870MHz - 1750MHz				
WGN-800/2400	800MHz - 2400MHz				
WGN-100/3000	100MHz - 3000MHz				

Please consult factory for additional models



RF Test Equipment for Wireless Communications

PRODUCT _______

AGC circuitry is capable of settling in a few short symbols, giving the receiver unprecedented response time and enhanced efficiency. The IC shaves peak transmit power consumption to less than 570 mW and achieves transmit EVM of -27 dB at all data rates and output power levels. The ICE5351 is supplied in a $15 \times 15 \times 1.6$ -mm low-profile fine-pitch ball-grid-array (LFBGA) housing.

The ICE5125 802.11 MAC is compliant with 802.11a, b, and g standards. The IC includes a 32-b bus master DMA controller to transfer data to and from the system memory, minimizing the load on the host central-processing unit (CPU). The MAC supports a variety of security methods as well as 64- and 128-b encryption keys.

The ICE5352 GaAs
PHEMT amplifier is
unique among WLAN
PAs, employing efficient
Class F switch-mode
technology along with
Chireix combiners.

For 802.11a/g, it support data rates of 6, 9, 12, 18, 24, 36, 48, and 54 Mb/s, while for 802.11b, it supports data rates of 1.0,2.5, 5.0, and 11.0 Mb/s. It supports automatic rate switching to adapt to different link conditions. It features on-chip packet buffers, supports dynamic frequency selection and transmit-power-control functions, and includes Windows 2000, Windows XP, and Linux 2.4 drivers. The ICE5125 is supplied in a 12 × 12 × 1.4-mm LFBGA housing.

The cornerstone of the SureFyre collection, the ICE5352 gallium-arsenide (GaAs) pseudomorphic-high-electron-mobility-transistor (PHEMT) amplifier is optimized for use from 5.15 to 5.35 GHz and is first in a family of PAs covering the global 4.9-to-5.85-GHz band. It is unique among WLAN PAs, employing efficient Class F switch-mode technology along with patented

low-loss Chireix signal combiners (see figure). The result of this novel technology is an amplifier capable of delivering 125 mW (+21 dBm) output power with 35-percent power-added-efficiency (PAE) for IEEE 802.11a applications, or 200 mW (+23 dBm) output power

with 31-percent PAE. The amplifier can provide continuously variable output-power levels from +2 to +23 dBm (by varying the DC supply voltage from +0.5 to +7.0 VDC), and achieves system-level transmit modulation accuracy (EVM performance) of -27 dB at a



PRODUCT technology

data rate of 54 Mb/s. The amplifier consumes only 360 mW power when generating +21 dBm output power and only 250 mW power when generating +19 dBm output power. The ICE5352 PA is supplied in an 8 × 8-mm, 15-pin ceramic-leadless-chip-carrier (CLCC) package.

For developers working on multiple-WLAN-standard solutions, the TwinFyre™ 802.11a/b/g system handles the three leading WLAN standards at both 2.4 and 5 GHz. The chip set consists of the ICE2501 802.11b/g RF IC, the ICE5825 802.11a IC with baseband processor, the ICE5125 802.11 MAC, and the ICE5352 PA. The system is ideal for partner-provided commodity 2.4-GHz radios and third-party MAC solutions, with strong support for IEEE 802.11b and IEEE 802.11g.

The TwinFyre chip set basically adds 802.1b and 802.11g capabilities to the 802.11a performance of the SureFyre

system, with as much as +17 and +22 dBm output power while working in 802.11b and 802.11g operation modes, respectively. The TwinFyre system offers 10 dB better receive sensitivity than the 802.11b/g specifications.

Both the SureFyre and TwinFyre chip sets benefit from innovative technology, including TrueSygnal™ per packet equalization and decode processing, which provides equalization of all carriers in the presence of fading and dynamic-channel-quality assessment to select optimal channels in the presence of interference while optimizing output power levels. Working with a Viterbi decoder, the TrueSygnal approach uses equalization results (channel state information) to optimize the decoding process based on the quality of the receive carrier signals. The IcePick™ per packet antenna diversity provides as much as 10 dB additional gain in receiver sensitivity, especially in multipath environments. Another feature offered is Transmit per Packet Power Control (TPPC), which provides for dynamic interference avoidance, whereby the transmitted power of each OFDM packet is adjusted for optimal AP-STA performance, but minimal RF network interference.

The ICE5351 and ICE5352 ICs are currently available in sample quantities as part of the ICE5300A-EVK evaluation kit, while the ICE5125 is sampling as part of the ICE5100A-EVK evaluation kit. SureFyre-based Mini-PCI reference designs will be available during the last quarter of 2003. The TwinFyre chip set will begin sampling in the second quarter of 2004, with volume production expected by the third quarter of 3004. IceFyre Semiconductor Corp., 300-411 Legget Dr., Kanata, Ontario K2K 3C9, Canada; (613) 599-3000, FAX: (613) 599-4965, Internet: www. IceFvre.com.

LASER ACCURATE RECRUITING MICROWAVES

FOCUSED ON CONNECTING INDUSTRY PROFESSIONALS AND EMPLOYERS, mesmatch.com uses the most advanced profiling and matching technology available to ensure that employers find the talent they need and candidates find the opportunity that's right for them.

As a partner in the Defense Talent Network, mesmatch.com provides employers with access to an extensive pool of industry specific talent. The matching features allow powerfully precise recruiting from the widest possible talent pool.

Mesmatch.com exposes candidates to opportunities throughout the Defense Talent Network and offers them Ultimate Candidate Confidentiality, the most advanced privacy levels available.

Representing the evolution of on-line recruiting and career advancement, Candidates using mesmatch.com:

- Select the level of Candidate Confidentiality that's right for them
- •Identify job opportunities that match their profile
- •Implement automated job-search agents
- Monitor employer interest in their profile

Microwaves & RF, the leading publication for the military and aerospace electronics industry, has created MESMATCH.com, an on-line career site as innovative as the industry itself.

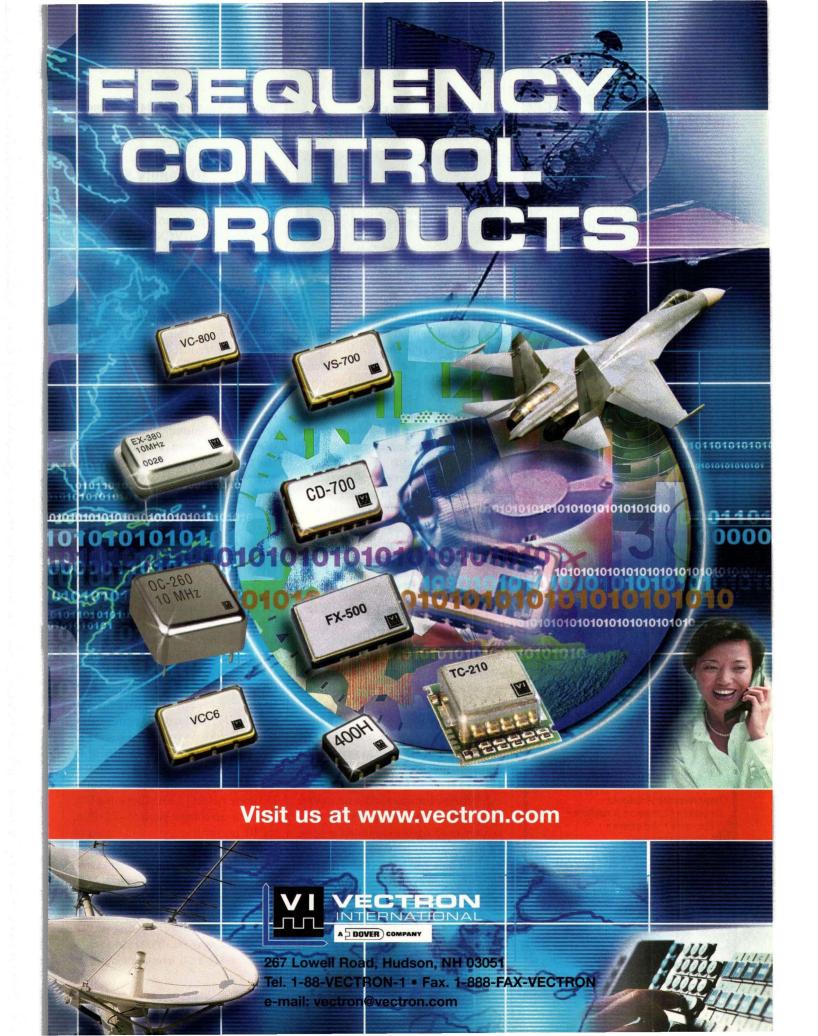
Employers using mesmatch.com:

- Get the information they need to assess candidate suitability
- Have access to candidate profiles unrivalled in their precision and scope
- Automatically filter out unqualified candidates
- Pinpoint with laser accuracy the best matches for their job opportunities
- Compare and rank candidates (tables, charts etc.)

Employers can take advantage of our introductory offer and post 6 job opportunities on mesmatch.com for FREE.

Candidates register FREE and have the perfect opportunity find you!







Other Herotek Products: Detectors • Limiters • Amplifiers •

Subassemblies

Herotek, Inc.

155 Baytech Drive

San Jose, CA 95134

Tel: (408) 941-8399

Fax: (408) 941-8388

Email: info@herotek.com

Website: www.herotek.com

Switches • Multipliers •

Herotek

The microwave

products source

new products

UMTS Radio Tester Reduces Costs



THE R&S CMU300 FACILITATES the introduction of UMTS. It reduces the costs per channel in production and allows function-reliable installation of the UMTS network, R&S CMU300s already used with GSM or EDGE can be expanded by UMTS. The R&S CMU300 is suited for mass production since it provides transmitter and receiver measurements in a single instrument of compact dimensions.

Rohde & Schwarz GmbH & Co. KG. Mühldorfstr, 15, D-81671 Munich, Germany; +49 89 4129-13779, FAX: +49 89 4129-13777, e-mail: customersupport@ rsd.rohde-schwarz.com, Internet: www.rohde-schwarz.com.

Demodulators Simplify Radio Design

TWO NEW DIRECT-CONVERSION quadrature demodulators simplify radio design for cellular base stations and microwave and satellite links. The LT5515 and LT5516 direct-conversion quadrature demodulators provide high linearity, providing more flexible system design and wide spur-free dynamic range. The LT5515 and LT5516 have applications in cellular infrastructure and in microwave and satellite links, where they directly convert an RF signal to baseband in-phase (I) and quadrature-phase (Q) components. The LT5515 operates over an input frequency range of 1.5 to 2.5 GHz, and the LT5516 operates with RF input from 0.8 to 1.5 GHz. The LT5515 and LT5516 are offered in 4 × 4-mm QFN packages. P&A: \$6.75 [LT5515] and \$7.40 [LT5516] (1000 qty.).

Linear Technology Corp., 1630 McCarthy

Blvd., Milpitas, CA 95035-7417; Internet: www.linear.com

Small VCXO Family Suits PLL Applications

THE V71 FAMILY OF voltage-controlled crystal oscillators (VCXOs) offers design engineers the industry's smallest VCXO. Hermetically sealed in a 3.2×5.0 -mm package, this HCMOS VCXO is available in either 3.3- or 5-V versions with a pull range of ±100 ppm minimum. Stabilities are available at ±50 and ±100 ppm, with frequencies from 2 to 52 MHz. This family of VCXO oscillators is designed for phase-locked-loop (PLL) applications requiring low jitter and tight stability. P&A: \$3.95 (5000 qty.); 8 wks. lead time.

Connor-Winfield Corp., 2111 Comprehensive Dr., Aurora, IL 60505; (630) 851-4722, FAX: (630) 851-5040, e-mail: info@ conwin.com, Internet: www.conwin.com.

Mixer Offers +32-dBm IIP3 For GSM/CDMA 450 Infrastructure

AN MMIC MIXER ACHIEVES up to +32-dBm input IP3 for GSM and CDMA 450- and 480-MHz infrastructure applications. The HMC387MS8 is a high-dynamicrange passive MMIC mixer in a plastic surface-mount 8-lead Mini Small Outline Package (MSOP) covering 450 to 500 MHz RF. Input IP3 performance of +32 dBm for downconversion and +29 dBm for upconversion is provided at an LO drive of +17 dBm. The mixer also has performance with as little as +13 dBm LO drive yielding a +30 dBm input IP3. With a 1-dB compression of +22 dBm, the RF port will accept a wide range of input signal levels. The DC-to-150-MHz IF frequency response will satisfy many cellular transmit or receive frequency plans. P&A: Sample and production quantities are available. Hittite Microwave Corp., 12 Elizabeth Dr., Chelmsford, MA 01824; (978) 250-3343, FAX: (978) 250-3373, Internet: www. hittite.com.

WORLD'S SMALLEST DIRECTIONAL COUPLERS

9 to 20dB... Immediate Delivery



\$199 only each (qty.25)

The DBTC series from Mini-Circuits is quite simply the smallest, *lowest priced* 5 to 2000MHz directional coupler series on Earth! Available in 9 to 20dB nominal coupling values, these patented 50&75 ohm couplers integrate Blue Cell™ design techniques for *very flat coupling*, low insertion loss, and multi-decade *broad bandwidths*. All-welded connections improve reliability, and automated production delivers high unit-to-unit performance repeatability. Plus, Mini-Circuits low price of only \$1.99 each (qty. 25) gets even lower with higher quantities! So, preserve precious board space, and capital as well. Specify Mini-Circuits DBTC directional couplers.

CUSTOM PRODUCT NEEDS...Let Our Experience Work For You.

BLUE CELL

Protected by U.S. Patent 6140887. Additional patents pending.

DBTC SPECIFICATIONS

Coupling 9dB 10dB 12dB 13dB	Model DBTC-9-4 DBTC-10-4-75 DBTC-12-4 DBTC-13-4	Freq. (MHz) 5-1000 5-1000 5-1000	Ins. Loss (dB) Midband Typ 1.2 1.4 0.7 0.7	Directivity (dB Midband Typ 18 20 21 18
13dB	DBTC-13-5-75	5-1000 1000-1500	1.0 1.4	19 17
16dB	DBTC-16-5-75	5-1000 1000-1500	1.0 1.3	21 19
17dB	DBTC-17-5	50-1000 1000-1500 1500-2000	0.9 1.0 1.1	20 20 14
18dB 20dB Dimens	DBTC-18-4-75 DBTC-20-4 sions 0.15" squa	5-1000 20-1000 are.	0.8 0.4	21 21

DESIGNER'S KITS

K1-DBTC (50 Ohms) 5 of ea. DBTC-9-4, 12-4, 13-4, 17-5, 20-4. Total 25 Units \$49.95 K2-DBTC (75 Ohms) 5 of ea. DBTC-10-4-75, 13-5-75, 16-5-75, 18-4-75. Total 20 Units \$39.95

For detailed specs visit: www.minicircuits.com/dcoupler.html

We're redefining what VALUE is all about!



P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 For quick access to product information see MINI-CIRCUITS CATALOG & WEB SITE

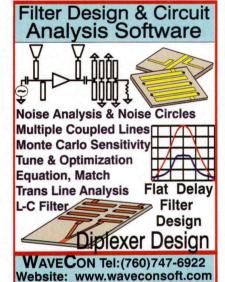
The Design Engineers Search Engine Provides ACTUAL Data Instantly From MINI-CIRCUITS At: www.minicircuits.com

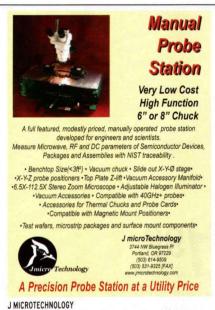
MICROWAVES & RF DIRECT CONNECTION ADS

TO ADVERTISE, CALL JOANNE REPPAS (201) 666-6698



T & C POWER CONVERSION

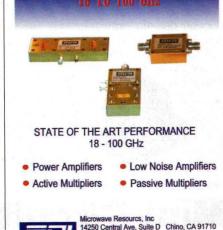




WAVECON



AVIEL ELECTRONICS 5530 South Valley View Ste. 103 Las Vegas, Nevada 89118 Tel: 702-739-8155 Fax: 702-739-8161 http://www.engineers.com/ aviel/home.htm



AMPLIFIERS AND MULTIPLIERS

MICROWAVE RESOURCES

Your Online Resource

For RF and Microwave **Products and Manufacturers**

Electronic engineers typically create designs that require hundreds and, sometimes, thousands of different components from a wide range of suppliers. Finding the optimum components for a design from a reliable vendor can be an exercise in futility without the proper research tools. And one of the most important reference sources is the online version of the Microwaves & RF Product Data Directory, at www.m-rf.com.

This powerful website and search engine offers thousands of high-frequency manufacturers, searchable by means of more than 500 different product categories, from amplifiers to wire. The site provides access to names, addresses, telephone numbers, FAX numbers, e-mail addresses, and even provides active links to key suppliers.

Take a few minutes to set up your user file at www.m-rf.com. After that, you'll be able to log on in second by just entering your telephone number. While you're on the site, don't forget to check out the more than 500 New Product listings, with key specifications for everything from systems to semiconductors.

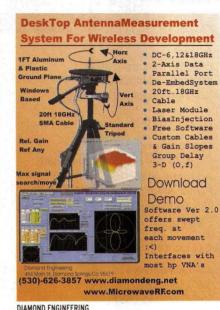
If you need a part, you'll find it at:

www.m-rf.com

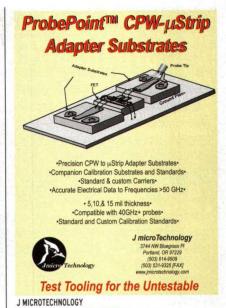
Tel: (909) 627-4125 Fax: (909)627-4295

MICROWAVES & RF DIRECT CONNECTION ADS

TO ADVERTISE, CALL JOANNE REPPAS (201) 666-6698







SECTOR MICROWAVES



COMPACT DROS AND PHASE LOCKED DROs OPERATE AT FREQUENCIES FROM 3.3 TO 14 GHz OVER -54 TO +85°C

Mechanical tuning range 4%

Power output +15 dBm min. Reference input frequency 10-150 MHz Power Supply: $+12 \text{ or } +15 \pm 1 \text{VDC}$ @ 75mA

RESOTECH ALSO OFFERS FERRITE CIR-CULATORS AND ISOLATORS FROM 50 MHz TO 100 GHz

RESOTECH, INC. 13610 N. Scottsdale Rd., #10-233 Scottsdale, AZ 85254 Tel: (480) 483-8400 Fax: (480) 483-2504

www.resotechinc.com

RESOTECH, INC.

SP16T Pin-Diode Switch (0.5-18 Ghz)

UMCC's Model SR-U010-16S is an absorptive sinteen-throw solid state switch operating over 0.5-16 Ghz. Switch features: 7.0 dB loss / 60dB location at 18 Ghz, 21 VSWR, 25ns ReserFall time, 40-12 VDC Supples, CMCS or TTL controls, all removable connections. Unit measures 1.5 ° 2.6 V 4.0-4.

- Solid State Variable Attenuators
 DC-Blocks, Bias Tee's, Transford
 Directional Couplers
 Hybrid Couplers (90°/180°)
 Power Dividers / Combiners

- Solid State Switches

Special Function Subsyst

Universal Microwave Components Corporation

5702-D General Washington Drive Alexandria, Virginia 22312 Tel: (703) 642-6332, Fax: (703) 642-2568 Email: UMCC@ UMCC111.Com Web: www.umcc111.com

UNIVERSAL MICROWAVE



POLYFET RF DEVICES

SAW FILTERS
AEC Ltd. & SAW Electronic Solutions

Choose your filter from our catalogue @ http://on.wplus.net/aec/

Hundreds SAWs to choose from:

SAW filters

Telecommunication, CATV & SATV, general purpose, Delay lines

Chirp devices, PSK delay lines, VCO delay lines

Resonators for VCOs **GPS/GLONASS SAWs**

- We deliver your custom designed SAW samples in just a couple of weeks
- We have minimum or no design charges
- We offer extremely competitive prices
- We ship high or low quantity product

Please contact our expert service at SES (SAW Electronic Solutions) Tel. (USA) 770-569-7308, Voice mail/Fax 770-360-8292

E-mail ses4@comcast.net, or visit our catalogue @ http://on.wplus.net/aec/

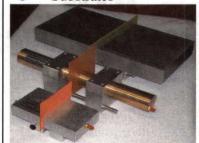


ADVANCED SAW FILTERS

SAW ELECTRONIC SOLUTIONS

THIN SHEET TESTERS

- Circuit Boards
- Radome Skins
- Substrates



- ε , tan δ / Dk, Df
- 100 MHz 12 GHz

www.damaskosinc.com

(610)358-0200 fax(610)558-1019

MINIATURE RF AMPLIFIERS FREQ Ranges (MHz): 1-500, .1-150, .4-300, .005-100, 1-1000 15, 20 or 30 dB available (not in all ranges) VSWR: 1.5:1 max, 1.1:1 Typical FLATNESS: ± 1 dB or better depending on Freg. range WIDE BAND ENGINEERING CO, INC.

www.wbecoinc.com P.O. Box 21652, Phoenix, AZ 85036 Phone & Fax (602) 254-1570 WIDE BAND ENGINEERING

MICROWAVES & RF DIRECT CONNECTION ADS TO ADVERTISE, CALL JOANNE REPPAS (201) 666-6698

S BAND & X BAND

High quality and reliability frequency synthesizers for the S and X bands. These are proven production units readily available at low costs!

- Output frequencies up to 9 GHz direct and to 18 GHz with X2 multiplier
- Bandwidths up to 2 GHz
- Rugged EMI package
- All standard interface options selectable within the unit (RS232, RS422, RS485)
- · Low phase noise, low microphonics and no phase hits (over temperature)
- Reference frequency: 1, 5, 10, or 20 MHz or Internal ref (±1PPM)

LIJFE RESEARCH



Your Choice for Sources with World Class Performance, Quality & Low Cost

RESEARCH

20 N. Tyson Ave., Floral Park, NY 11001 Tel: (516) 358-2880 Fax: (516) 358-2757

Web: www.luffresearch.com E-mail: sales@luffresearch.com



Laboratory (RF)MicroProbe Station

Extremely Low Cost < \$10,000 US DC/RF/Microwave Test

A ultra compact, manually operated probe station for engineers. scientists and students. Measure Microwave, RF and IV parameters of Semiconductor Devices. Characterize MEMS, wireless, photonic and nanoelectronic components and assemblies

Benchtop Size(1ff) • 2" Vacuum chuck with pump• 1"X-Y-Ø stage with z-lift• 2ea. 0.5"X-Y-Z probe positioners, includes 2ea. 18 GHz probes & DC needles• 10X/30X Stereo Zoom Trinocular Microscope• Flourescent Illuminator• Compatible with additional Magnetic Mount Positioners(optional)• Compatible with industry standard microwave probes(optional)•

*Cost effective for research projects



J microTechnology

Research Performance / Student Price

J MICROTECHNOLOGY

APRIL INSTRUMENTS

SECTOR MICROWAVE SWITCHES FILTERS MILITARY HI-REI 631) 242-2300 Voice (631) 242-8158 www.SectorMicrowave.com

SECTOR MICROWAVE

SIGNAL GENERATORS



"A premier search and recruiting firm"

KLG SEARCH GROUP

for technical, engineering, and operations including management through executive level positions.

> **Contact Kathleen Luis** Tel: (425) 788-8333 E-mail: klg5@comcast.net

KLG SEARCH GROUP

MICROWAVES & RF ENGINEERING

RATES

Effective January 1, 2003 \$225 per column inch Commissionable to agencies

DEADLINES

Space reservation:

5th of month preceding issue date

Ad material to:

Penton Media Inc., Classified Dept. 45 Eisenhower Dr. Paramus, NJ 07652

SALES STAFF

JoAnne Reppas (201) 666-6698

Fax: (201) 666-0557

e-mail: jrepfrangides@msn.com

Wanted: Forward looking company, ready to compete in the world's largest market by establishing a sales office in the United States. Experienced sales and marketing professional, knowledgeable in a variety of electronic components is currently seeking a challenging opportunity. Contact: Douglas Kaplan, 301-874-0584 or e-mail: kaplandp@erols.com.



If you would like to place an ad in the

Classified Section of Microwaves &RF!

Customer Service Department at...

- PH 201-393-6083
- FAX 201-393-0410

In most cases, advertisements contained in Microwaves &RF employment section indicate that the companies are equal opportunity employers. The Federal Civil Rights Act of 1964, and other laws, prohibit discrimination in employment based on race, color, religion, national origin, sex or for any reason other than lack of professional qualification for the position being offered. It should be noted that employment advertisements in Microwaves & RF are published for the readers convenience and in no way, to the best of our knowledge, promote unlawful discrimination.

Advertiser	Website, E-Mail Address Page
Advanced Radio Cornoration	www.advradio.com; e-mail: info@advradio.com
	www.aqilent.com/view/ephemt
	www.alkeng.com
American Technical Ceramics	www.atceramics.com
Ansoft Corporation	www.ansoft.com/ansoftdesigner
	www.hfss.com
	www.aextal.com; e-mail: sales@aextal.com
	www.aprilinstrument.com
	www.mwoffice.com
AR Kalmus Corporation	www.arkalmus.com
Arra Inc	www.arra.com; e-mail: sales@arra.com
	www.atmel.com/ad/wireless
	www.engineers.com/aviel/home.htm1
	C
California Eastern Labs	www.cel.com/mpow.asp
Chipcon AS	www.chipcon.com; e-mail: wireless@chipcon.com
ian Wireless Inc	www.CiaoWireless.com
	www.coilcraft.com
	www.compac-rf.com
	www.cst-world.com
	www.cti-inc.com; e-mail: sales@cti-inc.com
Credence Systems Corporation .	www.credence.com
	D
Name of the last	www.damaskosinc.com
	www.daico.com
DBM.LLC	www.dbmcorp.com
Diamond Engineering	www.diamondeng.net; www.MicrowaveRF.com
	www.digi-key.com; e-mail: www.digikey.com
	www.ditom.com; e-mail: sales@ditom.com
	E
M Research Inc	www.emresearch.com; e-mail: sales@emresearch.com
EM Research Inc Electromagnetic Tech/ETI	
EM Research Inc Electromagnetic Tech/ETI Focus Microwave	www.emresearch.com; e-mail: sales@emresearch.com
EM Research Inc Electromagnetic Tech/ETI Focus Microwave. Frequency Electronics Inc.	
EM Research Inc Electromagnetic Tech/ETI Focus Microwave. Frequency Electronics Inc.	
EM Research Inc Electromagnetic Tech/ETI Focus Microwave. Frequency Electronics Inc.	
M Research Inc Lectromagnetic Tech/ETI Focus Microwave Frequency Electronics Inc. Herotek Inc.	
EM Research Inc Electromagnetic Tech/ETI Focus Microwave. Frequency Electronics Inc. Herotek Inc Huber & Suhner, Inc.	
EM Research Inc Electromagnetic Tech/ETI Focus Microwave. Frequency Electronics Inc. Herotek Inc Huber & Suhner, Inc.	
M Research Inc Electromagnetic Tech/ETI Focus Microwave Frequency Electronics Inc Herotek Inc Huber & Suhner, Inc	
M Research Inc Lectromagnetic Tech/ETI Focus Microwave Frequency Electronics Inc Herotek Inc Huber & Suhner, Inc Interad Ltd TT Industries	
M Research Inc Liectromagnetic Tech/ETI Focus Microwave Frequency Electronics Inc Herotek Inc Huber & Suhner, Inc Interad Ltd ITT Industries	
M Research Inc Liectromagnetic Tech/ETI Focus Microwave. Frequency Electronics Inc. Herotek Inc. Huber & Suhner, Inc. Interad Ltd TT Industries J Microtechnology.	
EM Research Inc Electromagnetic Tech/ETI Focus Microwave. Frequency Electronics Inc Herotek Inc Huber & Suhner, Inc Interad Ltd ITT Industries J Microtechnology. J Microtechnology.	
EM Research Inc Electromagnetic Tech/ETI Focus Microwave. Frequency Electronics Inc. Herotek Inc Huber & Suhner, Inc. Interad Ltd TT Industries J Microtechnology. J Microtechnology.	
EM Research Inc Lectromagnetic Tech/ETI Focus Microwave Frequency Electronics Inc. Herotek Inc Huber & Suhner, Inc. Interad Ltd TT Industries J Microtechnology J Microtechnology J Microtechnology	
EM Research Inc Electromagnetic Tech/ETI Focus Microwave Frequency Electronics Inc Herotek Inc Huber & Suhner, Inc TI Industries J Microtechnology J Microtechnology J Microtechnology J Microtechnology J Microtechnology	
EM Research Inc Electromagnetic Tech/ETI Focus Microwave. Frequency Electronics Inc. Herotek Inc. Huber & Suhner, Inc. Interad Ltd TT Industries J Microtechnology. J Microtechnology. J Microtechnology. JFW Industries Inc.	
EM Research Inc Electromagnetic Tech/ETI Focus Microwave. Frequency Electronics Inc. Herotek Inc Huber & Suhner, Inc. Interad Ltd TT Industries J Microtechnology. J Microtechnology. J Microtechnology. J Microtechnology. J Wirotechnology.	
EM Research Inc Electromagnetic Tech/ETI Focus Microwave. Frequency Electronics Inc. Herotek Inc Huber & Suhner, Inc. Interad Ltd TT Industries J Microtechnology. J Microtechnology. J Microtechnology. J Microtechnology. J Wirotechnology.	
EM Research Inc Lectromagnetic Tech/ETI Focus Microwave Frequency Electronics Inc. Herotek Inc Luber & Suhner, Inc. Linterad Ltd TT Industries J Microtechnology J Microtechnology J Microtechnology JCA Technology JCA Technology JFW Industries Inc. K&L Microwave/Dover	
M Research Inc Lectromagnetic Tech/ETI Focus Microwave Frequency Electronics Inc Letrotek Inc Le	
EM Research Inc Electromagnetic Tech/ETI Focus Microwave. Frequency Electronics Inc. Herotek Inc. Huber & Suhner, Inc. Interad Ltd ITT Industries J Microtechnology. J Microtechnology. J Microtechnology. JCA Technology. JCA Technology. JCA Technology. JCFW Industries Inc. K&L Microwave/Dover. K&LG Search Group	
EM Research Inc Electromagnetic Tech/ETI Focus Microwave. Frequency Electronics Inc. Herotek Inc Huber & Suhner, Inc. Interad Ltd TT Industries J Microtechnology. J Microtechnology. J Microtechnology. JFW Hudustries Inc. K&L Microwave/Dover. KLG Search Group Linear Technology Corporation.	
EM Research Inc Liectromagnetic Tech/ETI Focus Microwave. Frequency Electronics Inc. Herotek Inc Liuber & Suhner, Inc. J Microtechnology J	
EM Research Inc Electromagnetic Tech/ETI Focus Microwave. Frequency Electronics Inc. Herotek Inc Huber & Suhner, Inc. Interad Ltd TT Industries J Microtechnology. J Microtechnology. JCA Technology. JFW Industries Inc. K&L Microwave/Dover. KLG Search Group Linear Technology Corporation. Luff Research	www.emresearch.com; e-mail: sales@emresearch.com. e-mail: info@focus-microwaves.com www.freqelec.com H www.herotek.com; e-mail: info@herotek.com. e-mail: interad@interadItd.com www.jmicrotechnology.com www.jmicrotechnology.com www.jmicrotechnology.com www.jmicrotechnology.com www.jmicrotechnology.com www.jfwindustries.com; e-mail: jca@jcatech.com www.jfwindustries.com; e-mail: sales@jfwindustries.com e-mail: klg5@comcast.net www.linicroavave.com e-mail: klg5@comcast.net www.linicroavave.com e-mail: klg5@comcast.net www.linicroavave.com e-mail: klg5@comcast.net www.linicroavave.com e-mail: klg5@comcast.net
EM Research Inc Electromagnetic Tech/ETI Focus Microwave. Frequency Electronics Inc. Herotek Inc Huber & Suhner, Inc. Interad Ltd TT Industries J Microtechnology. J Microtechnology. JCA Technology. JFW Industries Inc. K&L Microwave/Dover. KLG Search Group Linear Technology Corporation. Luff Research	www.emresearch.com; e-mail: sales@emresearch.com. e-mail: info@focus-microwaves.com www.freqelec.com H www.herotek.com; e-mail: info@herotek.com. e-mail: interad@interadItd.com www.jmicrotechnology.com www.jmicrotechnology.com www.jmicrotechnology.com www.jmicrotechnology.com www.jmicrotechnology.com www.jfwindustries.com; e-mail: jca@jcatech.com www.jfwindustries.com; e-mail: sales@jfwindustries.com e-mail: klg5@comcast.net www.linicroavave.com e-mail: klg5@comcast.net www.linicroavave.com e-mail: klg5@comcast.net www.linicroavave.com e-mail: klg5@comcast.net www.linicroavave.com e-mail: klg5@comcast.net
EM Research Inc Electromagnetic Tech/ETI Focus Microwave. Frequency Electronics Inc. Herotek Inc Huber & Suhner, Inc. Interad Ltd ITT Industries J Microtechnology. J	
EM Research Inc Electromagnetic Tech/ETI Focus Microwave. Frequency Electronics Inc. Herotek Inc. Huber & Suhner, Inc. Interad Ltd ITT Industries J Microtechnology. J Microtechnology. J Microtechnology. JCA Technology. JCA Technology. JCA Technology. JCA Fochnology. Linear Technology Corporation. Linear Technology Corporation. Lift Research Maxim Integrated Products Maxim Integrated Products Marki Microwave Inc.	
EM Research Inc Electromagnetic Tech/ETI Focus Microwave. Frequency Electronics Inc. Herotek Inc Huber & Suhner, Inc. Huterad Ltd ITT Industries J Microtechnology.	
EM Research Inc Electromagnetic Tech/ETI Focus Microwave. Frequency Electronics Inc. Herotek Inc Huber & Suhner, Inc. Huterad Ltd ITT Industries J Microtechnology.	
EM Research Inc Electromagnetic Tech/ETI Focus Microwave. Frequency Electronics Inc. Herotek Inc Huber & Suhner, Inc. Hitrad Ltd HITI Industries J Microtechnology. J Microtechnology. J Microtechnology. J Microtechnology. J Wis Industries Inc. K&L Microwave/Dover. KLG Search Group Linear Technology Corporation. Luff Research Maxim Integrated Products Marki Microwave Inc Merrimac Industries Inc.	
EM Research Inc Electromagnetic Tech/ETI Focus Microwave. Frequency Electronics Inc. Herotek Inc Huber & Suhner, Inc. Interad Ltd ITT Industries J Microtechnology. J Microtechnology. J Microtechnology. J Microtechnology. J Microtechnology. JKE Huber & Suhner, Inc. Linear Technology. Linear Technology Corporation. Luff Research Maxim Integrated Products Marki Microwave Inc. Maury Microwave Inc. Maury Microwave Inc. Maury Microwave Inc. Mid-Atlantic RF Systems Inc. Mid-Atlantic RF Systems Inc.	www.emresearch.com; e-mail: sales@emresearch.com.
EM Research Inc Electromagnetic Tech/ETI Focus Microwave. Frequency Electronics Inc. Herotek Inc Huber & Suhner, Inc. Interad Ltd ITT Industries J Microtechnology. J Microtechnology. J Microtechnology. J Microtechnology. JCA Technology. J	
EM Research Inc Electromagnetic Tech/ETI Focus Microwave. Frequency Electronics Inc. Herotek Inc Huber & Suhner, Inc. Hiterad Ltd ITT Industries J Microtechnology. J Microtechnology. J Microtechnology. J Wirotechnology. JCA Technology. JCA Technology. JFW Industries Inc. K&L Microwave/Dover. KLG Search Group Linear Technology Corporation. Luff Research Maxim Integrated Products Maxim Integrated Products Maxim Integrated Products Maxim Integrated Inc. May Microwave Inc May Microwave Inc Mary Microwave Inc Merrimac Industries Inc Mid-Atlantic RF Systems Inc Mini-Circuits/SCI Components Mini-Circuits/SCI Components Mini-Circuits/SCI Components	
EM Research Inc Electromagnetic Tech/ETI Focus Microwave. Frequency Electronics Inc. Herotek Inc Huber & Suhner, Inc. Interad Ltd ITT Industries J Microtechnology.	www.emresearch.com; e-mail: sales@emresearch.com.
EM Research Inc Electromagnetic Tech/ETI Focus Microwave. Frequency Electronics Inc. Herotek Inc Huber & Suhner, Inc. Hitrad Ltd ITT Industries J Microtechnology. J	
EM Research Inc Liectromagnetic Tech/ETI Focus Microwave Frequency Electronics Inc. Herotek Inc Liuber & Suhner, Inc. Linterad Ltd TT Industries J Microtechnology J Microtechnology J Microtechnology J Microtechnology JCA Technology	

Advertiser	Website, E-Mail Address	Page
Mini-Circuits/SCI Components	www.minicircuits.com	71
Mini-Circuits/SCI Components	www.minicircuits.com	
Mini-Circuits/SCI Components	www.minicircuits.com	
Mini-Circuits/SCI Components	www.minicircuits.com	
	www.minicircuits.com	
	www.minicircuits.com	
Mini-Circuits/SCI Components	www.minicircuits.com	87
Mini-Circuits/SCI Components	www.minicircuits.com	9
Mini-Circuits/SCI Components	www.minicircuits.com	95
Mini-Circuits/SCI Components	www.minicircuits.com	10
Mini-Circuits/SCI Components	www.minicircuits.com	
Microsemi Corporation	www.Microsemi.com	
Microwave Dynamics	www.microwave-dynamics.com;	-
	e-mail: info@microwave-dynamics.com	
Micro Lambda Wireless,inc	e-mail: sales@microlambdawireless.com	A
	e-mail: sales@microlamodawireless.com www.midwest-microwave.com;	
Midwest Microwave	www.midwest-microwave.com;	Cour
	e-mail: sales@midwest-microwave.com	
	www.miteq.com	
	www.miteq.com	
MITEQ MEDIA		
	N	01 2 /
	www.nardamicrowave.com; e-mail: nardeast	
	www.nexyn.com	
Nemal Electronics Intl Inc	www.nemal.com; e-mail: info@nemal.com	
Nova Engineering Inc	www.nova-eng.com/go/ns2; e-mail: novasour	rce@nova-eng.com /
	P	
	www.polyfet.com	
Programmed Test Sources Inc	www.programmedtest.com	l
Pulsar Microwave Corp	www.pulsarmicrowave.com; e-mail: sales@pu	ulsarmicrowave.com . 6
	R	100
	www.resotechinc.com	
RFHIC Company	www.rfhic.com; e-mail: sales@rfhic.com	4
RF Micro Devices	www.rfmd.com	
	www.rfmd.com	
Rockwell Scientific	www.rockwellscientific.com	
Saw Flactronic Solutions	www.on.wplus.net/aec; e-mail: ses4@comcas	st net 10°
	www.sectormicrowave.com	
Sector Microwaves Ind Inc	www.sectormicrowave.com	110
	www.spectrum-et.com; e-mail:specelek@Com	
	www.ssicable.com	
	www.synergymwave.com; e-mail: sales@syne	
	www.synergymwave.com; e-mail: sales@syne	
Synergy Microwave	www.synergymwave.com; e-mail: sales@syne	ergymwave.com7.
of merodiate contract	T	,
TEC Power Conversion inc	www.tcpowerconversion.com	10
	www.tcpowerconversion.com	
	www.tte.com.	
TTE IIICOI por ateu		
Universal Microwaya Company	nts www.umcc111.com; e- mail: UMCC@UMCC111.co	om 10
	V — V	JIII
	www.vectorfields.com; e-mail: info@vectorfi	olds com o
	www.vectorrields.com; e-mail: info@vectorrie	
	www.VoltronicsCorp.com; e-mail: infovoltron	
Voltronics Fraguency Control Bred	lucts inc www.voitronicscorp.com; e-mail: info@voitron	icsten com 10
Ford Offics Frequency Control Proc	ucts inc www.voitromesrep.com; e-mail: info@voitrom	псэтер.сопт 10
The second secon	www.waveconsoft.com	
Want of the second seco	www.waveconsoft.com	
	The state of the s	man and a second of the second of the second
Waveline Inc	e-mail: wavelineinc.com	
Waveline Inc	www.wj.com	2
Waveline Inc	www.wj.comwww.wbecoinc.com	
Waveline Inc	www.wj.com	

MARKETING AND ADVERTISING STAFF

GROUP PUBLISHER Craig Roth (201) 845-2448 e-mail:croth@penton.com

SALES ASSISTANT Judy Kollarik (201) 845-2427 e-mail: jkollarik@penton.com

DIRECT CONNECTION ADS CLASSIFIED ADVERTISING Joanne Reppas (201) 666-6698 e-mail: jrepfrangides@msn.com CIRCULATION CUSTOMER

CIRCULATION CUSTOMER SERVICE (LIVE) Phone: (847) 763-9670 Fax: (847) 763-9673 e-mail: microwaves&rf@halldata.com NEW YORK, NEW ENGLAND, MIDDLE ATLANTIC, DC, VA, Paul Barkman Global Sales Manager Penton Media, inc. 45 Eisenhower Dr., rifth floor Paramus, NJ 07652 (908) 704-2460 FAX: (908) 704-2486 e-mail: pbarkman@penton.com

MIDWEST, SOUTHEAST, SOUTHWEST, CANADA Michael Barkman Account Executive Penton Media, Inc. 45 Eisenhower Dr., fifth floor Paramus, NJ 07652 (908) 832-6551 PAX: (908) 832-7052 e-mail: mbarkman@penton.com

c-mail: mod kmane-penton.co CALIFORNIA, NORTHWEST Nichole Fox Regional Sales Manager Penton Media, Inc. 45 Eisenhower Dr., fifth floor Paramus, NJ 07652 (858) 794-4941 FAX: (858) 794-4942 e-mail: nfox@penton.com ITALY Cesare Casiraghi Viale Varase 39 22100 Como - Italy Phone: 39-31-261407 FAX: 39-31-261380

GERMANY, AUSTRIA, SWITZERLAND Friedrich K. Anacker Managing Director InterMedia Partners GmbH (IMP) Deutscher Ring 40 42327 Wuppertal Germany Phone: 011-49-202-271-690 FAX: 011-49-202-271-6920

SPAIN Luis Andrade, Miguel Esteban Espana Publicidad Internacional Sepulveda, 143-38 08011 Barcelona, Spain Phone: 011-34-93-323-3031 FAX: 011-34-93-453-2977 FRANCE Emmanual Archambeaud Defense & Communication 48 Bd Jean-Jaures, 92110 Clichy France Phone: 33-01-47-30-7180

FAX: 33-01-47-30-0189

HOLLAND, BELGIUM
William J.M. Sanders, S.I.P.A.S.
Rechtestraat 58

1483 Be De Ryp, Holland
Phone: 31-299-671303

FAX: 31-299-671500

CZECH REPUBLIC

CZECH REPUBLIC
Robert Bilek
Production International
Slezska 61, 13000 Praha 3
Czech Republic
Phone: 011-42-2-730-346
FAX: 011-42-2-730-346

PORTUGAL
Paulo Andrade
Ilimitada-Publicidade
Internacional. LDA
Av. Eng. Duarte Pacheco
Empreedimento das
Amoreiras-Torre 2
Piso 11-Sala 11
1070 Lisboa, Portugal
Phone: 351-1-3883176
FAX: 351-1-3883283

TAIWAN, R.O.C. Charles C.Y. Liu, President Two-Way Communications Co., Ltd. 11F/1, No. 421 Sung Shan Road Taipei 110, Taiwan, R.O.C. Phone: 886-2-727-7799 FAX: 886-2-728-3686

JAPAN
Hiro Morita
Japan Advertising
Communications, Inc.
Three Star Building
3-10-3 Kanda Jimbocho
Chiyoda-ku, Tokyo 101, Japan
Phone: 81-3-3261-4591
FAX: 81-3-3261-6126

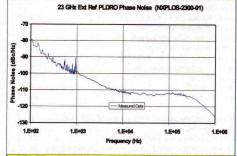
KOREA BISCOM Jo Young Sang Rm. 521 Midopa Bldg. 145 Dan Ju-Dong Chongno-Gu Seoul 110-071 Korea Phone: 027397840 FAX: 027323662

INDIA
Shivaji Bhattacharjee
Information & Education Services
Ist Floor, 30-9, Ber Saral Village,
Near I.J.T. Hauz Khas, Behind
South Indian Temple
New Delhi, 110016 india
FAX: 001-91-11-6876615

Renton

Experience the Nexyn Innovation

23 GHzPhase Locked DROs New Products Details on website



Phase Noise at 23 GHz (Typical)

100 Hz - 80 dBc/Hz 1 KHz -100 dBc/Hz 10 KHz -110 dBc/Hz 100 KHz -112 dBc/Hz 1 MHz -127 dBc/Hz

- Free Running/Phase Locked DRO
- Reliable and Rugged Design
- Extremely Low Microphonics
- 5-200 MHz External Reference
- Frequency: 3 to 26 GHz
- Power output: +10dBm
- · Spurious: -80 dBc
- -10 to +65 C (wider range options)
- Internal Ref/Dual Loop options
- Now offering PLO .3 to 3 GHz
- Low Noise crystal reference





Nexyn Corporation

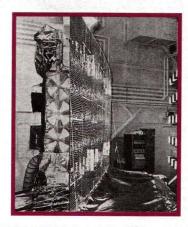
1089 Memorex Dr. Santa Clara, CA 95050

Tel: (408) 982-9339 Fax: (408) 982-9275

Visit our website at www.nexyn.com

Excellent Technical Support Guaranteed Performance and Competitive Pricing

looking back



ALMOST 20 YEARS AGO, RCA Astro Electronics (Princeton, NJ) received a \$171 million contract from the Space Division of the US Air Force for four weather satellites for the Defense Meteorological Satellite Program.

→next month

Microwaves & RF November Editorial Preview Issue Theme: Microwaves & Optics

News

Optical-communications markets appeared to explode near the end of the last century. Unfortunately, the cost of building high-speed optical networks and links far exceeded the expected incomes, leaving many suppliers of optical components holding large inventories by the end of 2000. What is the state of high-speed optical communications today, and is there still a need for OC-768 (40-Gb/s) systems? A special report in November will shed some light on high-speed fiber optics.

Design Features

November will examine simple photonic-bandgap (PBG) structures and how they can be used to provide effective and flexible control of electromagnetic (EM) waves in specific directions. In other articles, authors from New Jersey will detail linearization techniques for high-power microwave power modules (MPMs) capable of delivering 50 to 250 W, a well-known

MICROWAVES & RF

modulation expert offers an update on minimum-sideband (MSB) ultra-narrowband modulation techniques for high-datarate communications, and a physicist will share his thoughts on characterizing reed relays for applications through 10 GHz.

Product Technology

November unveils the latest version of a powerful frequency-domain circuit design environment based on a unique time-synchronous data-flow simulator. The software allows analog and digital designers to view their projects by means of frequencydomain parameters (rather than the time domain of traditional SPICE). Additional product Features will explore a family of highpass filters with cutoff frequencies from 600 to 3000 MHz fabricated on lowtemperature-cofired-ceramic (LTCC) materials, a group of high-performance frequency synthesizers from a source previously associated with receiver systems, and a line of frequency-tunable substrate materials.



The "no-nonsense" attenuator...
For Audio, IF, and VHF.

Simple, straight forward, no frills. Not bad when this economy model performs in the same classy manner as other ARRA high precision units.

- SMA connectors, others available
- Off-the-shelf delivery
- 50 ohm impedance, 75 ohms available
- Specs that beat the competition's

Directly calibrated models

Directly candrated models			
Freq Range (MHz)	Atten Range (dB)	Atten vs Freq (dB)	Model No.
DC-60	40	±1.0	0682-40F
DC-100	15	±0.3	0682-15F
DC-100	30	± 0.5	0682-30F
DC-250	10	±0.5	0682-10F
	Uncalibrat	ed models	•
DC-60	40	±1.0	0682-40
DC-100	20	±0.6	0682-20
DC-100	30	± 0.5	0682-30
DC-200	30	±2.0	0682-30A
DC-250	15	±1.2	0682-15
DC-500	10	± 0.25	0682-10

Visit our website at www.arra.com

The "incredible" attenuator...
Elegant, classic, exceptional. With all the extras you'd expect at the top of the ARRA line. So uniquely new in its approach, it's one of a kind. Nothing else like it on the market. It's got everything...

- · Low phase
- High RF Power
- Low VSWR & Insertion loss
- Extremely flat frequency response
- 0-3 dB & high attenuation models
- Bands from 350-5000 MHz

... the last word in variable attenuators

ARRA INC. —
15 Harold Court • Bay Shore NY 11706-2296

Tel 631-231-8400

Fax 631-434-1116

E-Mail: sales@arra.com



MIDWEST MICEROXYAYE

Attenuators



Fixed, Stepped, Continuously variable Low VSWR, D.C. - 26.5 GHz, QPL

Terminations



Low to medium power, Open circuits Short circuits, Low VSWR, D.C. - 26.5 GHz

D.C. Blocks



Inside/Outside, Inside Only Rugged Construction

Couplers



Multi Couplers, Multi-Octave broadbend Hybrids, Octave bandwidth, D.C. - 18 GHz

Power Dividers



Broadband, Ultrabroadband, High Isolation Low Phase & Amplitude Unbalance, D.C.-18 GHz

Equ**aliz**ers



Broad or Narrow band, Fixed, Linear Parabelic, Adjustable, D.C. - 18 GHz

Adapters



In - Series, Between Series, QPL D.C. - 26.5 GHz

Cable Assemblies



Flexible, Phase Stable, Phase Matched D.C. - 40 GHz

Delaw Lines · ·



Reformable, Phase Statute, Phase Matched. Delay Lines, D.C. - 40 GHz

For more information on any of these products and the rest of the Midwest Microwave rangerouteret us:

United States and Canada

6564 South State Road, Saline Michigan 48176 Tel: 734 429 4773 — Fax: 734 429 1415 E-mail: sales@midwest-microwave.com Web: www.midwest-microwave.dom

International

Russell Way, Wildford Industrial Estate, Chelmsford, Essex CM1 3AA United Kingdom. Tel: 44 (0):1245 359515 Fax: 44 (0) 1245 358938 E-mail: sales@midwest-microwave.htd.uk Web; www.midwest-microwave.htd.uk